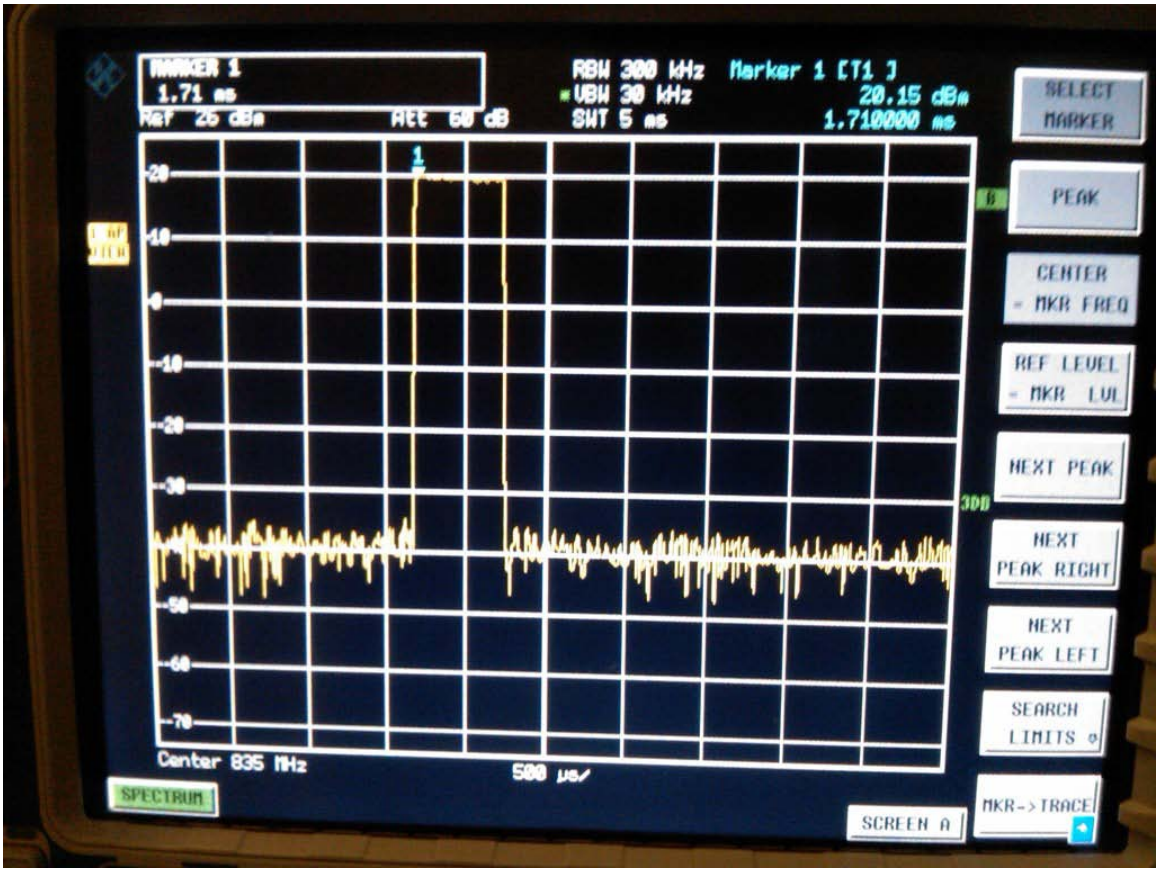
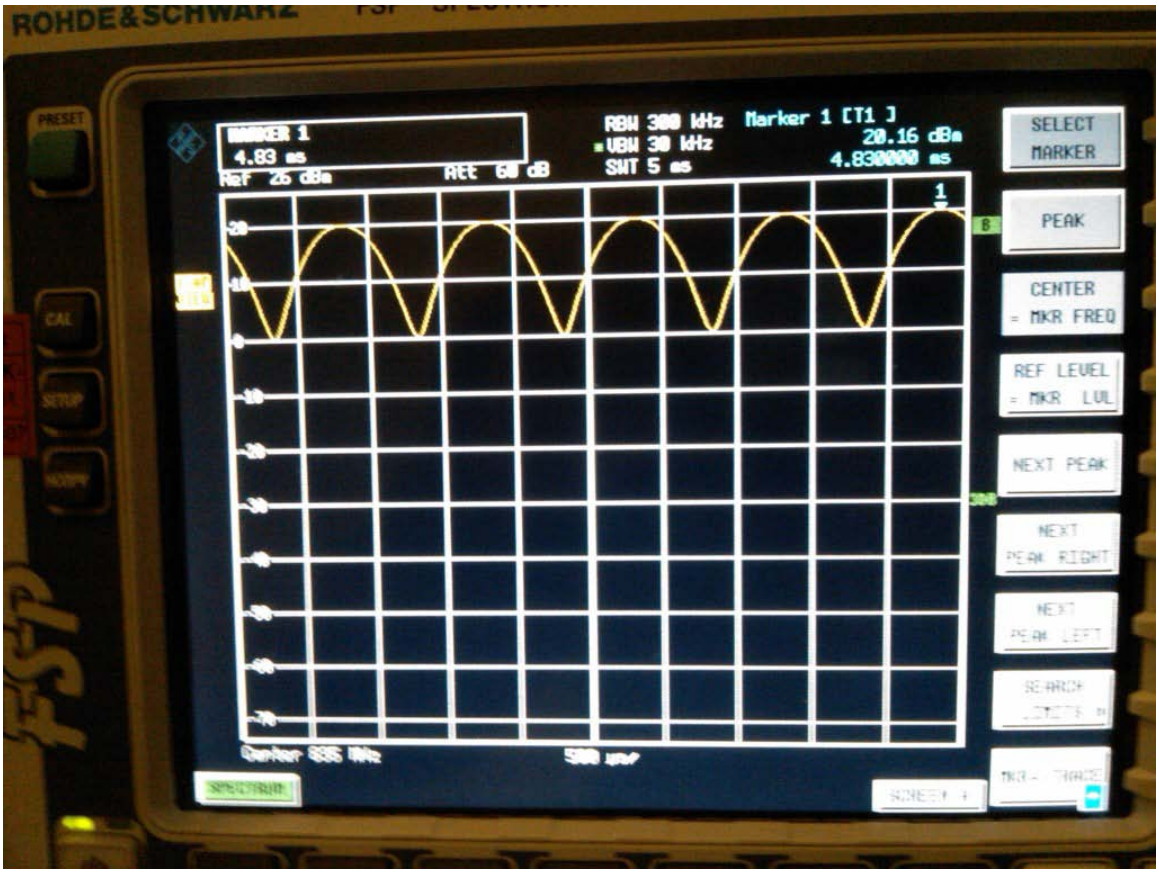
Annex A: Measurement data and plots

A.1 Spectrum analyser plots: GSM/UMTS, CW, 80%AM, signals

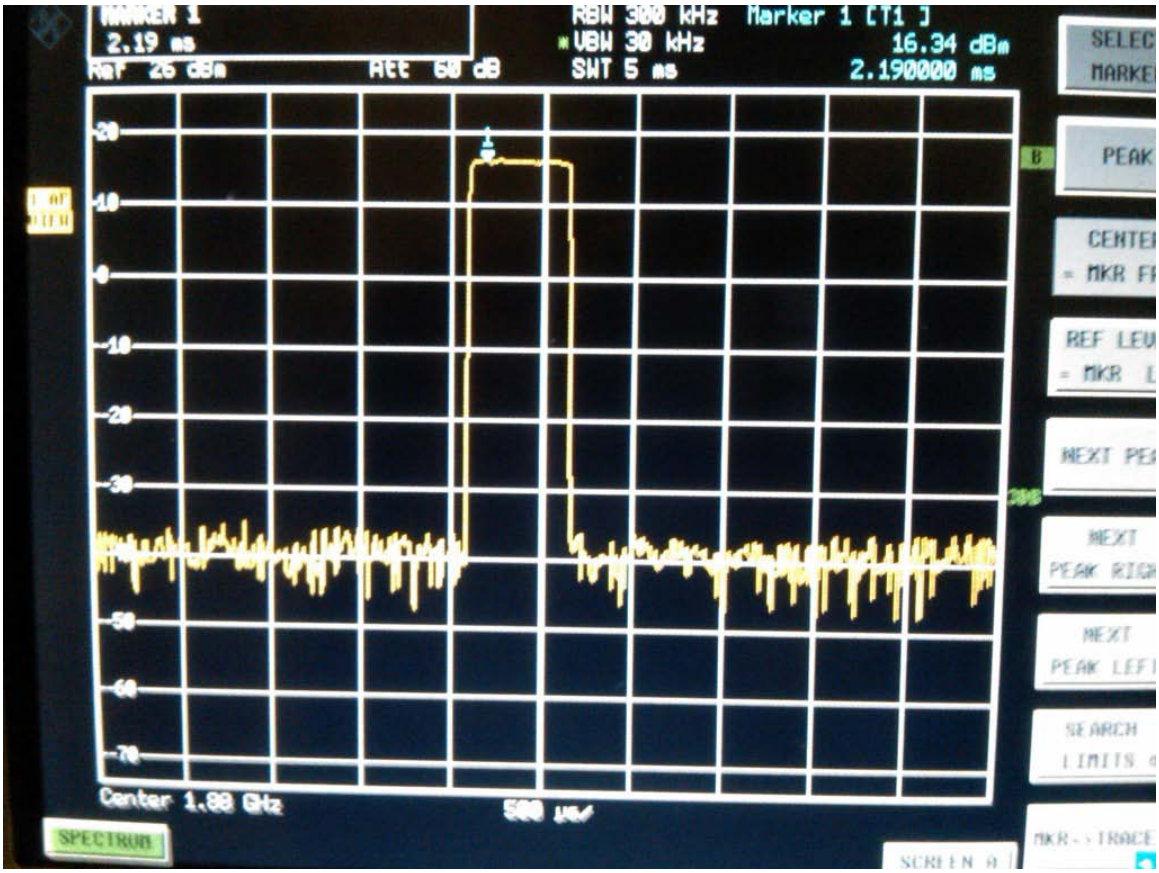


GSM 835 MHz

CW 835 MHz

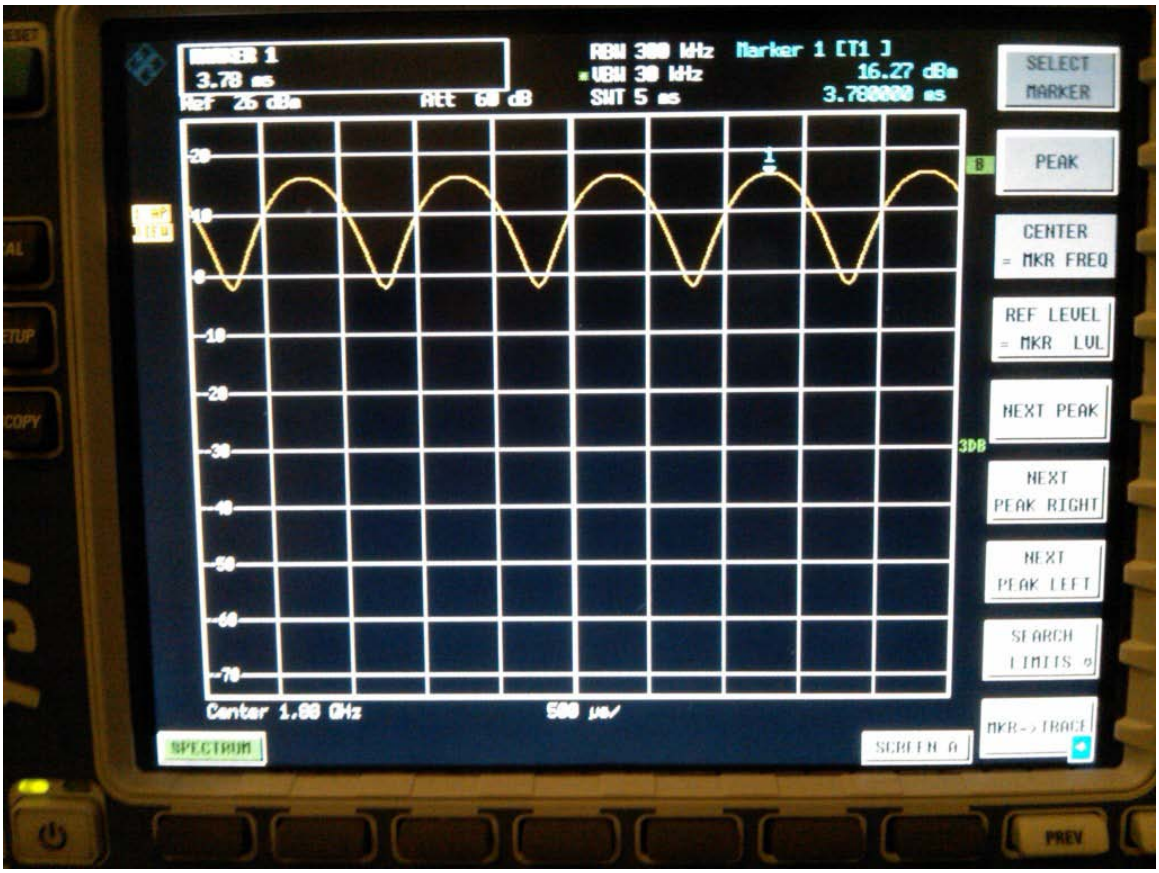


AM 80% 835 MHz



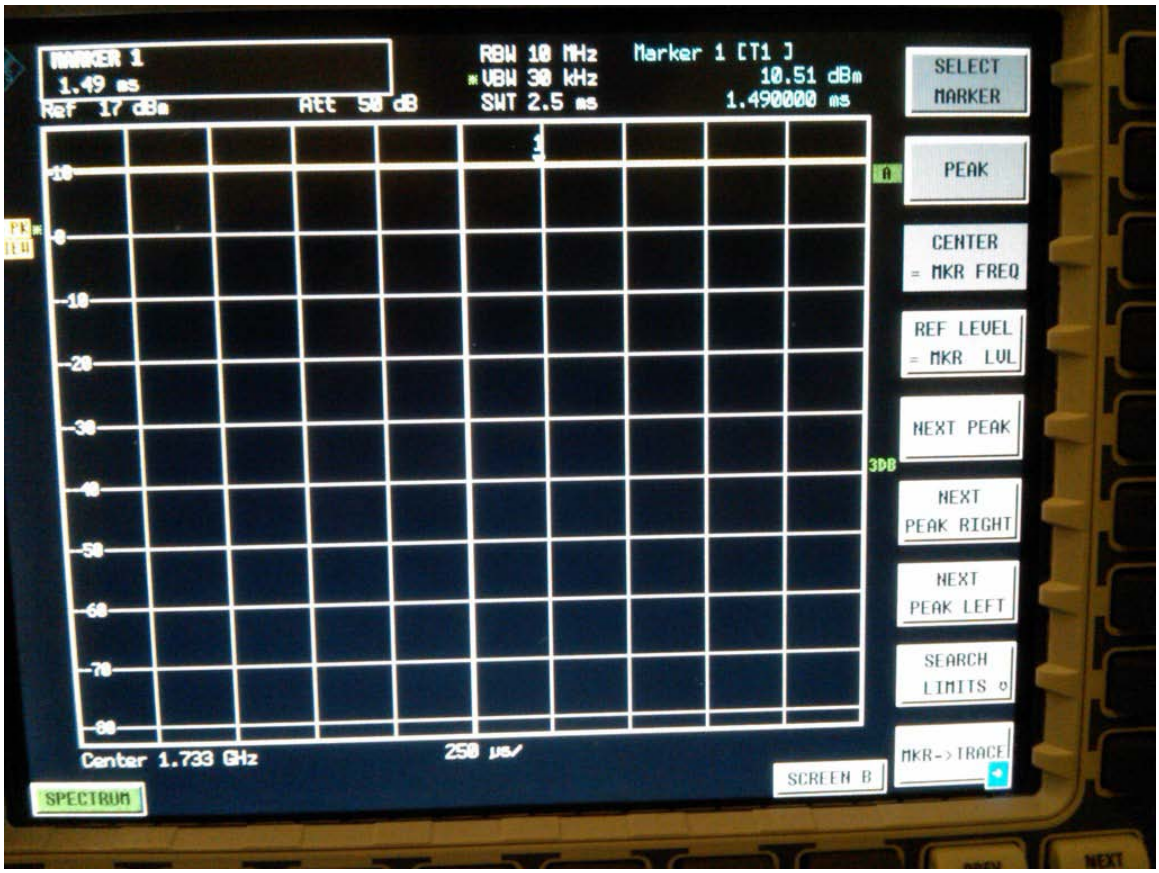
GSM 1880 MHz

CW 1880 MHz

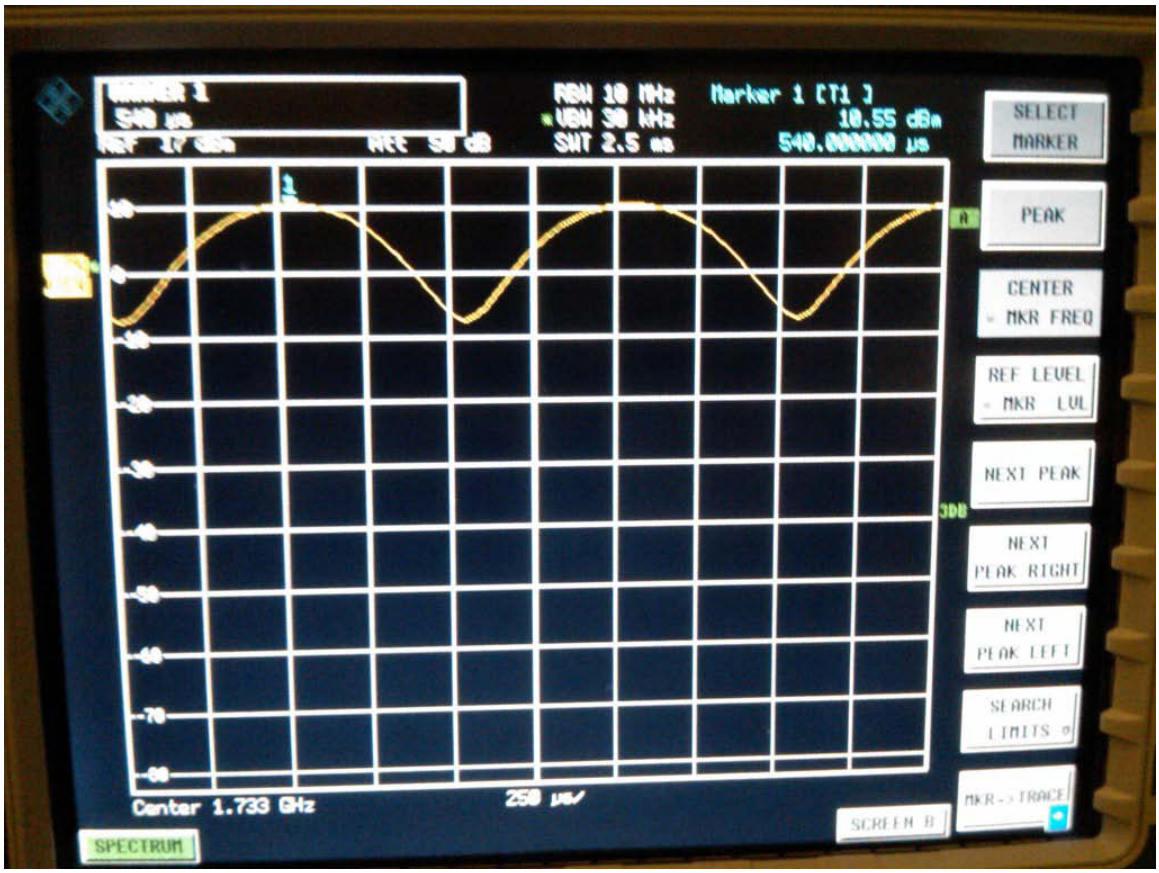


AM 80 % 1880 MHz

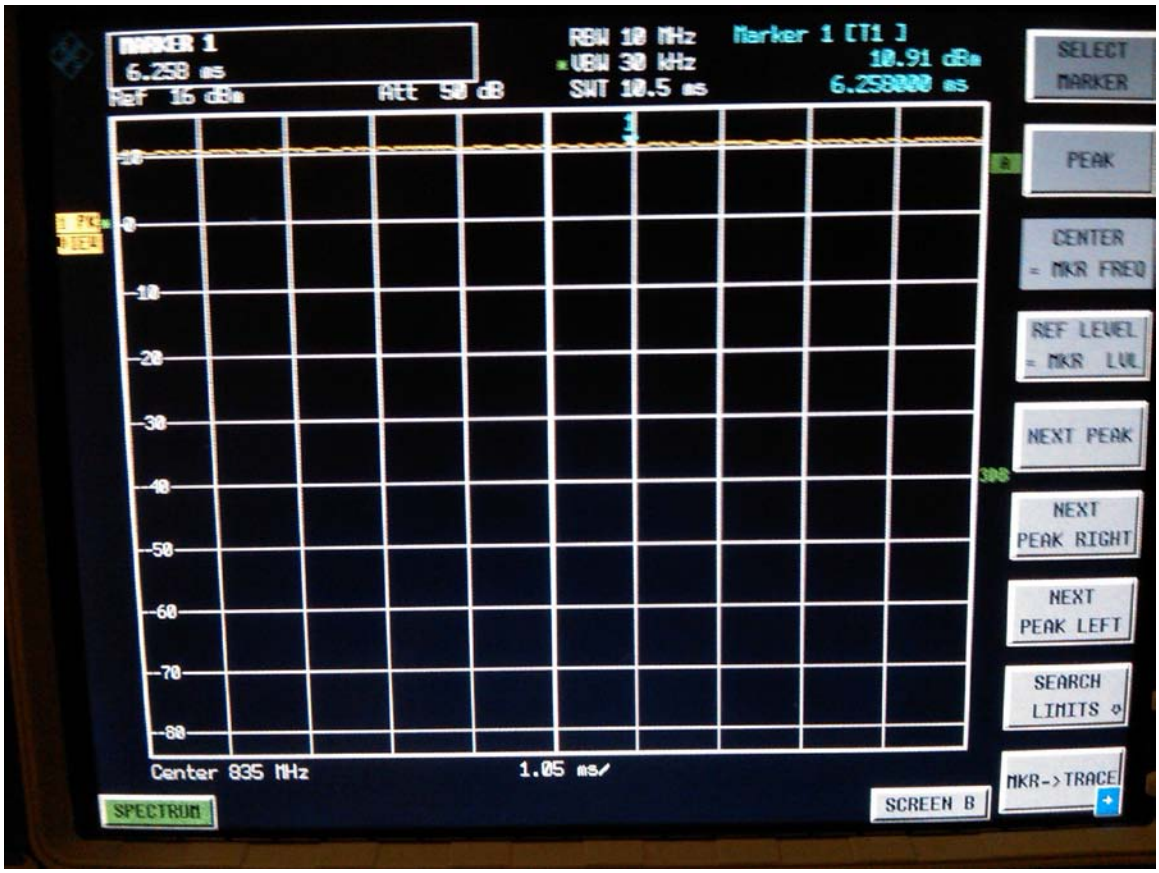
UMTS 1733 MHz



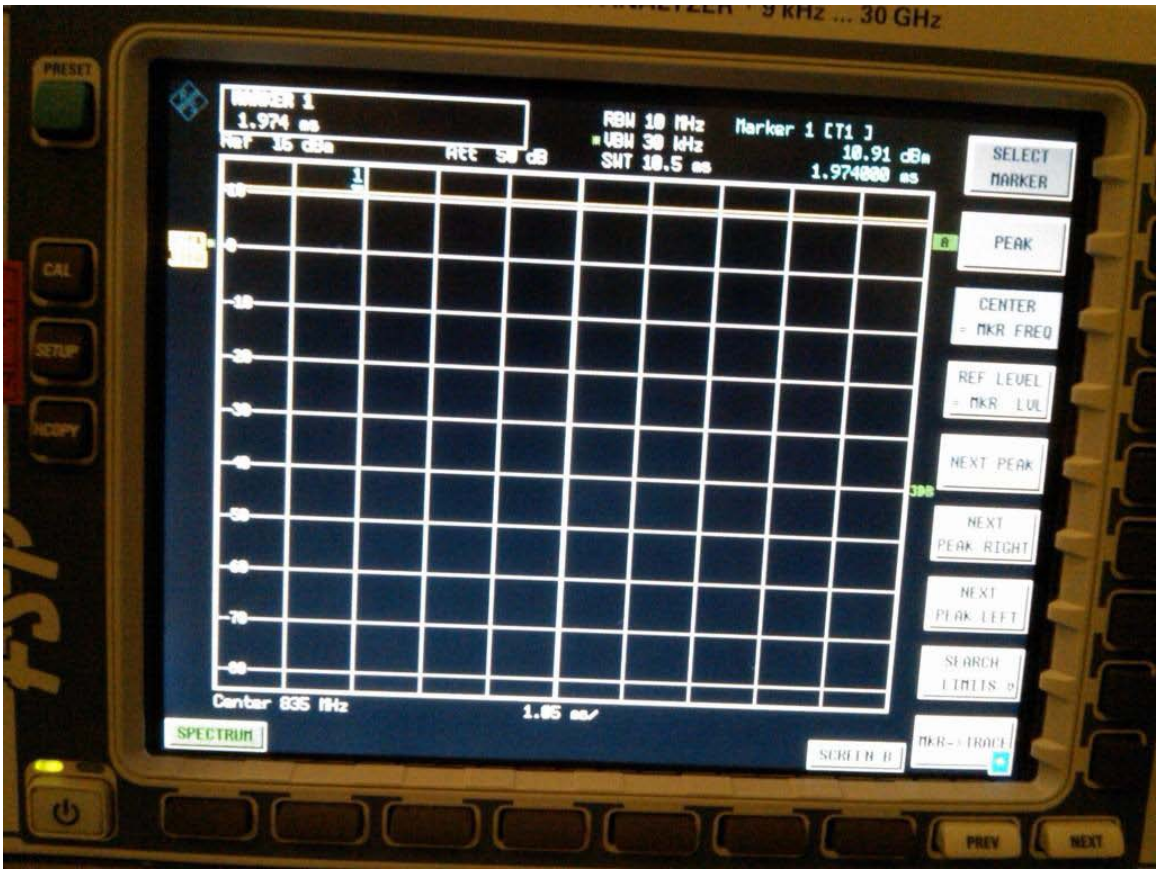
CW 1733 MHz



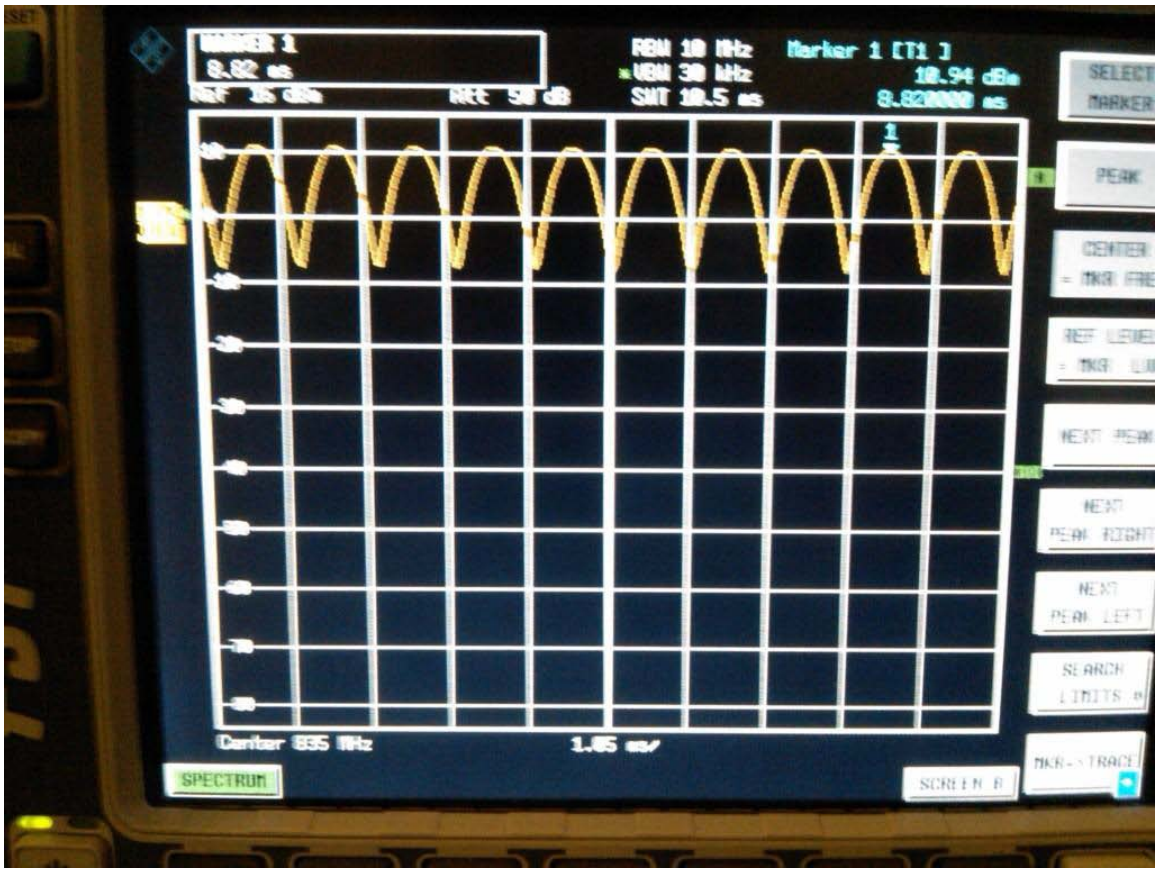
AM 80% 1733 MHz



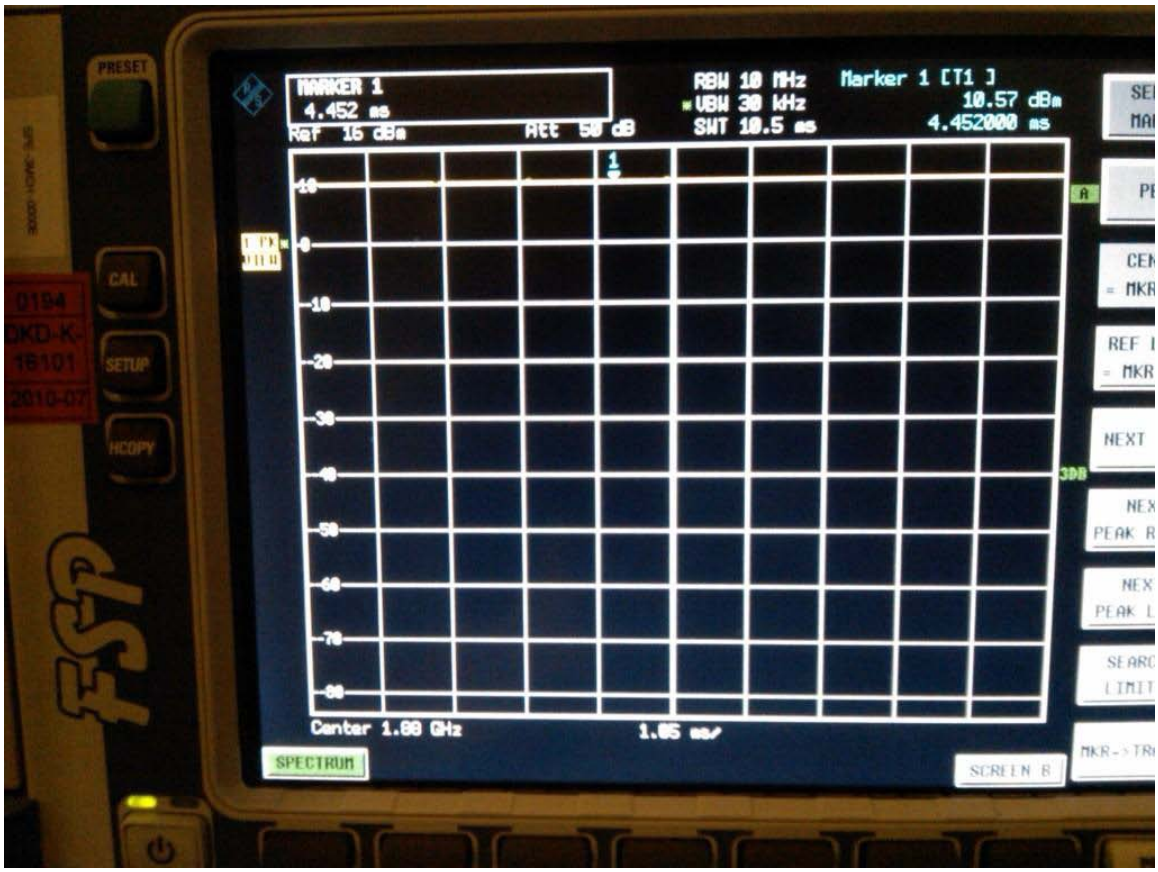
UMTS 835 MHz



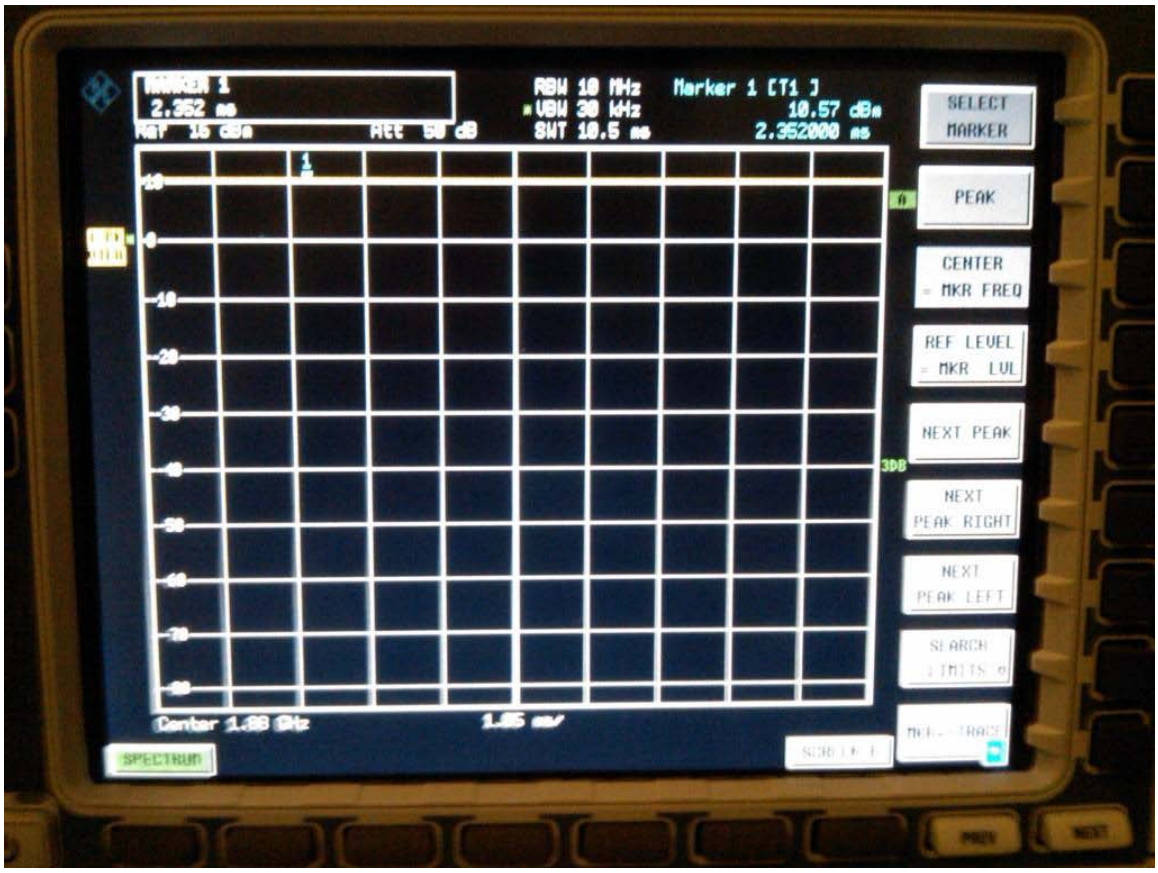
CW 835 MHz



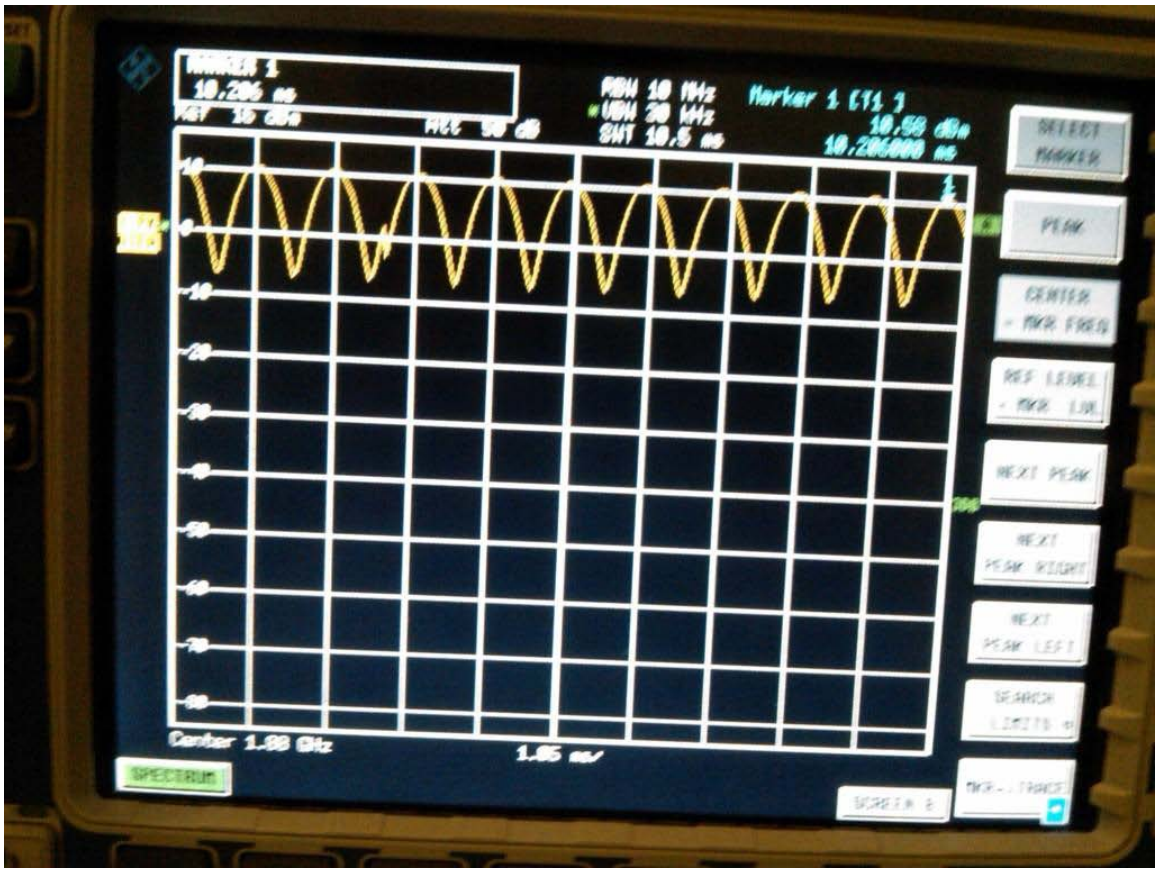
AM 80% 835 MHz



UMTS 1880 MHz



CW 1880 MHz



AM 80 % 1880 MHz

A.2 Dipole validation and probe modulation factor plots

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Test Laboratory: RIM Testing Services

HAC RF_E-Field_validation_835 MHz

DUT: HAC-Dipole 835 MHz; Type: D835V3;

Communication System: CW; Communication System Band: D835 (835.0 MHz); Frequency: 835 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

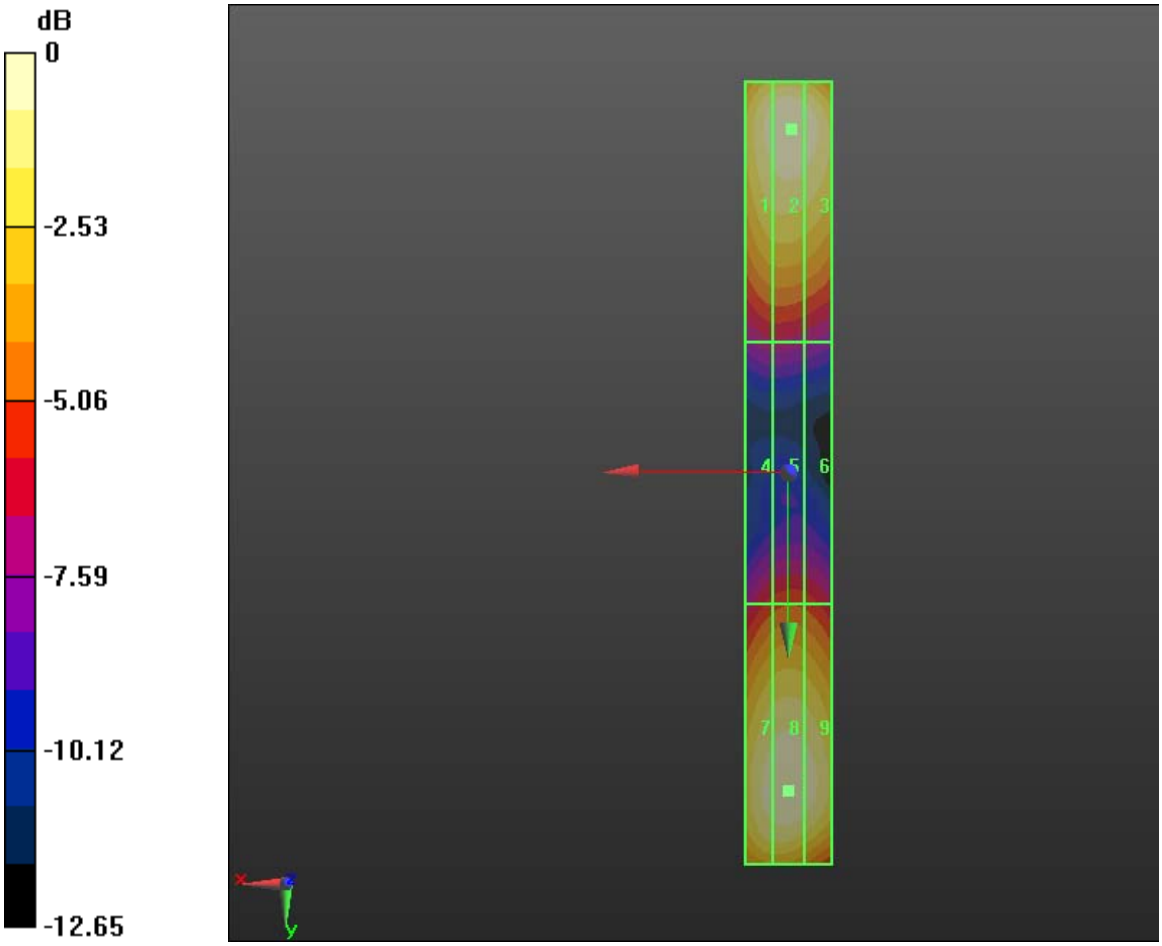
Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 160.2 V/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 119.1 V/m; Power Drift = 0.28 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **154.3 M4**	Grid 2 **160.2 M4**	Grid 3 **156.7 M4**
Grid 4 **85.253 M4**	Grid 5 **88.903 M4**	Grid 6 **87.202 M4**
Grid 7 **155.3 M4**	Grid 8 **158.9 M4**	Grid 9 **155.3 M4**

Cursor:

Total = 160.2 V/m
E Category: M4
Location: -0.5, -79, 4.7 mm



0 dB = 160.2V/m

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Test Laboratory: RIM Testing Services

HAC RF_E-Field_PMF_GSM_835 MHz

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: GSM 850;; Frequency: 835 MHz;Communication System PAR: 9.191 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

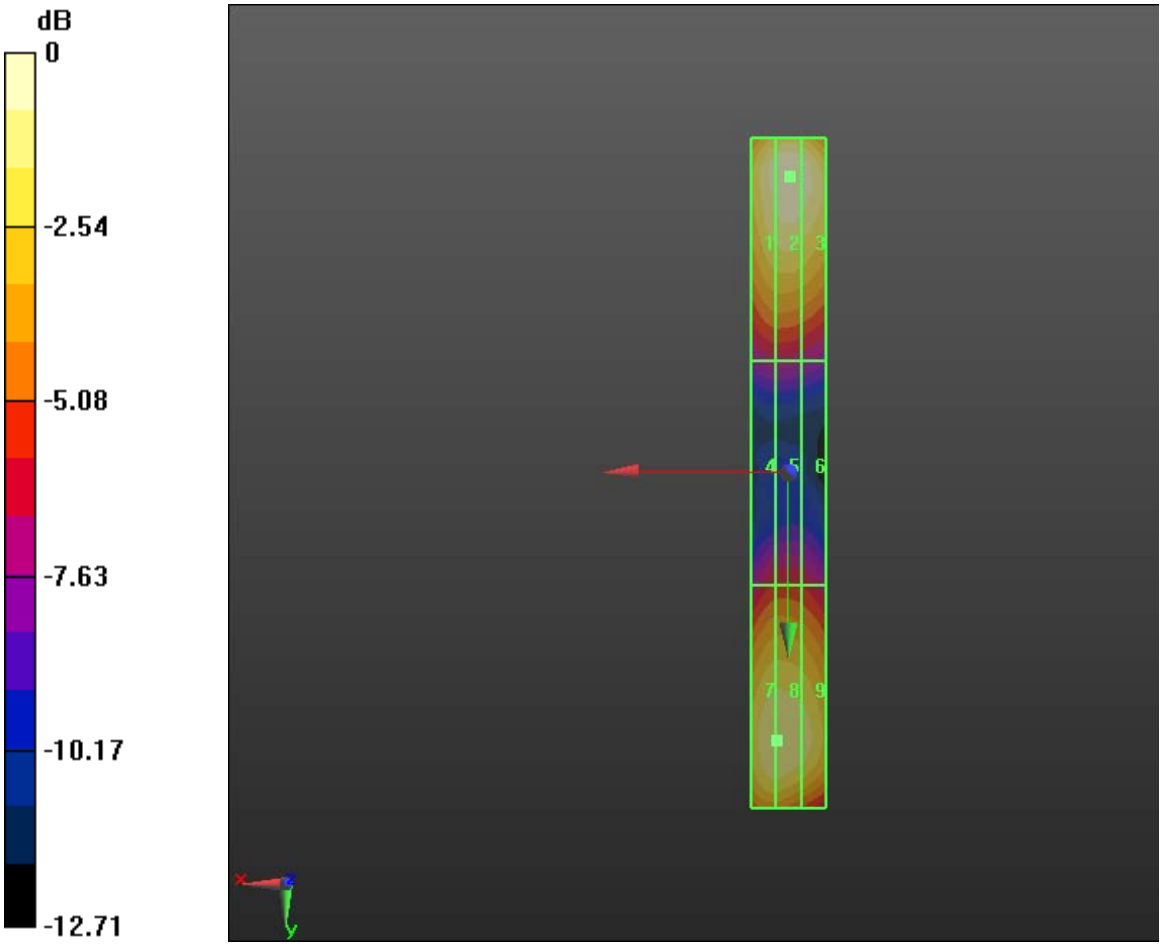
Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 54.142 V/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 38.642 V/m; Power Drift = -0.06 dB
Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **51.408 M4**	Grid 2 **54.142 M4**	Grid 3 **52.509 M4**
Grid 4 **27.621 M4**	Grid 5 **27.841 M4**	Grid 6 **27.144 M4**
Grid 7 **49.045 M4**	Grid 8 **49.106 M4**	Grid 9 **47.011 M4**

Cursor:

Total = 54.142 V/m
E Category: M4
Location: -0.5, -79.5, 4.7 mm



0 dB = 54.140V/m

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Test Laboratory: RIM Testing Services

HAC RF_E-Field_PMF_CW835 MHz_GSM

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: CW; Communication System Band: D835 (835.0 MHz); Frequency: 835 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

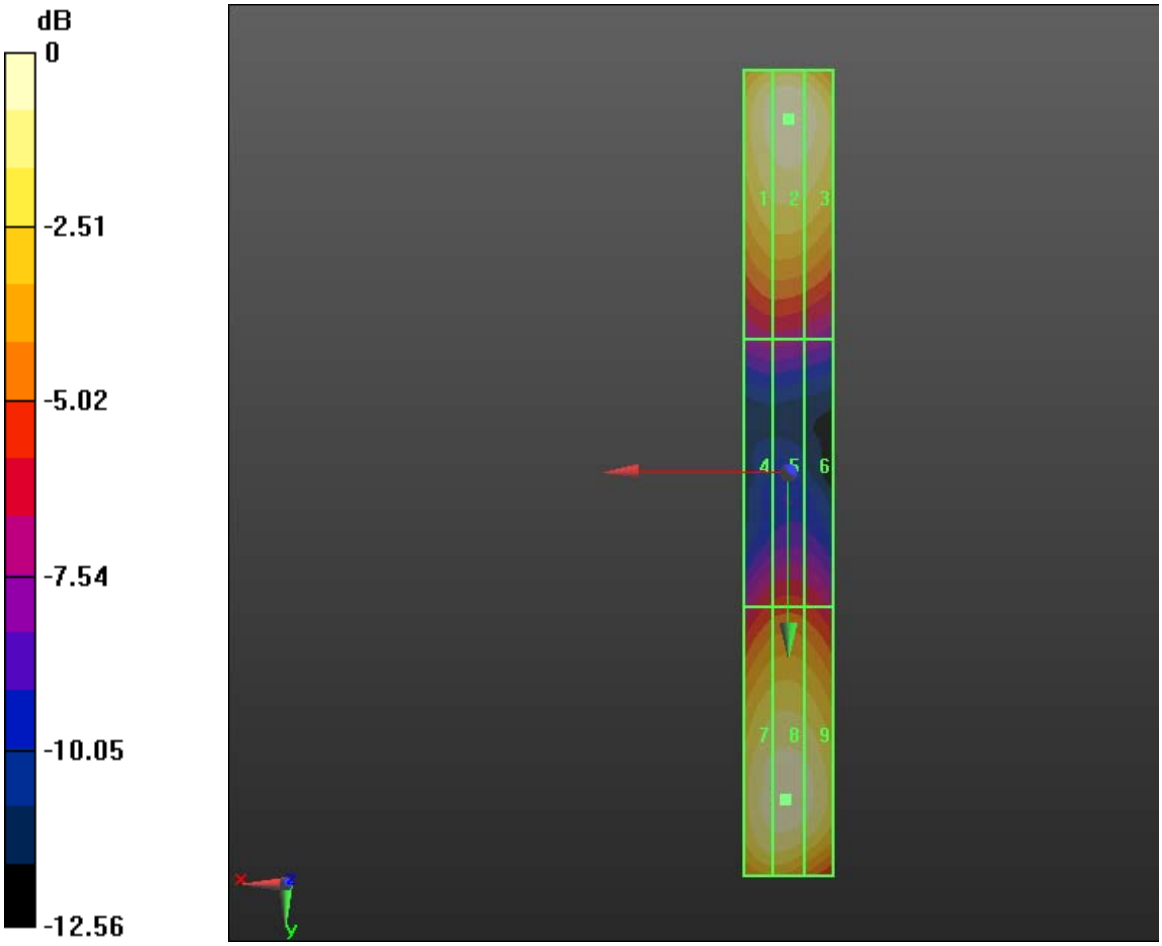
Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 159.3 V/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 120.6 V/m; Power Drift = -0.10 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **153.1 M4**	Grid 2 **159.3 M4**	Grid 3 **154.5 M4**
Grid 4 **8066 M4**	Grid 5 **86.943 M4**	Grid 6 **84.863 M4**
Grid 7 **153.2 M4**	Grid 8 **154.9 M4**	Grid 9 **151.1 M4**

Cursor:

Total = 159.3 V/m
E Category: M4
Location: 0, -79, 4.7 mm



0 dB = 159.3V/m

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Test Laboratory: RIM Testing Services

HAC RF_E-Field_PMF_AM80%835 MHz_GSM

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: AM 80%; Communication System Band: D835 (835.0 MHz);
Frequency: 835 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

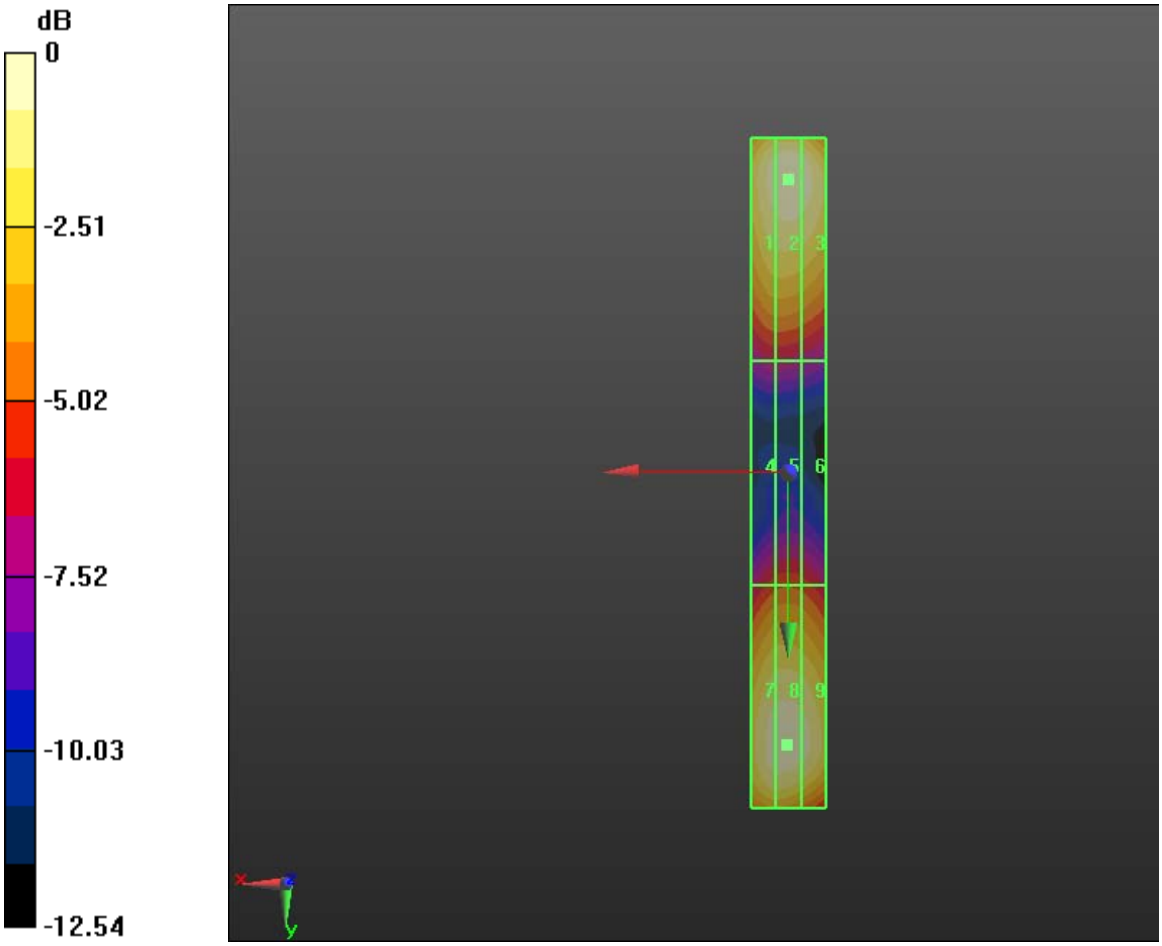
Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 99.820 V/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 74.981 V/m; Power Drift = -0.17 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **96.553 M4**	Grid 2 **99.820 M4**	Grid 3 **97.313 M4**
Grid 4 **54.091 M4**	Grid 5 **55.431 M4**	Grid 6 **53.882 M4**
Grid 7 **95.955 M4**	Grid 8 **97.176 M4**	Grid 9 **95.117 M4**

Cursor:

Total = 99.821 V/m
E Category: M4
Location: 0, -79, 4.7 mm



0 dB = 99.820V/m

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Test Laboratory: RIM Testing Services

HAC RF_E-Field_validation_1880 MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Communication System Band: D1900 (1900.0 MHz); Frequency: 1880 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

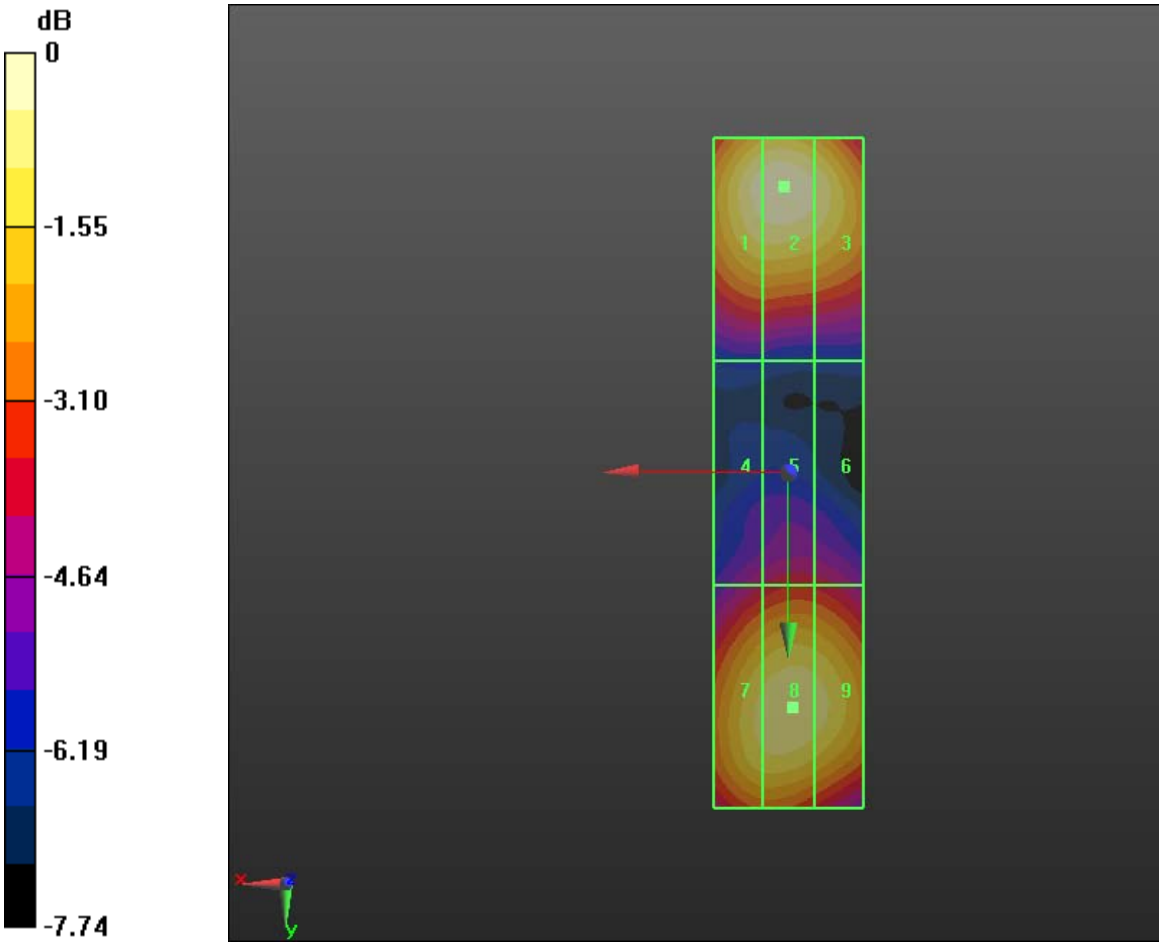
Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 133.2 V/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 124.8 V/m; Power Drift = -0.0086 dB
Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **130.6 M2**	Grid 2 **133.2 M2**	Grid 3 **126.2 M2**
Grid 4 **83.013 M3**	Grid 5 **87.500 M3**	Grid 6 **86.528 M3**
Grid 7 **121.2 M2**	Grid 8 **124.7 M2**	Grid 9 **122.2 M2**

Cursor:

Total = 133.2 V/m
E Category: M2
Location: 0.5, -38.5, 4.7 mm



0 dB = 133.2V/m

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Test Laboratory: RIM Testing Services

HAC RF_E-Field_PMF_GSM_1880 MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: GSM 1900; Frequency: 1880 MHz;Communication System PAR: 9.191 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

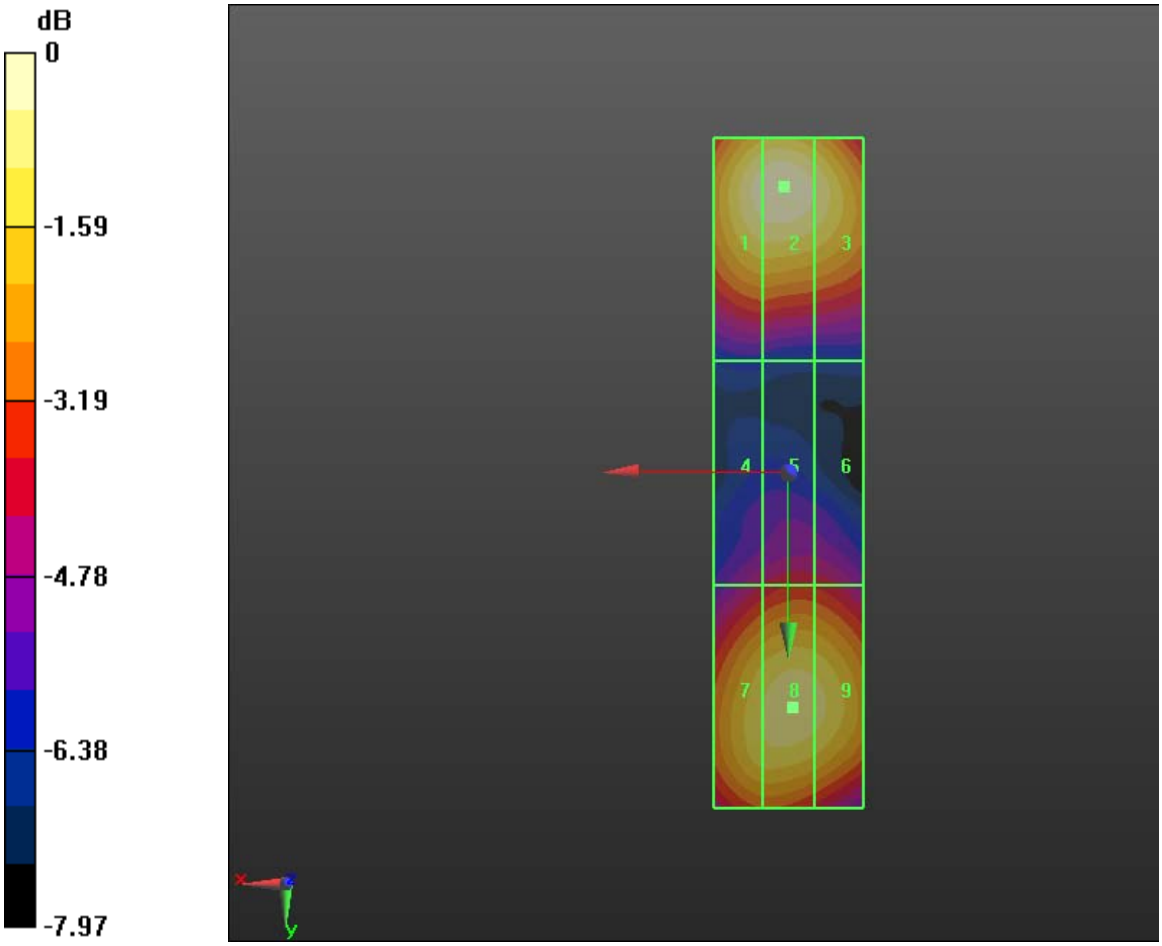
Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 27.663 V/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 25.374 V/m; Power Drift = 0.02 dB
Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **27.050 M4**	Grid 2 **27.663 M4**	Grid 3 **26.052 M4**
Grid 4 **17.031 M4**	Grid 5 **18.013 M4**	Grid 6 **17.833 M4**
Grid 7 **2036 M4**	Grid 8 **25.539 M4**	Grid 9 **25.116 M4**

Cursor:

Total = 27.663 V/m
E Category: M4
Location: 0.5, -38.5, 4.7 mm



0 dB = 27.660V/m

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Test Laboratory: RIM Testing Services

HAC RF_E-Field_PMF_CW1880 MHz_GSM

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Communication System Band: D1900 (1900.0 MHz); Frequency: 1880 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

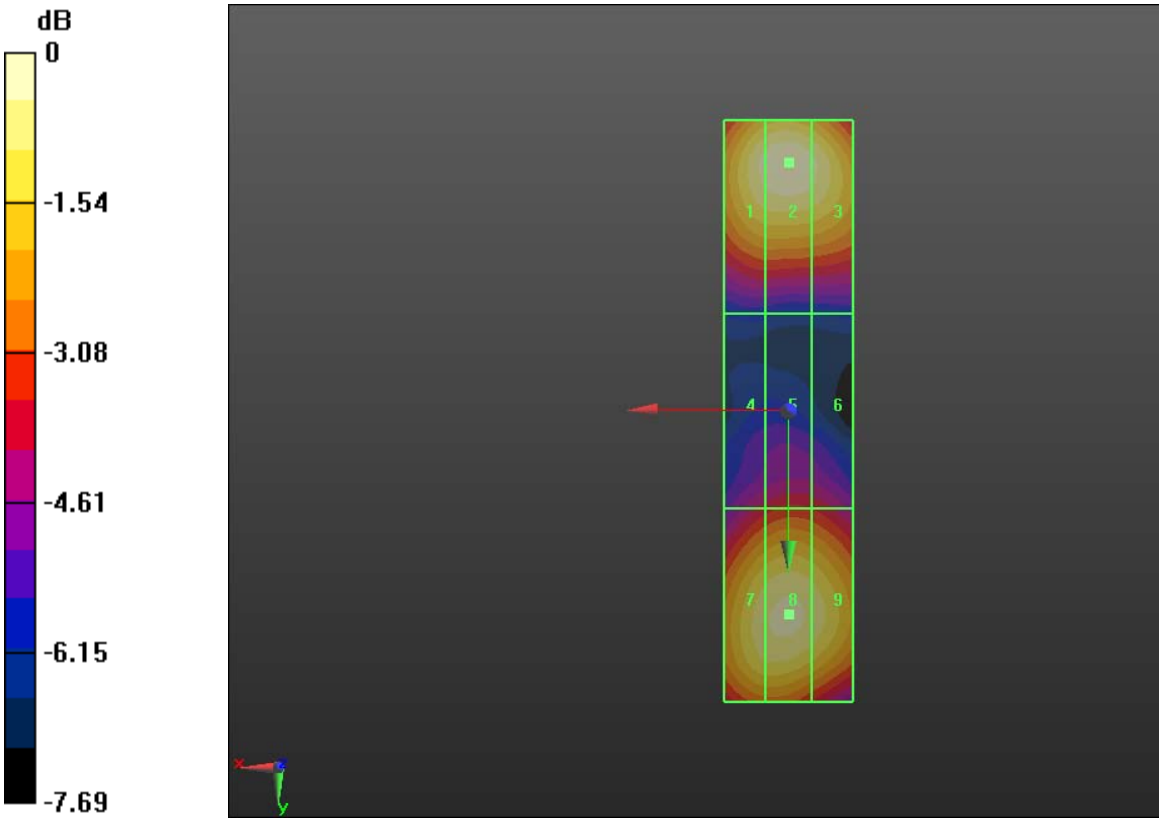
Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 82.216 V/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 78.932 V/m; Power Drift = 0.0039 dB
Hearing Aid Near-Field Category: M3 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **79.692 M3**	Grid 2 **82.216 M3**	Grid 3 **79.228 M3**
Grid 4 **52.849 M4**	Grid 5 **55.292 M4**	Grid 6 **54.232 M4**
Grid 7 **76.960 M3**	Grid 8 **78.815 M3**	Grid 9 **76.489 M3**

Cursor:

Total = 82.216 V/m
E Category: M3
Location: 0, -38.5, 4.7 mm



0 dB = 82.220V/m

Date/Time: 3/22/2011 4:12:07 PM

Test Laboratory: RIM Testing Services

HAC RF_E-Field_PMF_AM80%1880 MHz_GSM

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: AM 80%; Communication System Band: D1900 (1900.0 MHz);
Frequency: 1880 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

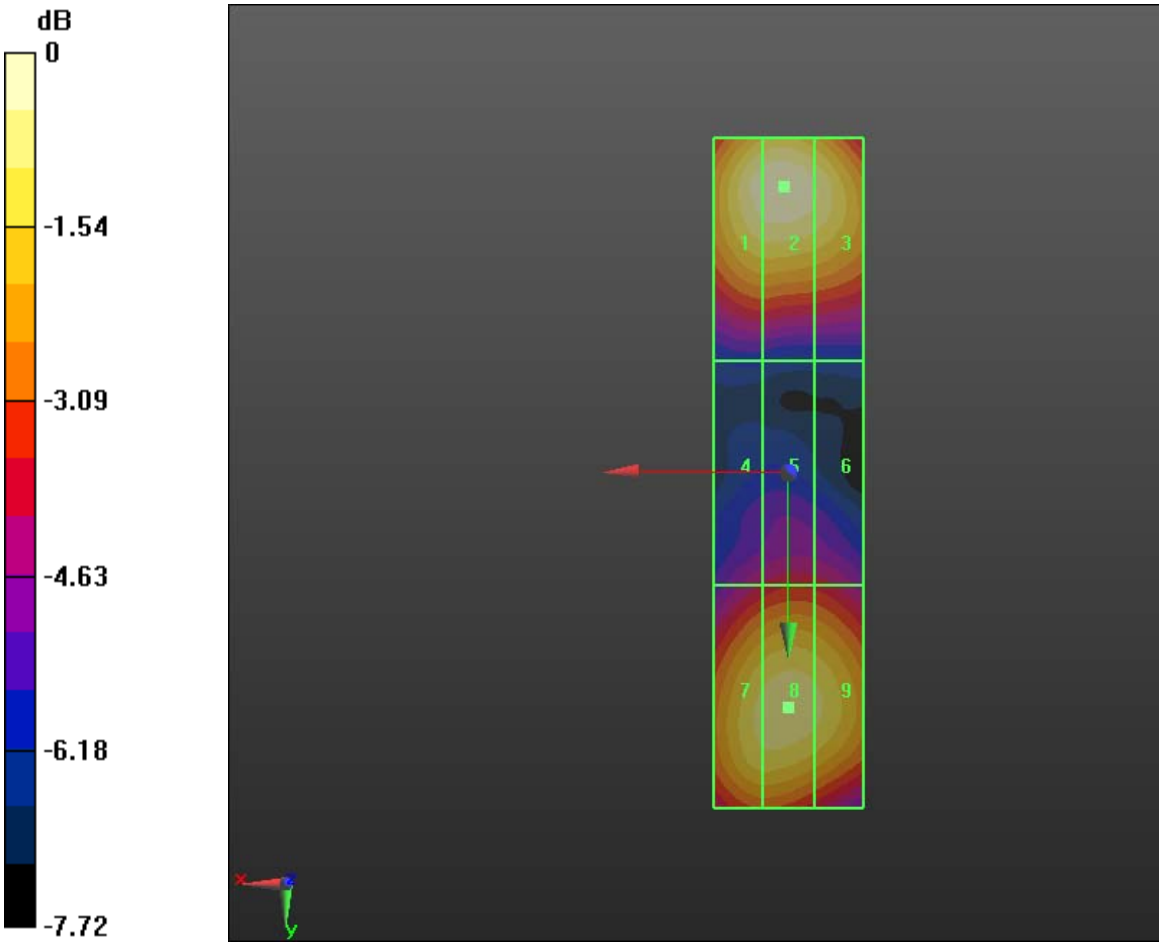
Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 53.337 V/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 49.939 V/m; Power Drift = -0.09 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **52.377 M4**	Grid 2 **53.337 M4**	Grid 3 **50.671 M4**
Grid 4 **3062 M4**	Grid 5 **35.058 M4**	Grid 6 **3043 M4**
Grid 7 **48.429 M4**	Grid 8 **49.374 M4**	Grid 9 **48.243 M4**

Cursor:

Total = 53.337 V/m
E Category: M4
Location: 0.5, -38.5, 4.7 mm



0 dB = 53.340V/m

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Test Laboratory: RIM Testing Services

HAC RF_H-Field_validation_835 MHz

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: CW; Communication System Band: D835 (835.0 MHz); Frequency: 835 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

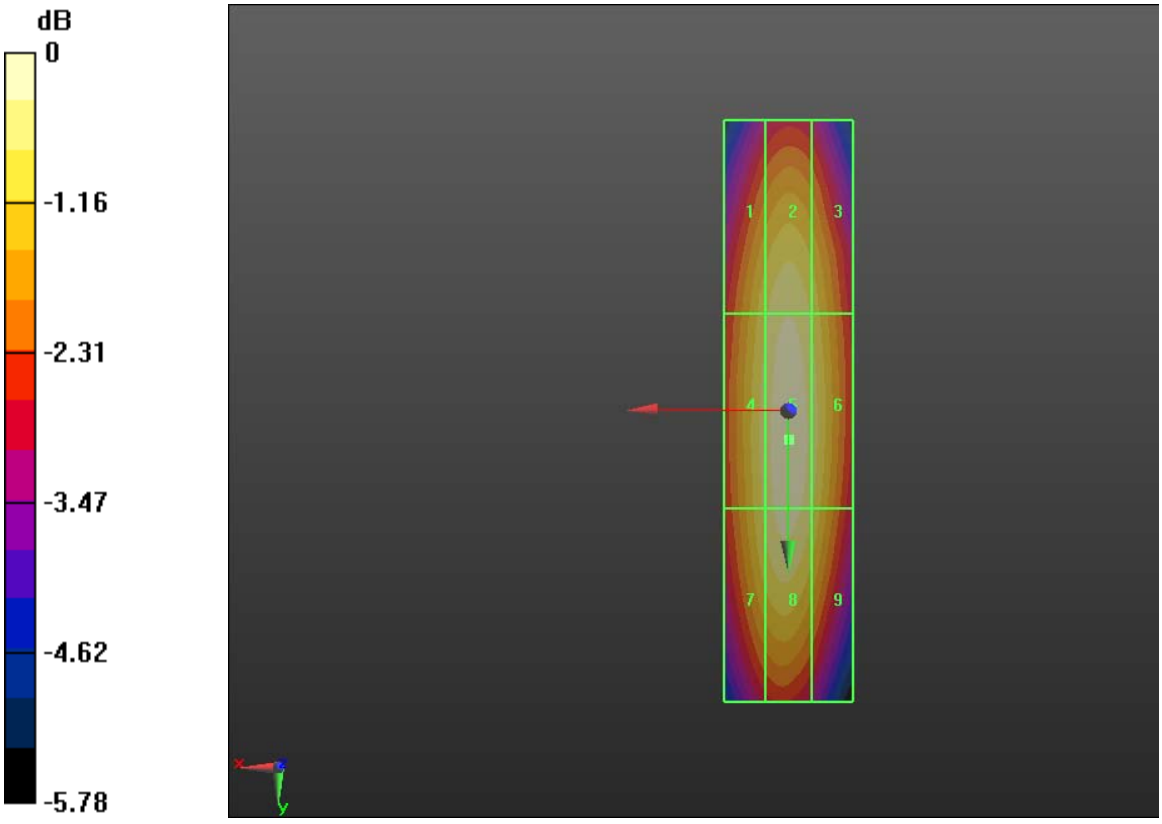
Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.475 A/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.514 A/m; Power Drift = -0.08 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.437 M4**	Grid 2 **0.459 M4**	Grid 3 **0.437 M4**
Grid 4 **0.453 M4**	Grid 5 **0.475 M4**	Grid 6 **0.453 M4**
Grid 7 **0.447 M4**	Grid 8 **0.469 M4**	Grid 9 **0.442 M4**

Cursor:

Total = 0.475 A/m
H Category: M4
Location: 0, 4.5, 4.7 mm



0 dB = 0.480A/m

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Test Laboratory: RIM Testing Services

HAC RF_H-Field_PMF_GSM_835 MHz

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: GSM 850; Frequency: 835 MHz;Communication System PAR: 9.191 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

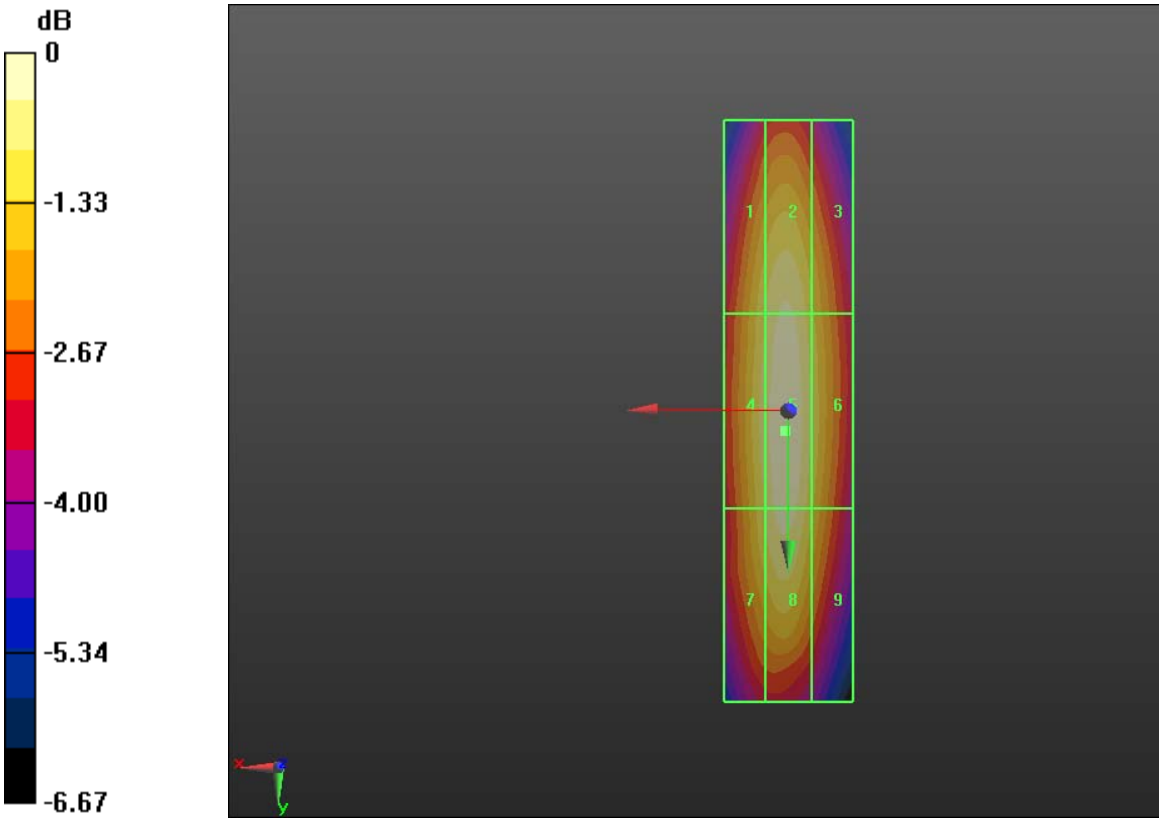
Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.168 A/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.173 A/m; Power Drift = 0.43 dB
Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m

Grid 1 **0.154 M4**	Grid 2 **0.163 M4**	Grid 3 **0.148 M4**
Grid 4 **0.159 M4**	Grid 5 **0.168 M4**	Grid 6 **0.153 M4**
Grid 7 **0.155 M4**	Grid 8 **0.165 M4**	Grid 9 **0.148 M4**

Cursor:

Total = 0.168 A/m
H Category: M4
Location: 0.5, 3, 4.7 mm



0 dB = 0.170A/m

Date/Time: 3/23/2011 3:23:34 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_PMF_CW835 MHz_GSM

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: CW; Communication System Band: D835 (835.0 MHz); Frequency: 835 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

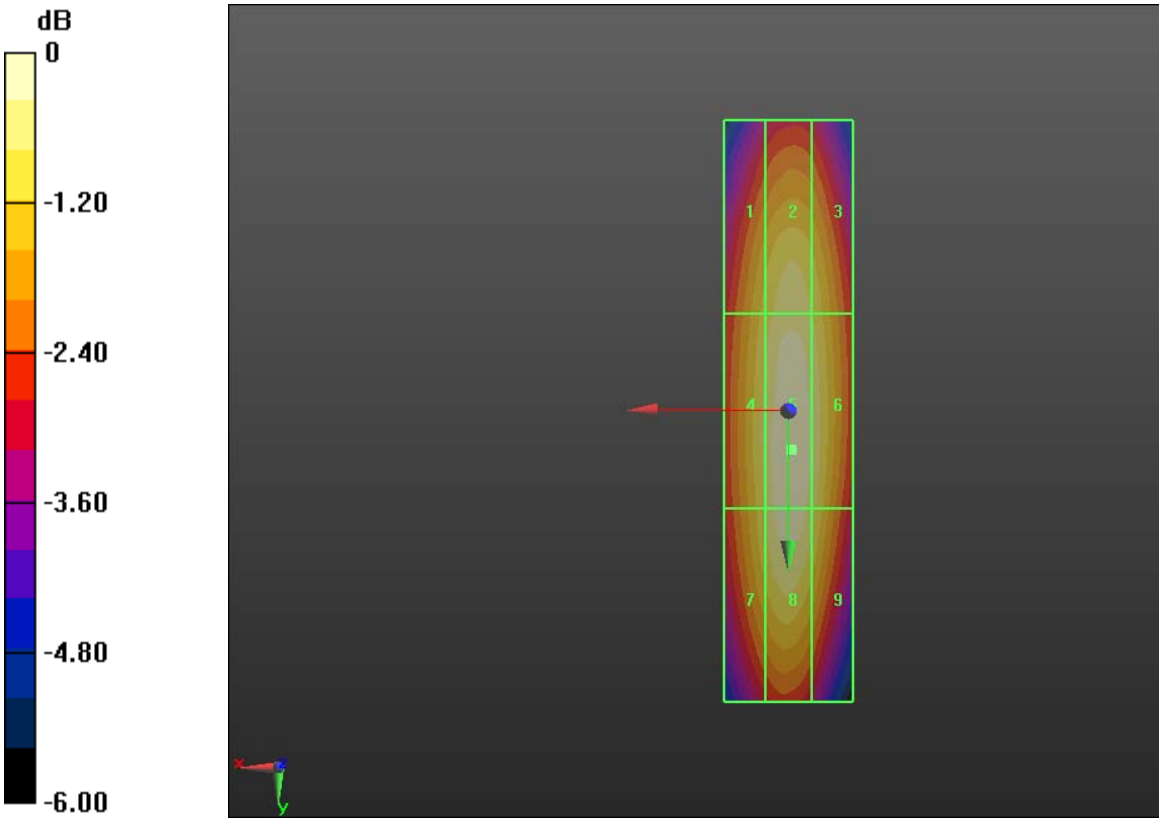
Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.482 A/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.503 A/m; Power Drift = -0.00099 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.429 M4**	Grid 2 **0.450 M4**	Grid 3 **0.439 M4**
Grid 4 **0.449 M4**	Grid 5 **0.482 M4**	Grid 6 **0.458 M4**
Grid 7 **0.441 M4**	Grid 8 **0.475 M4**	Grid 9 **0.448 M4**

Cursor:

Total = 0.482 A/m
H Category: M4
Location: -0.5, 6, 4.7 mm



0 dB = 0.480A/m

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Test Laboratory: RIM Testing Services

HAC RF_H-Field_PMF_AM80%835 MHz_GSM

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: AM 80%; Communication System Band: D835 (835.0 MHz);
Frequency: 835 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

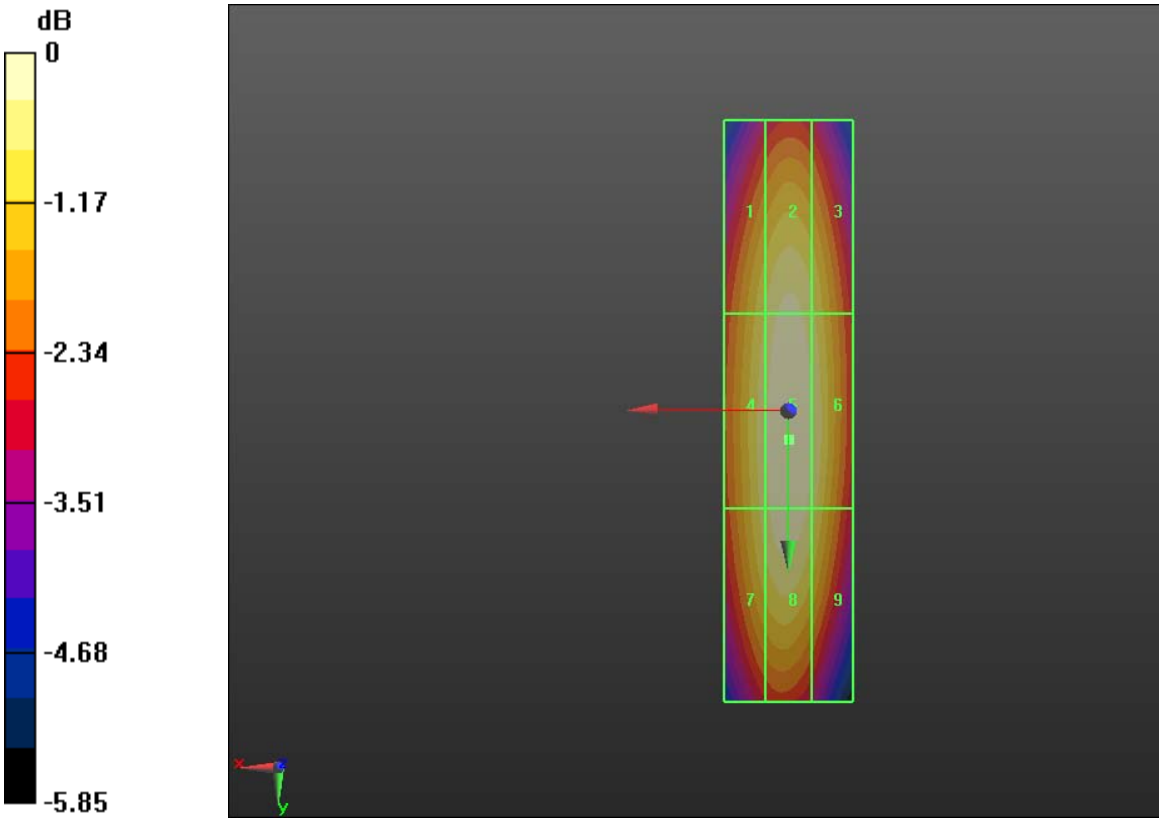
Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.302 A/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.326 A/m; Power Drift = -0.16 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.276 M4**	Grid 2 **0.292 M4**	Grid 3 **0.279 M4**
Grid 4 **0.286 M4**	Grid 5 **0.302 M4**	Grid 6 **0.289 M4**
Grid 7 **0.283 M4**	Grid 8 **0.299 M4**	Grid 9 **0.281 M4**

Cursor:

Total = 0.302 A/m
H Category: M4
Location: 0, 4.5, 4.7 mm



0 dB = 0.300A/m

Date/Time: 3/23/2011 12:47:34 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_validation_1880 MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Communication System Band: D1900 (1900.0 MHz); Frequency: 1880 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

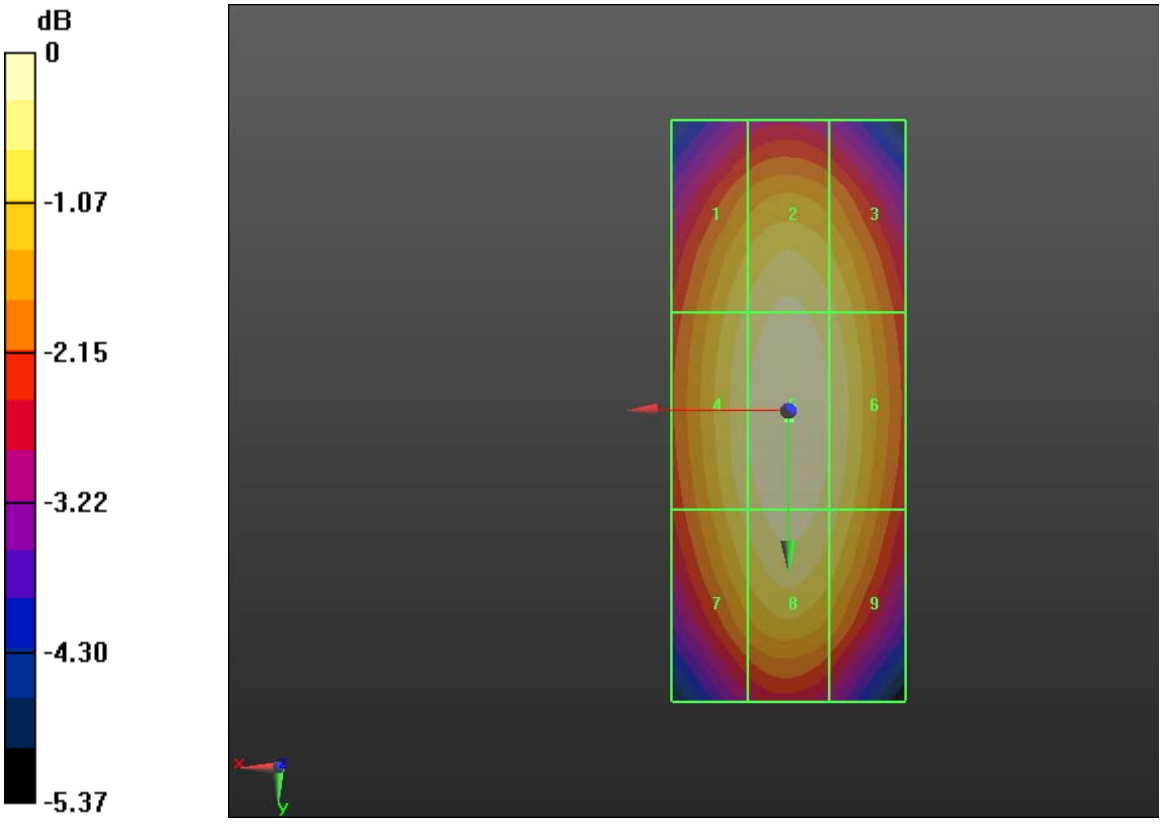
Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.451 A/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.479 A/m; Power Drift = -0.02 dB
Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.419 M2**	Grid 2 **0.436 M2**	Grid 3 **0.420 M2**
Grid 4 **0.432 M2**	Grid 5 **0.451 M2**	Grid 6 **0.434 M2**
Grid 7 **0.421 M2**	Grid 8 **0.442 M2**	Grid 9 **0.423 M2**

Cursor:

Total = 0.451 A/m
H Category: M2
Location: 0, 0.5, 4.7 mm



0 dB = 0.450A/m

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Test Laboratory: RIM Testing Services

HAC RF_H-Field_PMF_GSM_1880 MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: GSM 1900; Frequency: 1880 MHz;Communication System PAR: 9.191 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

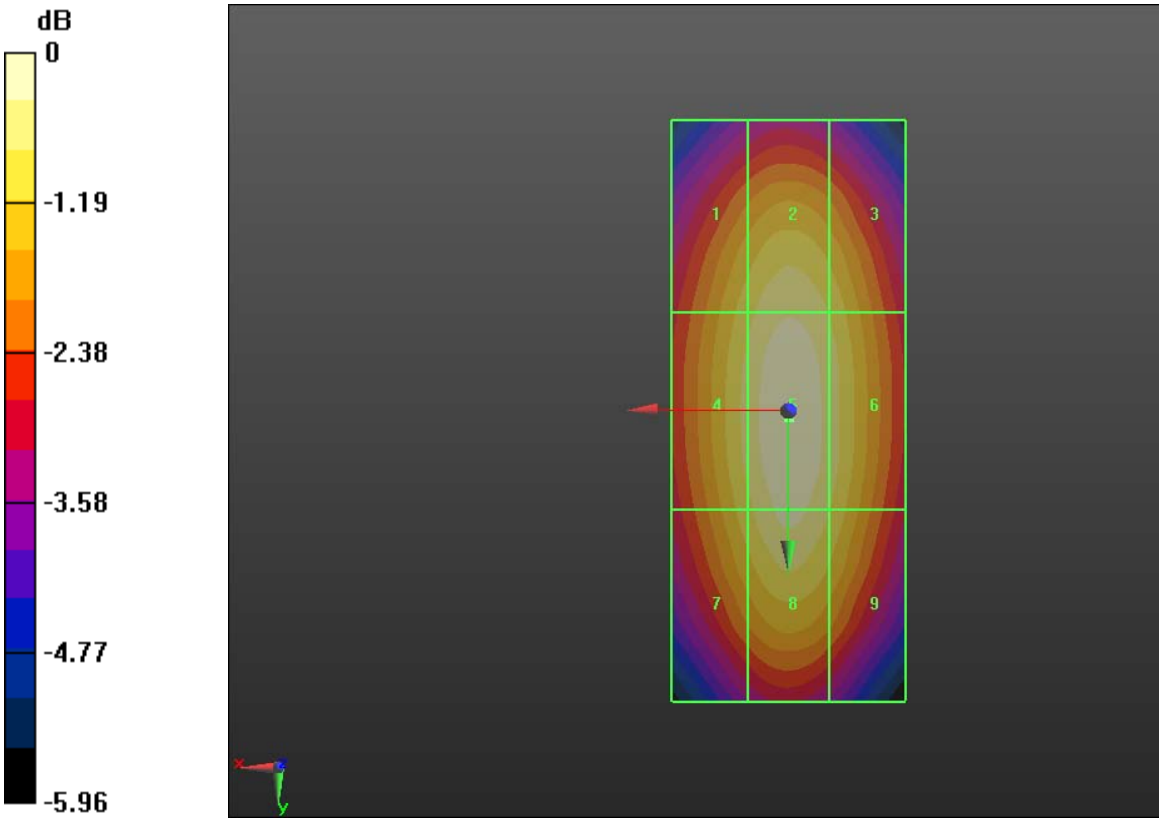
Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.099 A/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.105 A/m; Power Drift = 0.04 dB
Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m

Grid 1 **0.090 M4**	Grid 2 **0.095 M4**	Grid 3 **0.091 M4**
Grid 4 **0.093 M4**	Grid 5 **0.099 M4**	Grid 6 **0.094 M4**
Grid 7 **0.090 M4**	Grid 8 **0.097 M4**	Grid 9 **0.091 M4**

Cursor:

Total = 0.099 A/m
H Category: M4
Location: 0, 0.5, 4.7 mm



0 dB = 0.100A/m

Date/Time: 3/23/2011 12:41:56 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_PMF_CW1880 MHz_GSM

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Communication System Band: D1900 (1900.0 MHz); Frequency: 1880 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

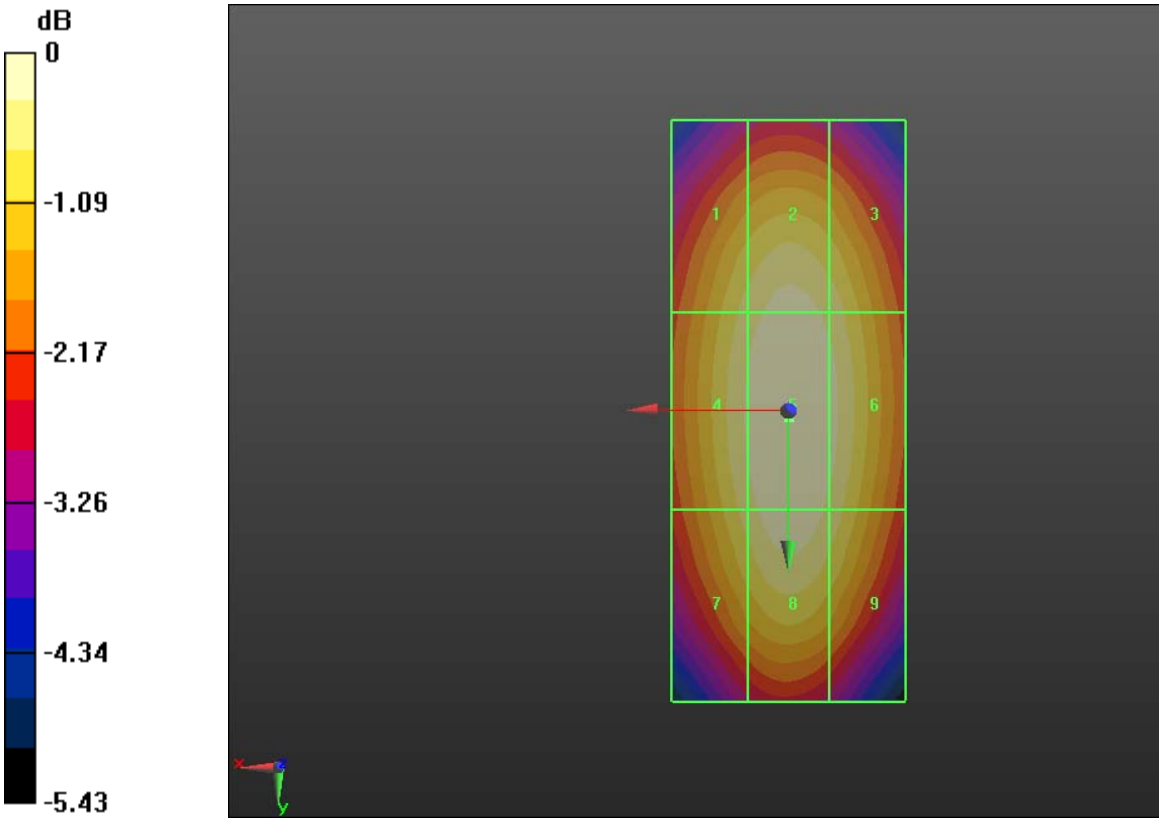
Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.284 A/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.302 A/m; Power Drift = -0.03 dB
Hearing Aid Near-Field Category: M3 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.263 M3**	Grid 2 **0.274 M3**	Grid 3 **0.265 M3**
Grid 4 **0.271 M3**	Grid 5 **0.284 M3**	Grid 6 **0.274 M3**
Grid 7 **0.263 M3**	Grid 8 **0.278 M3**	Grid 9 **0.266 M3**

Cursor:

Total = 0.284 A/m
H Category: M3
Location: 0, 0.5, 4.7 mm



0 dB = 0.280A/m

Date/Time: 3/23/2011 12:51:39 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_PMF_AM80%1880 MHz_GSM

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: AM 80%; Communication System Band: D1900 (1900.0 MHz);
Frequency: 1880 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: TCoil Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

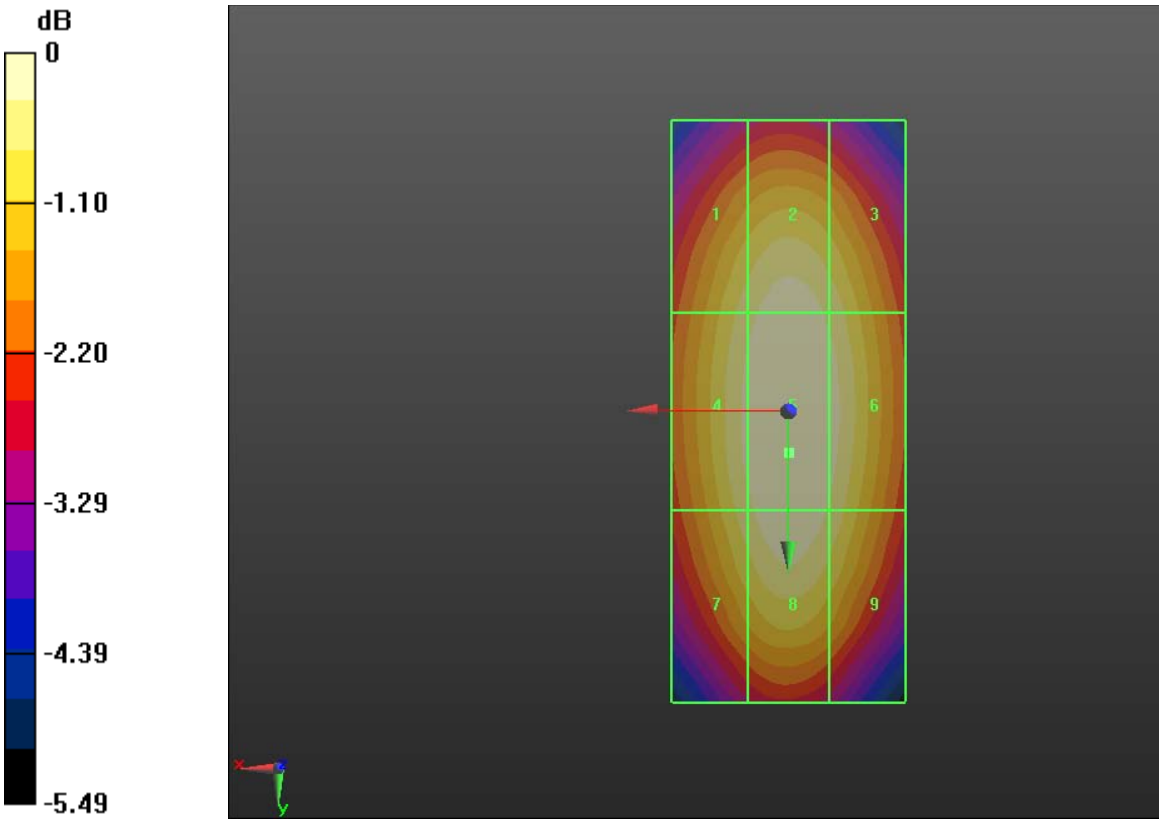
DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.184 A/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.196 A/m; Power Drift = -0.02 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.170 M4**	Grid 2 **0.178 M4**	Grid 3 **0.171 M4**
Grid 4 **0.175 M4**	Grid 5 **0.184 M4**	Grid 6 **0.177 M4**
Grid 7 **0.170 M4**	Grid 8 **0.180 M4**	Grid 9 **0.172 M4**



0 dB = 0.180A/m

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Test Laboratory: RIM Testing Services

HAC RF_E-Field_1733 MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: WCDMA FDD IV, Communication System: CW, Communication System: AM80%; Communication System Band: 1733; Frequency: 1732.6 MHz, Frequency: 1733 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 45.953 V/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 45.671 V/m; Power Drift = 0.0022 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **44.309 M4**	Grid 2 **45.897 M4**	Grid 3 **43.942 M4**
Grid 4 **32.194 M4**	Grid 5 **33.381 M4**	Grid 6 **32.650 M4**
Grid 7 **45.541 M4**	Grid 8 **45.953 M4**	Grid 9 **44.163 M4**

Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm 2/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 44.684 V/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 44.777 V/m; Power Drift = -0.03 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

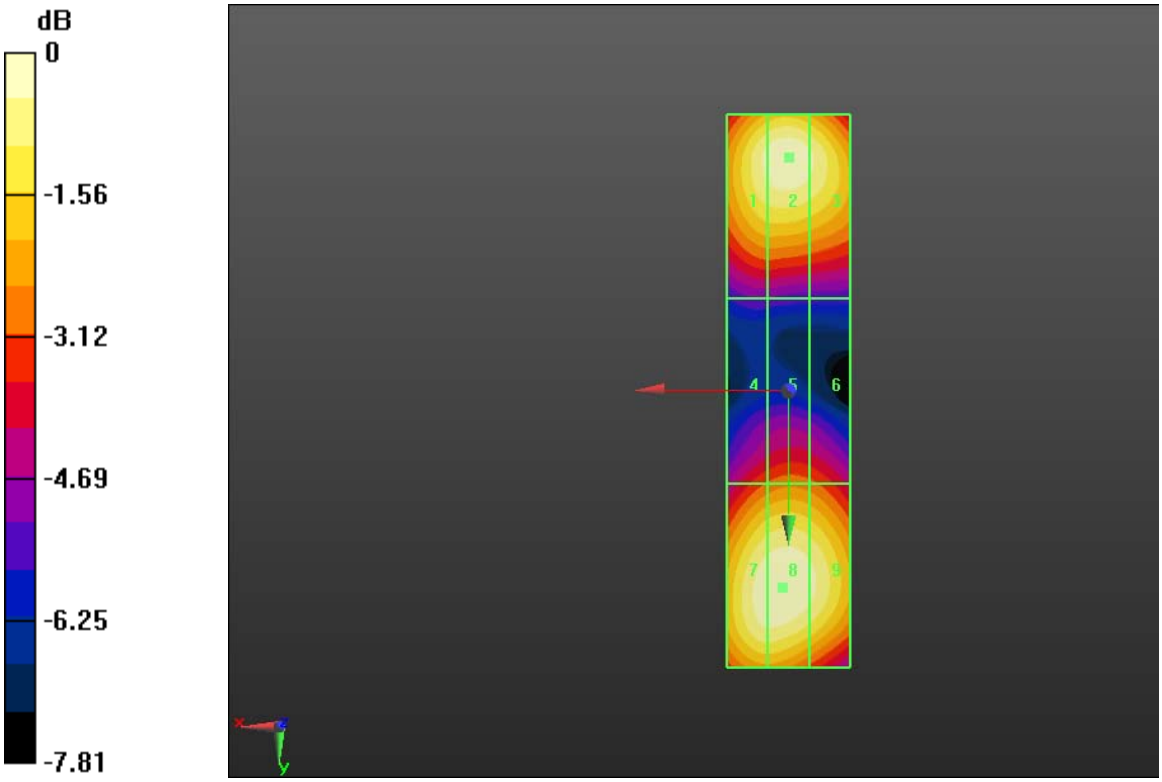
Grid 1 **42.576 M4**	Grid 2 **44.154 M4**	Grid 3 **42.558 M4**
Grid 4 **31.220 M4**	Grid 5 **32.494 M4**	Grid 6 **31.749 M4**
Grid 7 **44.140 M4**	Grid 8 **44.684 M4**	Grid 9 **42.994 M4**

Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm 2 2/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 28.697 V/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 28.666 V/m; Power Drift = -0.03 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **27.579 M4**	Grid 2 **28.576 M4**	Grid 3 **27.503 M4**
Grid 4 **20.034 M4**	Grid 5 **20.866 M4**	Grid 6 **20.402 M4**
Grid 7 **28.387 M4**	Grid 8 **28.697 M4**	Grid 9 **27.712 M4**



0 dB = 45.950V/m

Date/Time: 5/13/2011 2:33:55 PM

Test Laboratory: RIM Testing Services

HAC RF_E-Field_validation_1880 MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Communication System Band: D1900 (1900.0 MHz); Frequency: 1880 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

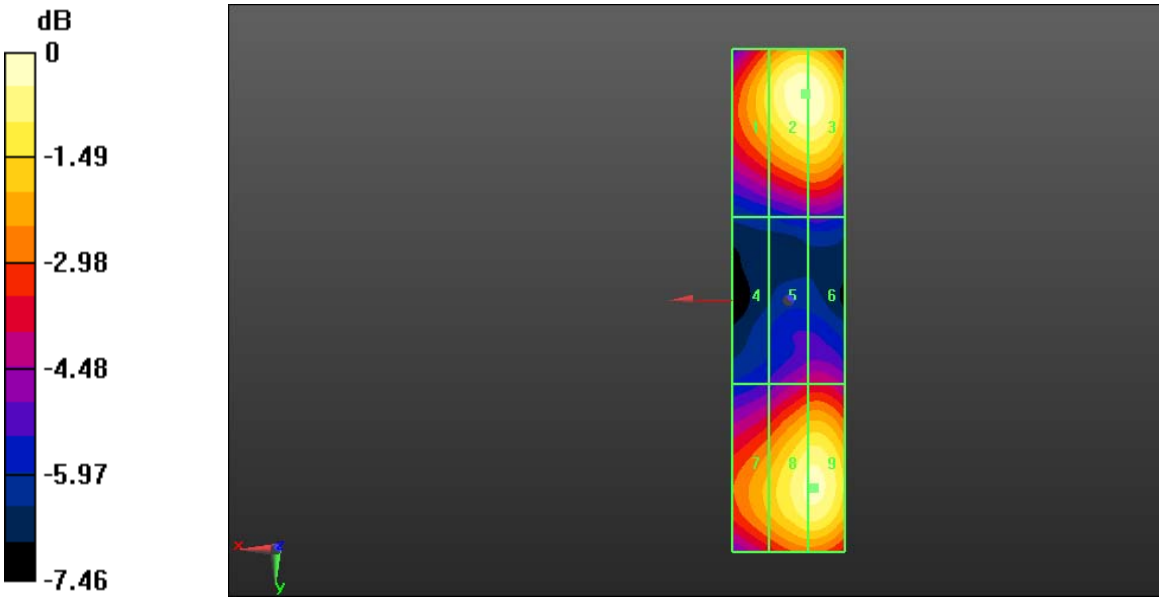
Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 131.2 V/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 120.2 V/m; Power Drift = 0.06 dB
Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **113.9 M2**	Grid 2 **131.2 M2**	Grid 3 **131.0 M2**
Grid 4 **71.642 M3**	Grid 5 **83.292 M3**	Grid 6 **84.259 M3**
Grid 7 **107.3 M3**	Grid 8 **126.1 M2**	Grid 9 **127.0 M2**

Cursor:

Total = 131.2 V/m
E Category: M2
Location: -3, -37, 4.7 mm



0 dB = 131.2V/m

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Test Laboratory: RIM Testing Services

HAC RF_H-Field_1733 MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: WCDMA FDD IV, Communication System: CW, Communication System: AM80%; Communication System Band: D1800 (1800.0 MHz); Frequency: 1732.6 MHz, Frequency: 1733 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole H-Field with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.165 A/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.175 A/m; Power Drift = -0.0064 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.148 M4**	Grid 2 **0.156 M4**	Grid 3 **0.151 M4**
Grid 4 **0.156 M4**	Grid 5 **0.165 M4**	Grid 6 **0.159 M4**
Grid 7 **0.151 M4**	Grid 8 **0.160 M4**	Grid 9 **0.153 M4**

Dipole H-Field with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm 2/Hearing Aid Compatibility Test (41x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.160 A/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.172 A/m; Power Drift = -0.08 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

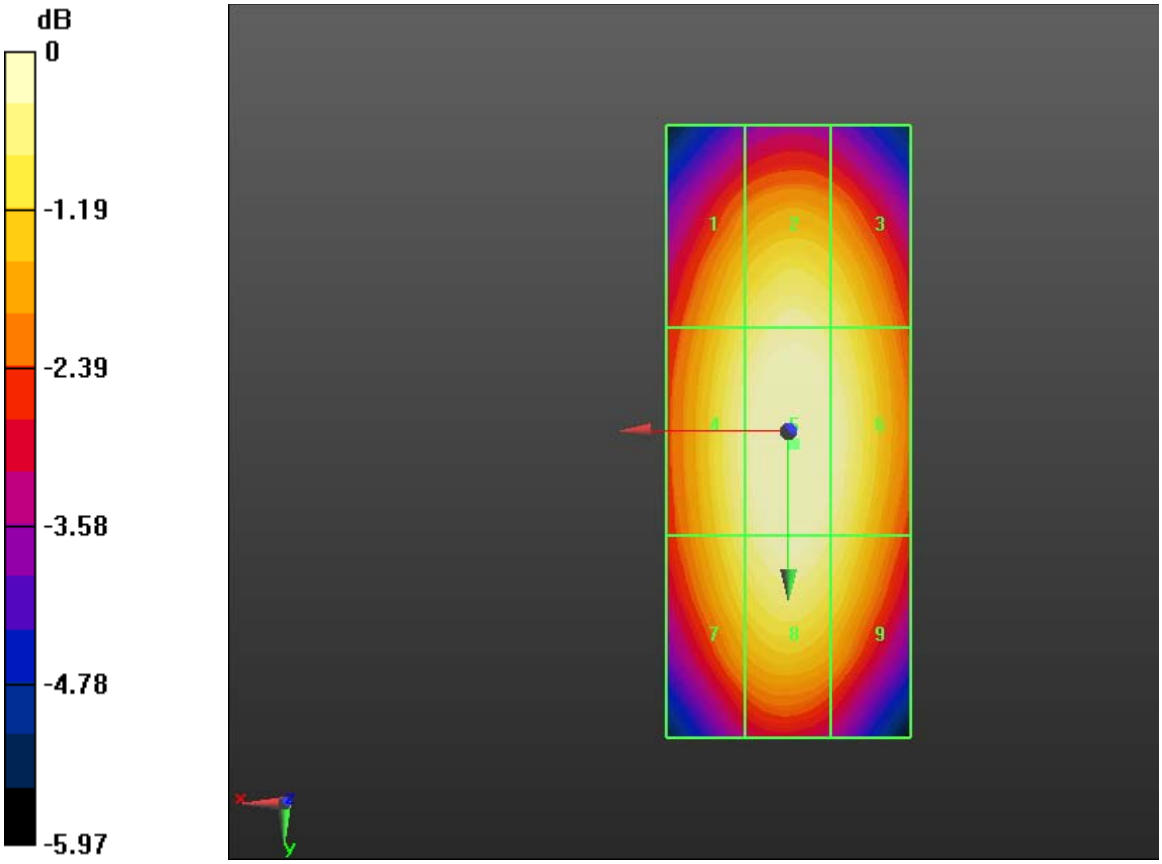
Grid 1 **0.144 M4**	Grid 2 **0.151 M4**	Grid 3 **0.147 M4**
Grid 4 **0.152 M4**	Grid 5 **0.160 M4**	Grid 6 **0.155 M4**
Grid 7 **0.148 M4**	Grid 8 **0.156 M4**	Grid 9 **0.149 M4**

Dipole H-Field with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm 2 2/Hearing Aid Compatibility Test (41x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.102 A/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.110 A/m; Power Drift = -0.04 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.091 M4**	Grid 2 **0.097 M4**	Grid 3 **0.093 M4**
Grid 4 **0.096 M4**	Grid 5 **0.102 M4**	Grid 6 **0.098 M4**
Grid 7 **0.093 M4**	Grid 8 **0.099 M4**	Grid 9 **0.094 M4**



0 dB = 0.160A/m

Date/Time: 5/13/2011 2:44:07 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_validation_1880 MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Communication System Band: D1900 (1900.0 MHz); Frequency: 1880 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

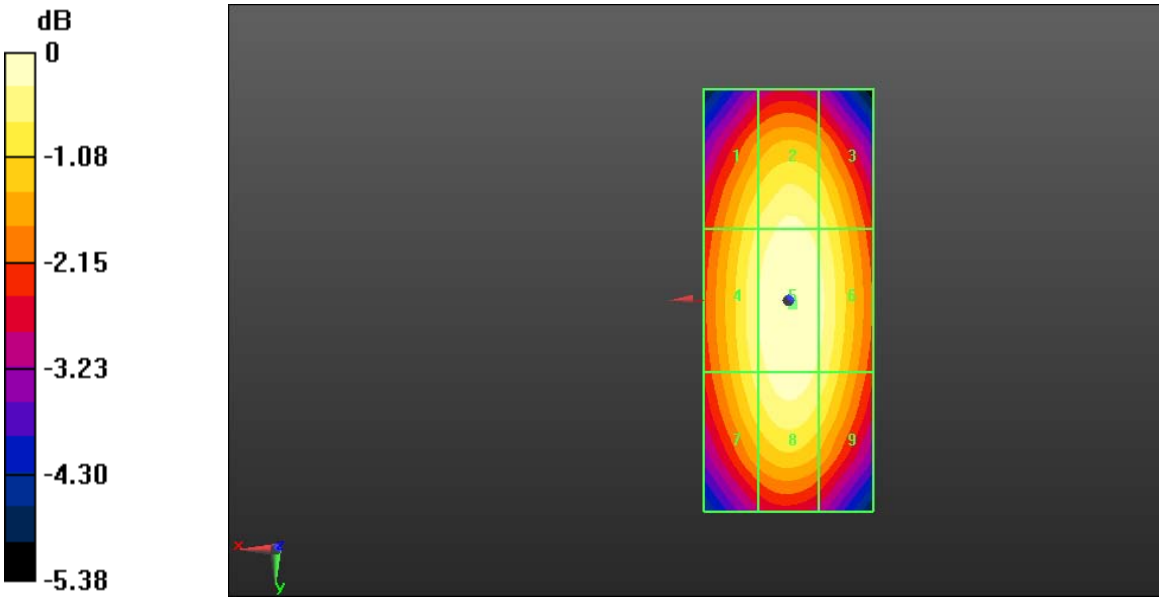
Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.455 A/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.484 A/m; Power Drift = -0.02 dB
Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.418 M2**	Grid 2 **0.437 M2**	Grid 3 **0.425 M2**
Grid 4 **0.432 M2**	Grid 5 **0.455 M2**	Grid 6 **0.439 M2**
Grid 7 **0.424 M2**	Grid 8 **0.445 M2**	Grid 9 **0.428 M2**

Cursor:

Total = 0.455 A/m
H Category: M2
Location: -0.5, 0.5, 4.7 mm



0 dB = 0.450A/m

Date/Time: 7/11/2011 11:23:27 AM

Test Laboratory: RIM Testing Services

HAC RF_E-Field_validation_835 MHz

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: CW; Communication System Band: D835 (835.0 MHz); Frequency: 835 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 3/7/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

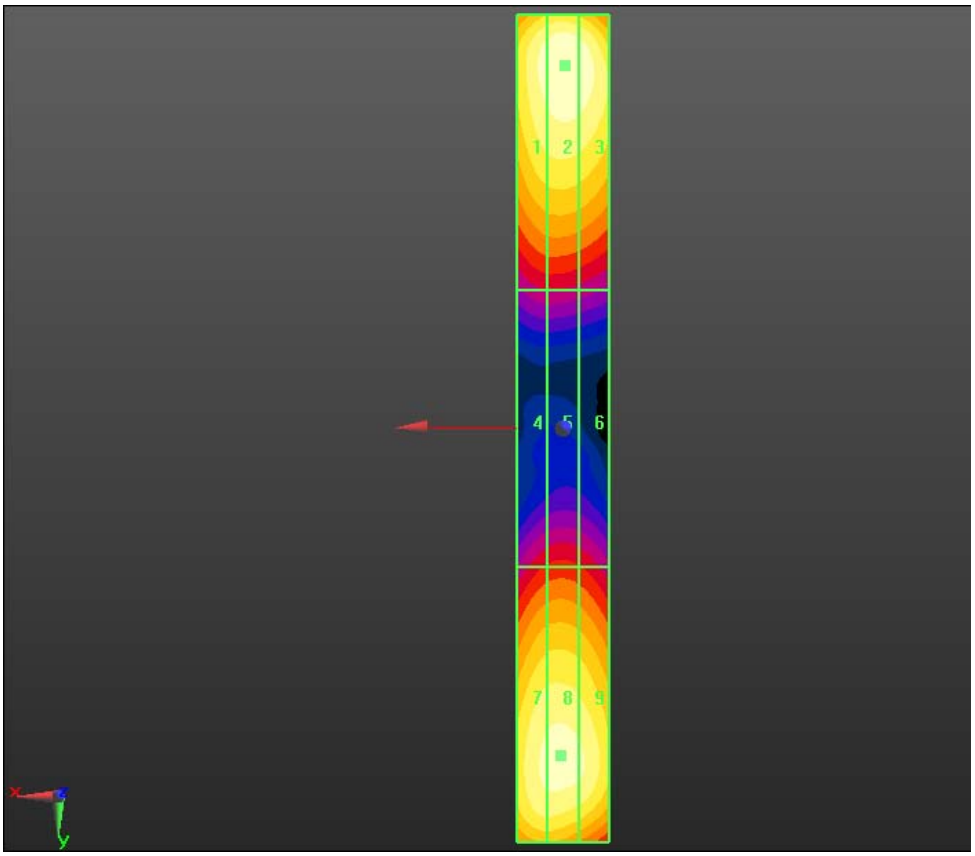
Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 164.6 V/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 119.5 V/m; Power Drift = -0.18 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **157.8 M4**	Grid 2 **164.6 M4**	Grid 3 **161.2 M4**
Grid 4 **83.084 M4**	Grid 5 **84.987 M4**	Grid 6 **82.687 M4**
Grid 7 **153.1 M4**	Grid 8 **155.5 M4**	Grid 9 **152.0 M4**

Cursor:

Total = 164.6 V/m
E Category: M4
Location: -0.5, -79, 4.7 mm



0 dB = 164.6V/m

Date/Time: 7/11/2011 11:41:33 AM

Test Laboratory: RIM Testing Services

HAC RF_E-Field_validation_1880 MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Communication System Band: D1900 (1900.0 MHz); Frequency: 1880 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 3/7/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

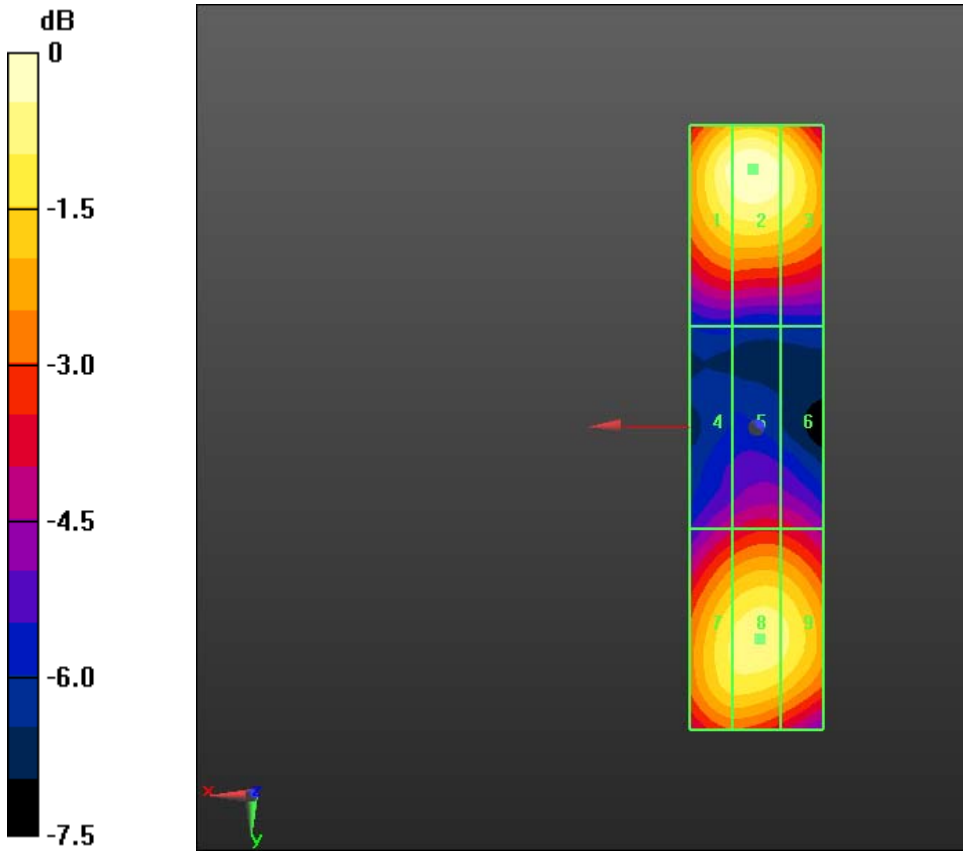
Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 132.4 V/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 122.0 V/m; Power Drift = -0.01 dB
Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **128.6 M2**	Grid 2 **132.4 M2**	Grid 3 **125.9 M2**
Grid 4 **82.565 M3**	Grid 5 **87.292 M3**	Grid 6 **86.553 M3**
Grid 7 **119.4 M2**	Grid 8 **122.5 M2**	Grid 9 **120.6 M2**

Cursor:

Total = 132.4 V/m
E Category: M2
Location: 0.5, -38.5, 4.7 mm



0 dB = 132.4V/m

Date/Time: 7/11/2011 2:26:24 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_validation_835 MHz

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: CW; Communication System Band: D835 (835.0 MHz); Frequency: 835 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 3/7/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

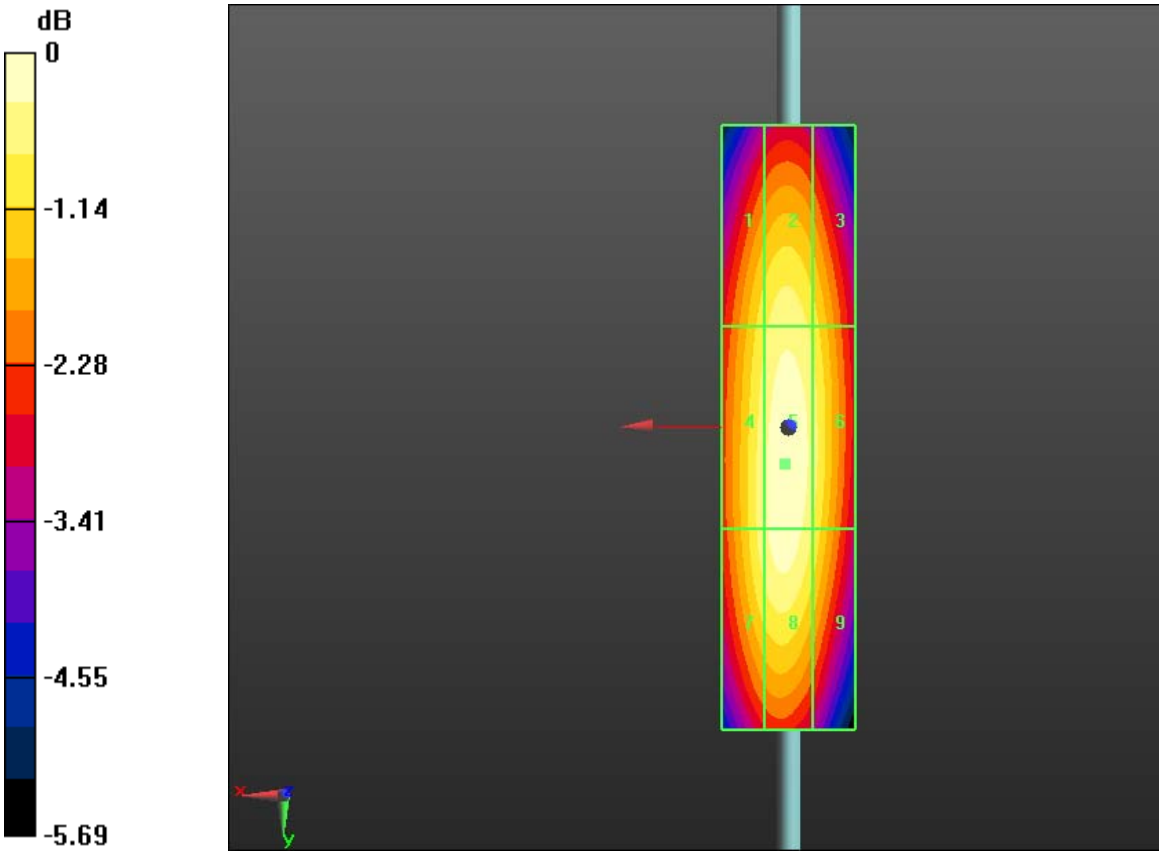
Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.469 A/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.495 A/m; Power Drift = 0.03 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.427 M4**	Grid 2 **0.444 M4**	Grid 3 **0.425 M4**
Grid 4 **0.448 M4**	Grid 5 **0.469 M4**	Grid 6 **0.443 M4**
Grid 7 **0.446 M4**	Grid 8 **0.463 M4**	Grid 9 **0.432 M4**

Cursor:

Total = 0.469 A/m
H Category: M4
Location: 0.5, 5.5, 4.7 mm



0 dB = 0.470A/m

Date/Time: 7/11/2011 2:34:34 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_validation_1880 MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Communication System Band: D1900 (1900.0 MHz); Frequency: 1880 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 3/7/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

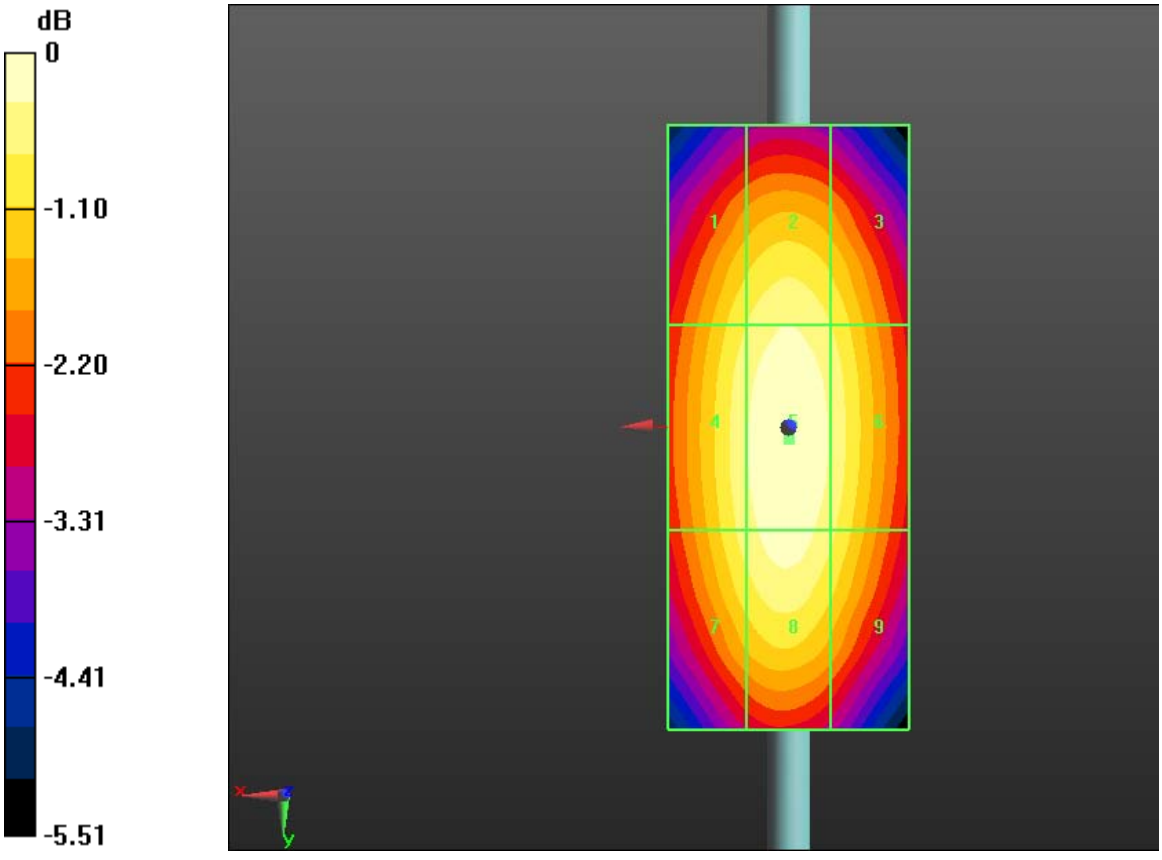
Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.461 A/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.490 A/m; Power Drift = 0.02 dB
Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.423 M2**	Grid 2 **0.441 M2**	Grid 3 **0.423 M2**
Grid 4 **0.439 M2**	Grid 5 **0.461 M2**	Grid 6 **0.439 M2**
Grid 7 **0.432 M2**	Grid 8 **0.453 M2**	Grid 9 **0.428 M2**

Cursor:

Total = 0.461 A/m
H Category: M2
Location: 0, 1, 4.7 mm



0 dB = 0.460A/m

Date/Time: 2/28/2011 1:07:46 PM

Test Laboratory: RIM Testing Services

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: WCDMA FDD V; Communication System Band:; Frequency: 835 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

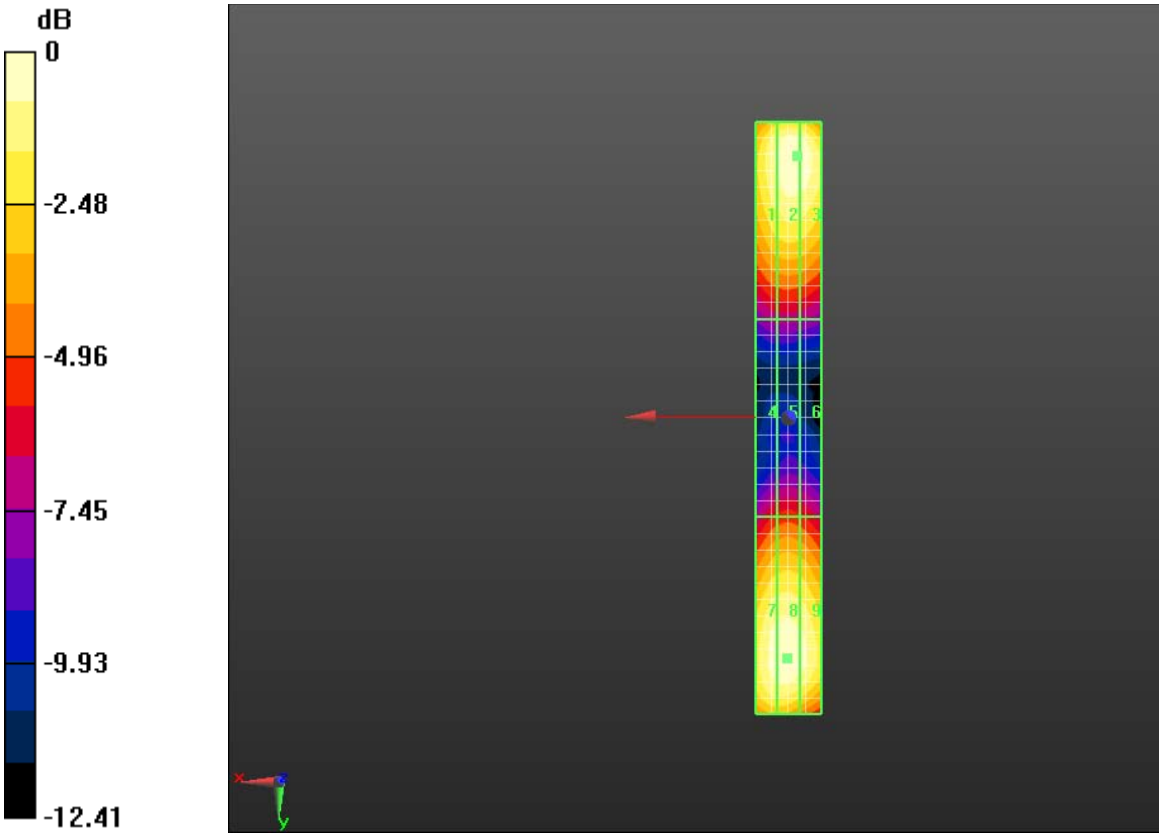
Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 56.944 V/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 42.995 V/m; Power Drift = 0.01 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **53.505 M4**	Grid 2 **56.944 M4**	Grid 3 **56.718 M4**
Grid 4 **30.372 M4**	Grid 5 **31.039 M4**	Grid 6 **30.245 M4**
Grid 7 **54.971 M4**	Grid 8 **56.115 M4**	Grid 9 **54.501 M4**

Cursor:

Total = 56.944 V/m
E Category: M4
Location: -2.5, -79.5, 4.7 mm



0 dB = 56.940V/m

Date/Time: 2/28/2011 12:43:40 PM

Test Laboratory: RIM Testing Services

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: CW; Communication System Band: D835 (835.0 MHz); Frequency: 835 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

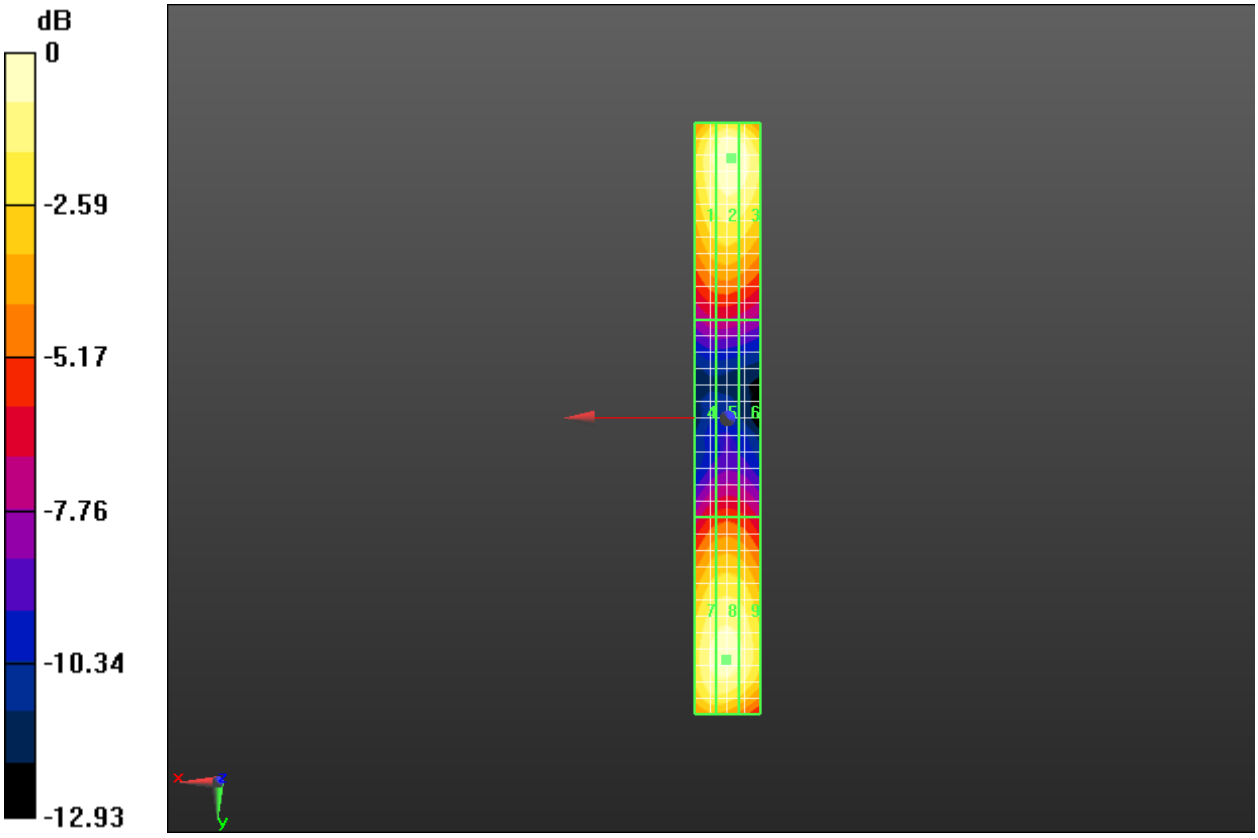
- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 57.608 V/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 42.622 V/m; Power Drift = -0.06 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **54.388 M4**	Grid 2 **57.608 M4**	Grid 3 **56.620 M4**
Grid 4 **30.355 M4**	Grid 5 **30.943 M4**	Grid 6 **30.261 M4**
Grid 7 **54.334 M4**	Grid 8 **55.102 M4**	Grid 9 **5076 M4**

Cursor:
Total = 57.608 V/m
E Category: M4
Location: -1, -79, 4.7 mm



0 dB = 57.610V/m

Date/Time: 2/28/2011 12:54:03 PM

Test Laboratory: RIM Testing Services

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: AM 80%; Communication System Band: D835 (835.0 MHz);
Frequency: 835 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

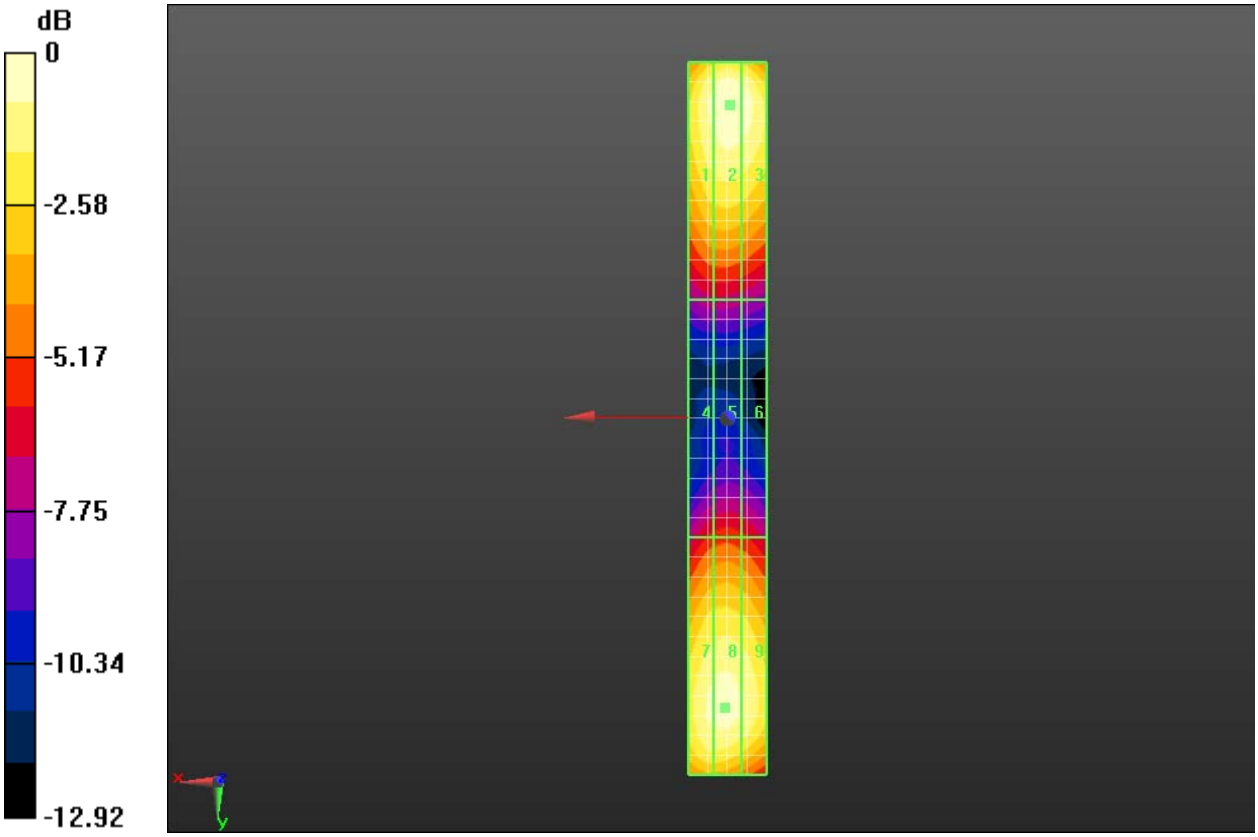
- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 37.106 V/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 26.469 V/m; Power Drift = 0.17 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **35.158 M4**	Grid 2 **37.106 M4**	Grid 3 **36.227 M4**
Grid 4 **19.445 M4**	Grid 5 **19.878 M4**	Grid 6 **19.259 M4**
Grid 7 **34.812 M4**	Grid 8 **35.203 M4**	Grid 9 **34.158 M4**

Cursor:
Total = 37.106 V/m
E Category: M4
Location: -0.5, -79, 4.7 mm



0 dB = 37.110V/m

Date/Time: 6/21/2011 3:33:41 PM

Test Laboratory: RIM Testing Services

HAC RF_E-Field_validation_PMF_835 MHz

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: CW, Communication System: CDMA 850, Communication System: CDMA 800; Communication System Band: D835 (835.0 MHz), Communication System Band: CDMA 2000 Cellular, Communication System Band: CDMA 2000 BC 10 ; Frequency: 835 MHz, Frequency: 820.5 MHz;Communication System PAR: 0, Communication System PAR: 9.19 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 3/7/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

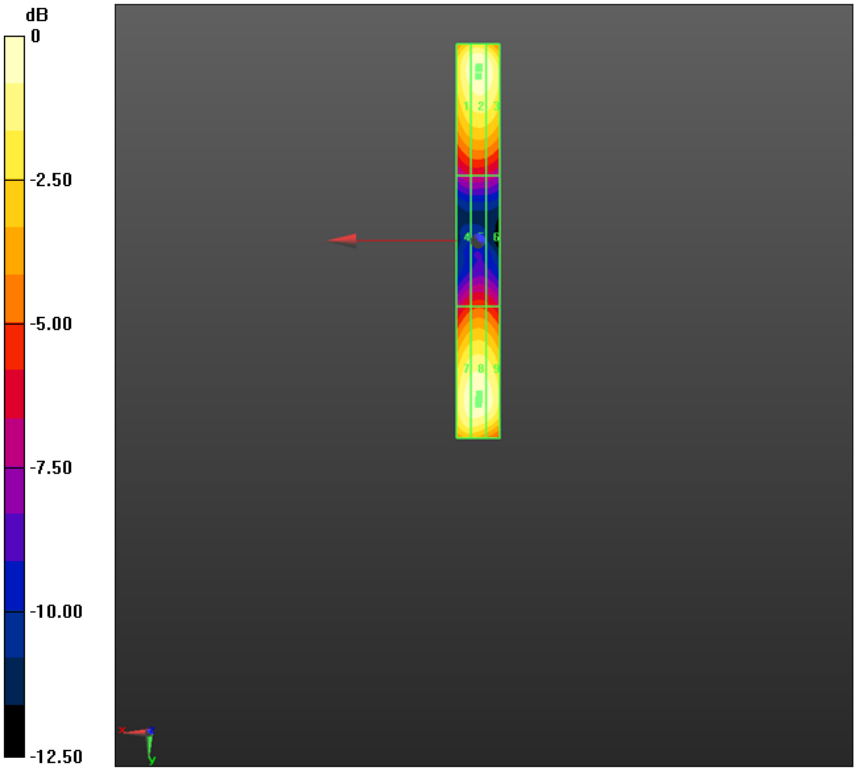
Dipole E-Field measurement/E Scan _CW_20dB_Validation - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 157.1 V/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 120.5 V/m; Power Drift = 0.01 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3

150.7 M4	**157.1 M4**	**154.2 M4**
Grid 4 **84.223 M4**	Grid 5 **87.459 M4**	Grid 6 **85.298 M4**
Grid 7 **151.8 M4**	Grid 8 **155.1 M4**	Grid 9 **152.4 M4**

Cursor:
Total = 157.1 V/m
E Category: M4
Location: -0.5, -79, 4.7 mm



0 dB = 157.1V/m

Date/Time: 2/28/2011 2:07:15 PM

Test Laboratory: RIM Testing Services

HAC RF_E-Field_PMF_UMTS_band_II_1880 MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial

Communication System: WCDMA FDD II;.; Frequency: 1880 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

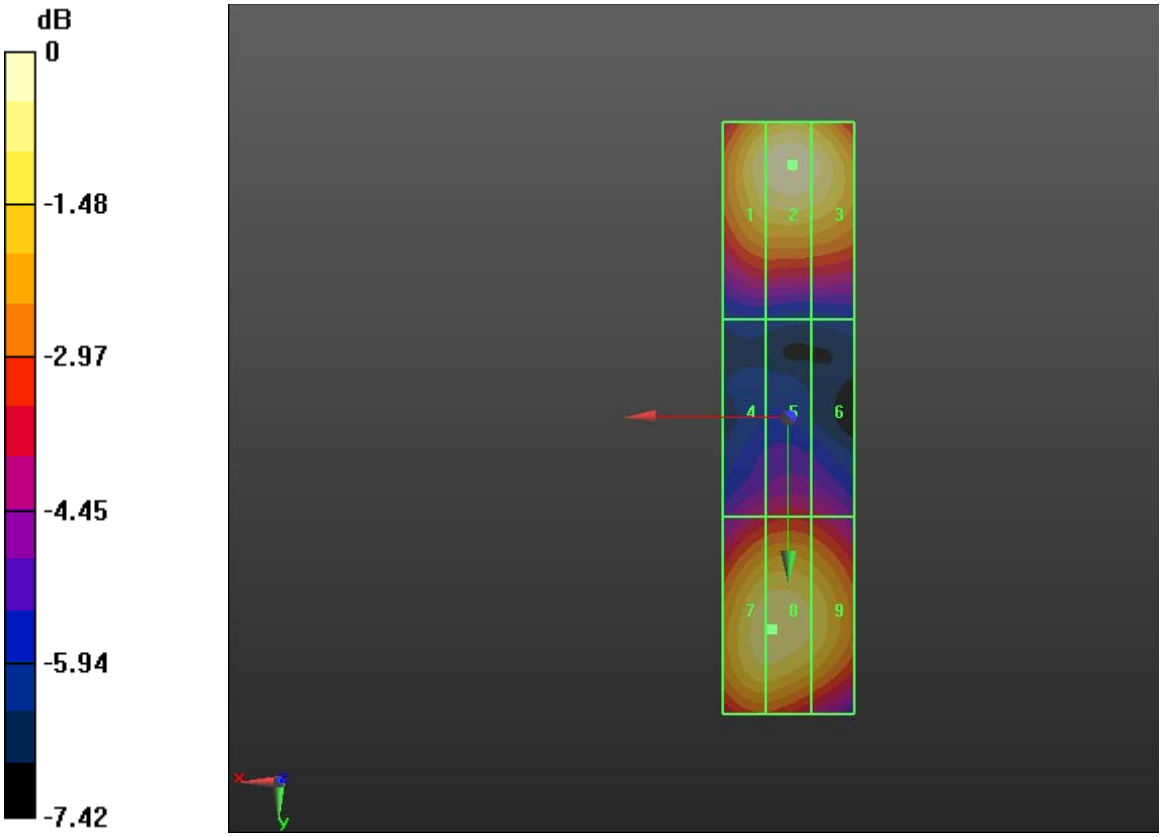
Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 38.483 V/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 35.028 V/m; Power Drift = 0.10 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **36.706 M4**	Grid 2 **38.483 M4**	Grid 3 **37.337 M4**
Grid 4 **24.878 M4**	Grid 5 **25.643 M4**	Grid 6 **25.076 M4**
Grid 7 **35.871 M4**	Grid 8 **35.988 M4**	Grid 9 **34.479 M4**

Cursor:

Total = 38.483 V/m
E Category: M4
Location: -0.5, -38.5, 4.7 mm



0 dB = 38.480V/m

Date/Time: 2/28/2011 2:16:59 PM

Test Laboratory: RIM Testing Services

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Communication System Band: D1900 (1900.0 MHz); Frequency: 1880 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

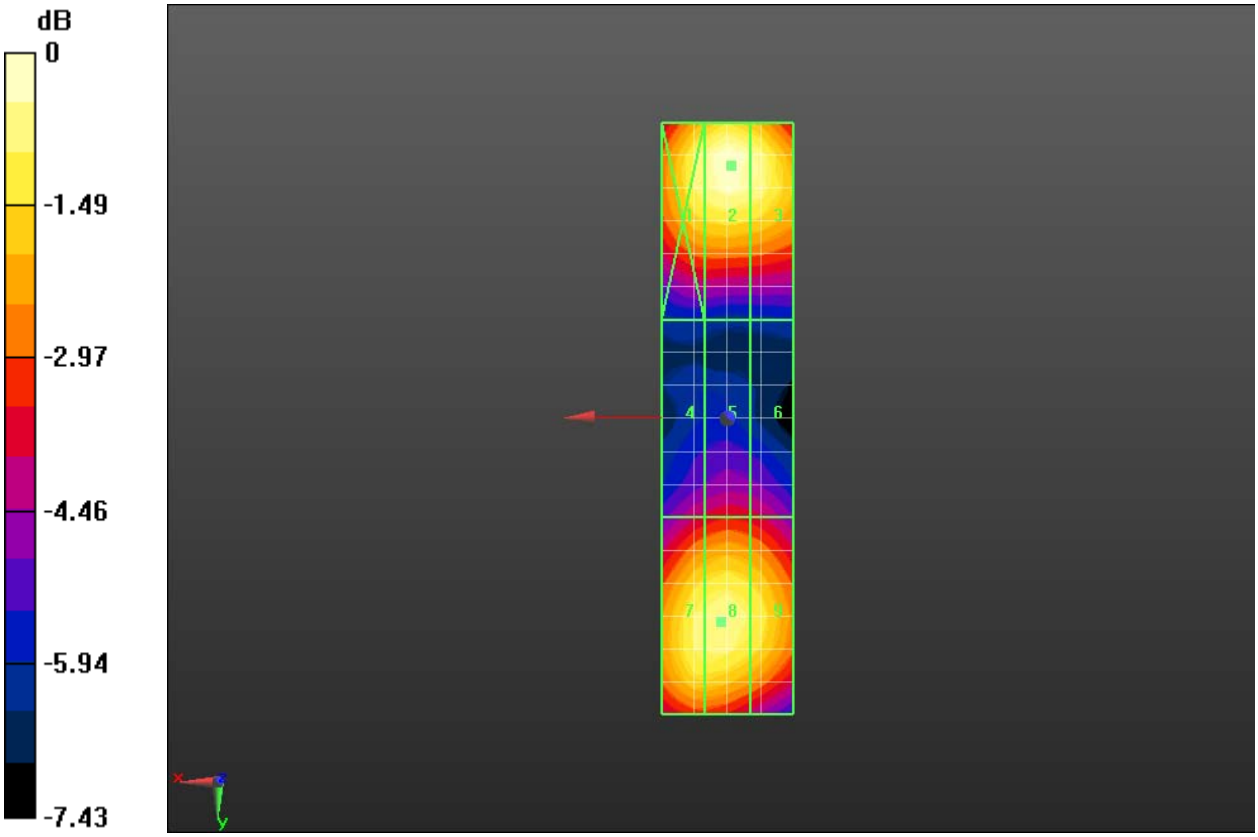
- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 43.024 V/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 38.861 V/m; Power Drift = 0.02 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **40.897 M4**	Grid 2 **43.024 M4**	Grid 3 **41.671 M4**
Grid 4 **27.919 M4**	Grid 5 **28.886 M4**	Grid 6 **28.274 M4**
Grid 7 **39.759 M4**	Grid 8 **40.082 M4**	Grid 9 **38.641 M4**

Cursor:
Total = 43.024 V/m
E Category: M4
Location: -0.5, -38.5, 4.7 mm



0 dB = 43.020V/m

Date/Time: 2/28/2011 2:21:55 PM

Test Laboratory: RIM Testing Services

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: AM 80%; Communication System Band: D1900 (1900.0 MHz);
Frequency: 1880 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

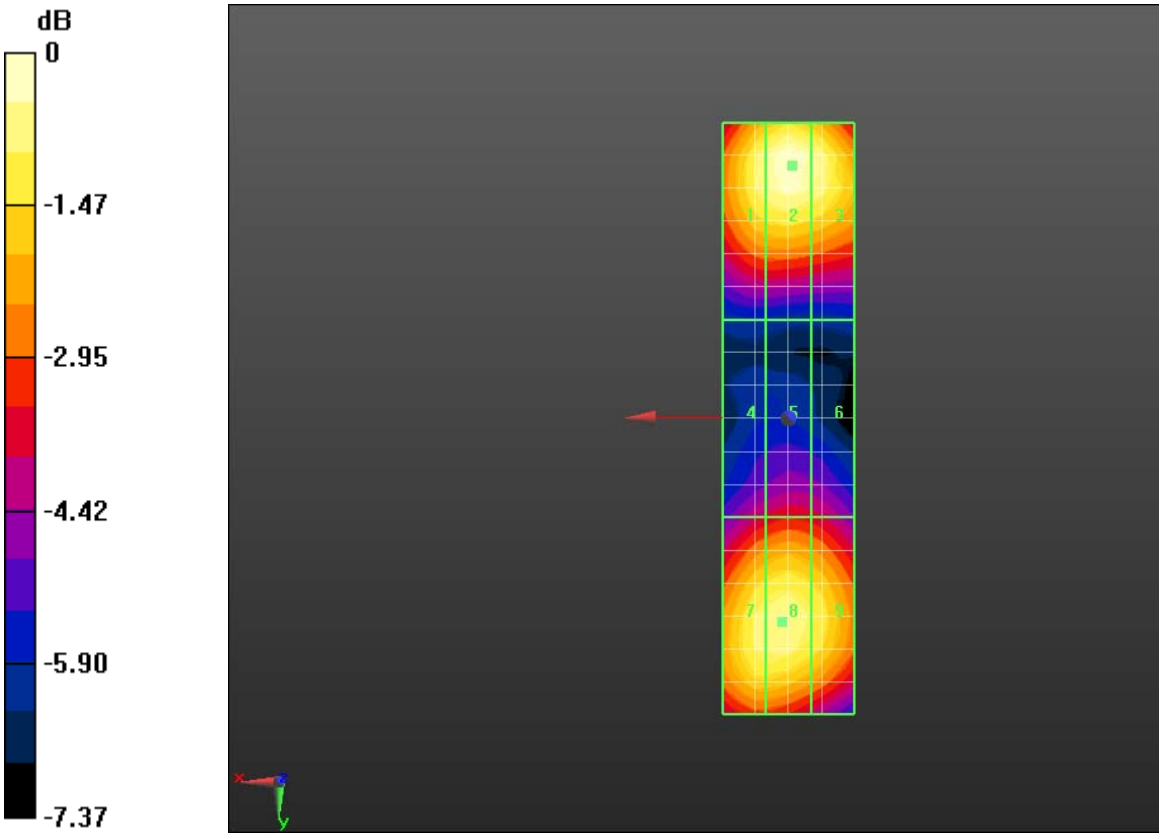
Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 27.543 V/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 25.024 V/m; Power Drift = -0.0069 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **26.151 M4**	Grid 2 **27.543 M4**	Grid 3 **26.639 M4**
Grid 4 **17.904 M4**	Grid 5 **18.574 M4**	Grid 6 **18.189 M4**
Grid 7 **25.506 M4**	Grid 8 **25.701 M4**	Grid 9 **24.770 M4**

Cursor:

Total = 27.543 V/m
E Category: M4
Location: -0.5, -38.5, 4.7 mm



0 dB = 27.540V/m

Date/Time: 6/21/2011 5:50:59 PM, Date/Time: 6/21/2011 6:15:20 PM, Date/Time: 6/21/2011 6:18:51 PM, Date/Time: 6/21/2011 6:28:10 PM

Test Laboratory: RIM Testing Services

HAC RF_E-Field_validation_PMF_1880 MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW, Communication System: CDMA 1900; Communication System Band: D1900 (1900.0 MHz), Communication System Band: CDMA 2000 PCS; Frequency: 1880 MHz;Communication System PAR: 0, Communication System PAR: 9.19 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 3/7/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

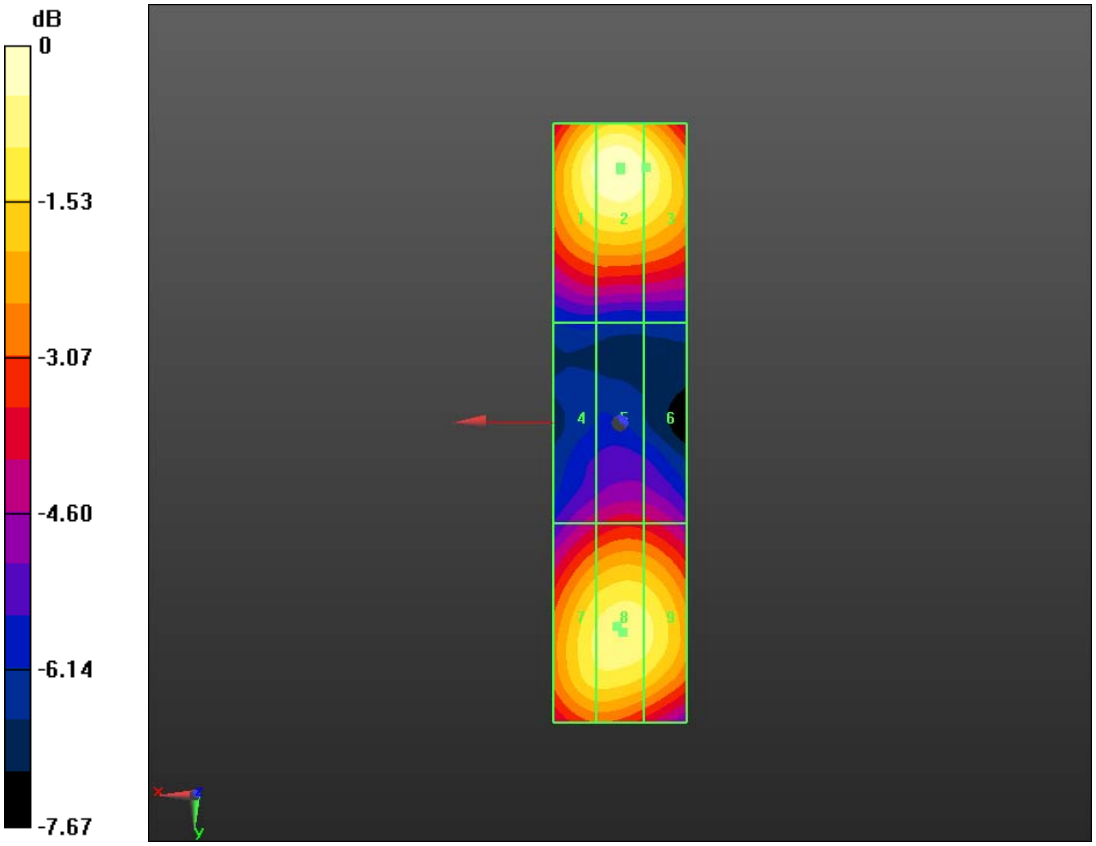
Dipole E-Field measurement/E Scan - 1880_validation_measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 133.7 V/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 122.4 V/m; Power Drift = 0.04 dB
Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **128.8 M2**	Grid 2 **133.7 M2**	Grid 3 **127.5 M2**
Grid 4 **82.667 M3**	Grid 5 **87.106 M3**	Grid 6 **86.101 M3**
Grid 7 **120.7 M2**	Grid 8 **123.8 M2**	Grid 9 **121.9 M2**

Cursor:

Total = 133.7 V/m
E Category: M2
Location: 0, -38, 4.7 mm



0 dB = 133.7V/m

Date/Time: 2/28/2011 3:32:16 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_PMF_UMTS_band V_835 MHz

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: WCDMA FDD V; ; Frequency: 835 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

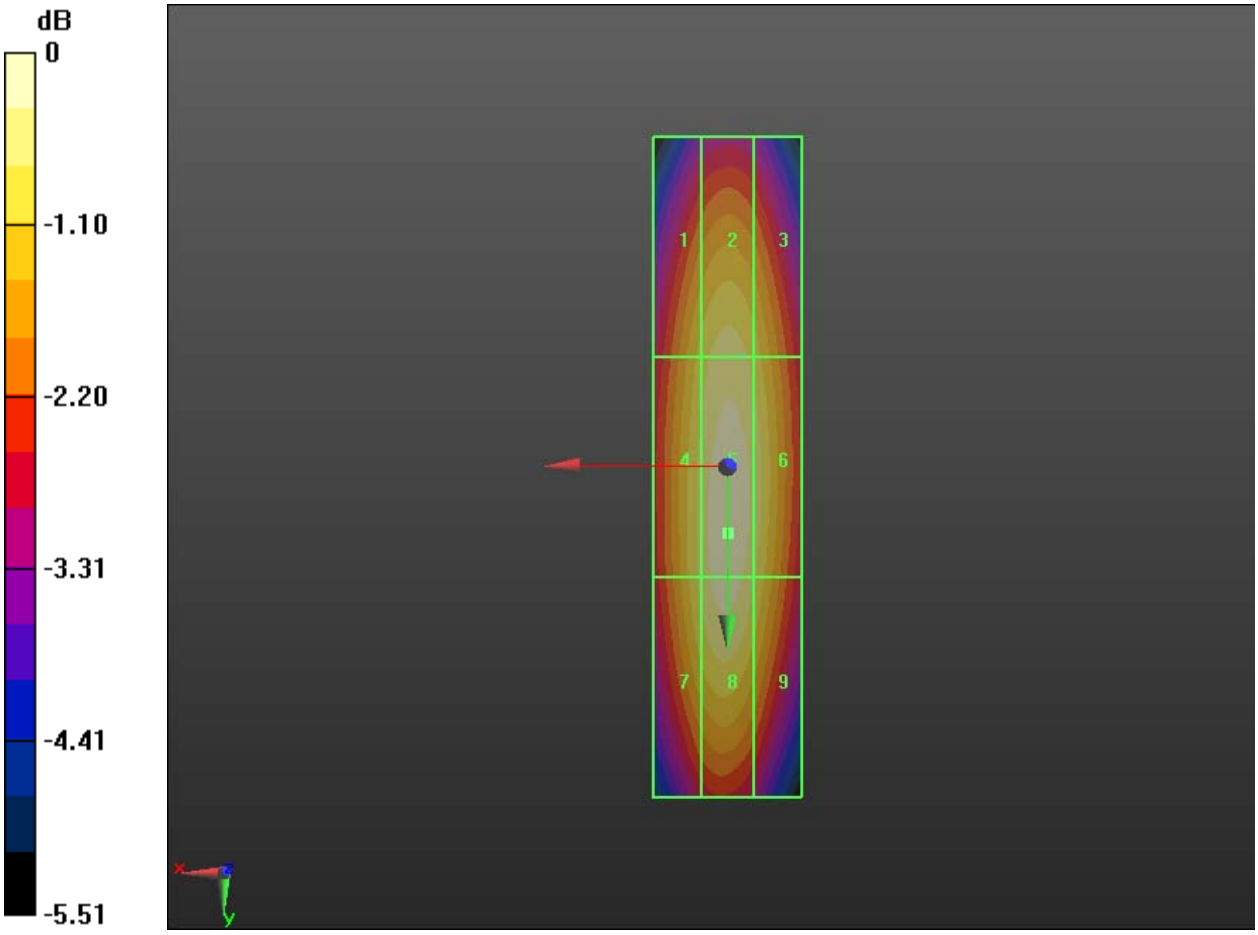
DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.168 A/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.178 A/m; Power Drift = 0.23 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.153 M4**	Grid 2 **0.160 M4**	Grid 3 **0.154 M4**
Grid 4 **0.160 M4**	Grid 5 **0.168 M4**	Grid 6 **0.161 M4**
Grid 7 **0.159 M4**	Grid 8 **0.166 M4**	Grid 9 **0.157 M4**



0 dB = 0.170A/m

Date/Time: 2/28/2011 3:41:08 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_PMF_CW835 MHz

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: CW; Communication System Band: D835 (835.0 MHz); Frequency: 835 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

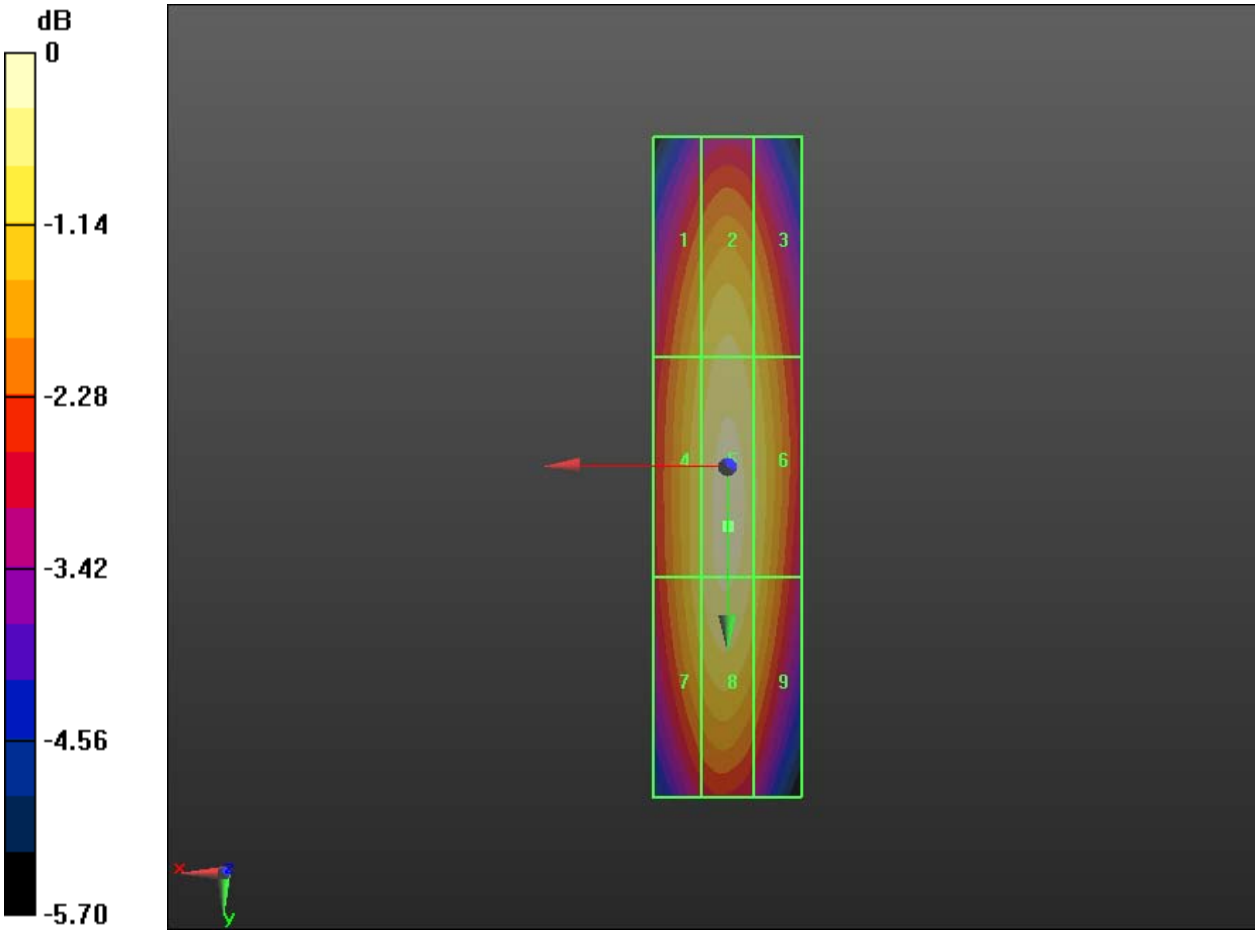
DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.166 A/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.177 A/m; Power Drift = -0.10 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.151 M4**	Grid 2 **0.158 M4**	Grid 3 **0.151 M4**
Grid 4 **0.157 M4**	Grid 5 **0.166 M4**	Grid 6 **0.159 M4**
Grid 7 **0.156 M4**	Grid 8 **0.164 M4**	Grid 9 **0.155 M4**



0 dB = 0.170A/m

Date/Time: 2/28/2011 3:45:30 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_PMF_AM80%835 MHz

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: AM 80%; Communication System Band: D835 (835.0 MHz);
Frequency: 835 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

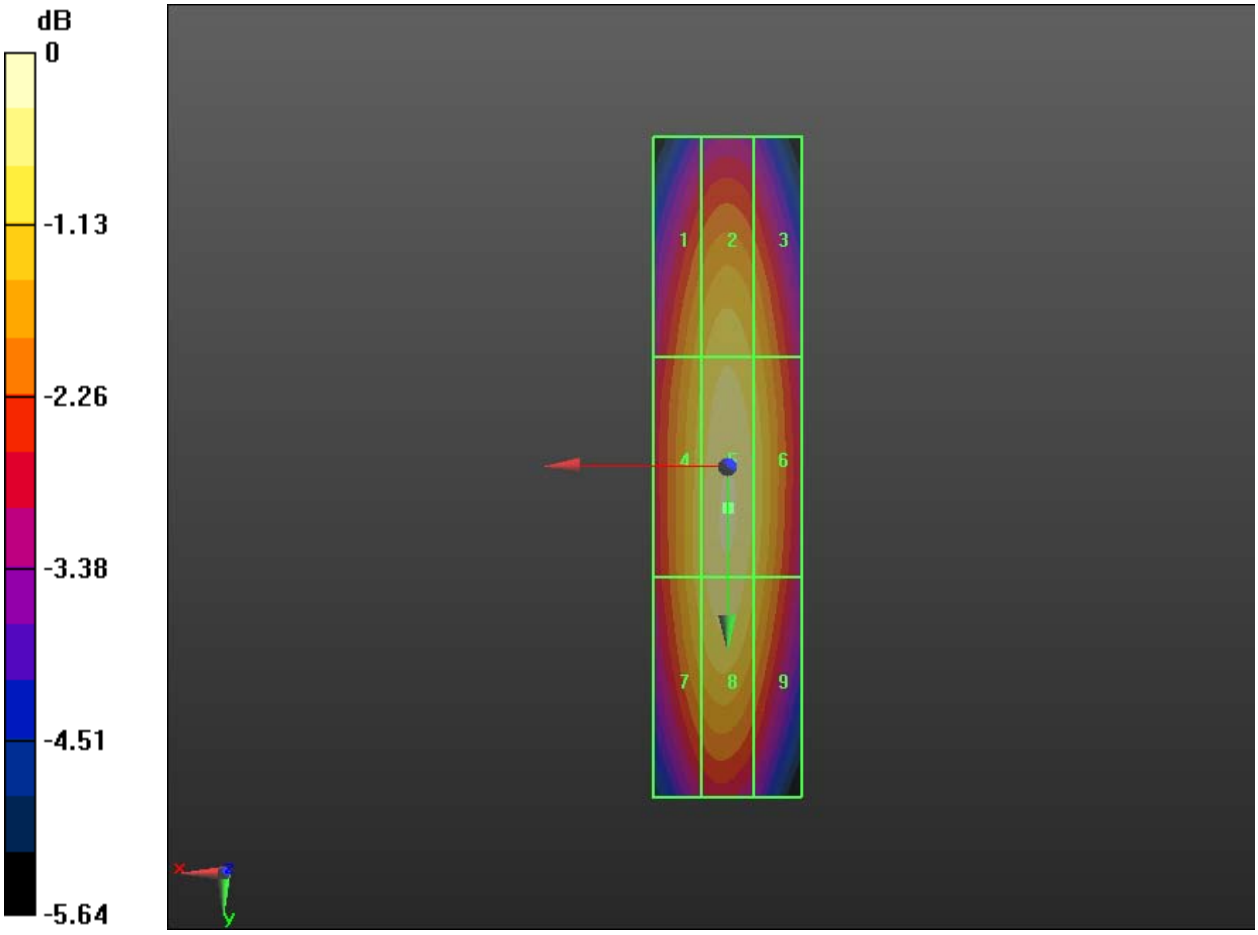
DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.106 A/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.113 A/m; Power Drift = 0.0097 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.096 M4**	Grid 2 **0.100 M4**	Grid 3 **0.096 M4**
Grid 4 **0.100 M4**	Grid 5 **0.106 M4**	Grid 6 **0.101 M4**
Grid 7 **0.100 M4**	Grid 8 **0.104 M4**	Grid 9 **0.098 M4**



0 dB = 0.110A/m

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Test Laboratory: RIM Testing Services

HAC RF_H-Field_validation_PMF_835 MHz

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: CW, Communication System: CDMA 800, Communication System: CDMA 850; Communication System Band: D835 (835.0 MHz), Communication System Band: CDMA 2000 BC 10 , Communication System Band: CDMA 2000 Cellular; Frequency: 835 MHz, Frequency: 820.5 MHz, Frequency: 836.52 MHz;Communication System PAR: 0, Communication System PAR: 9.19 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

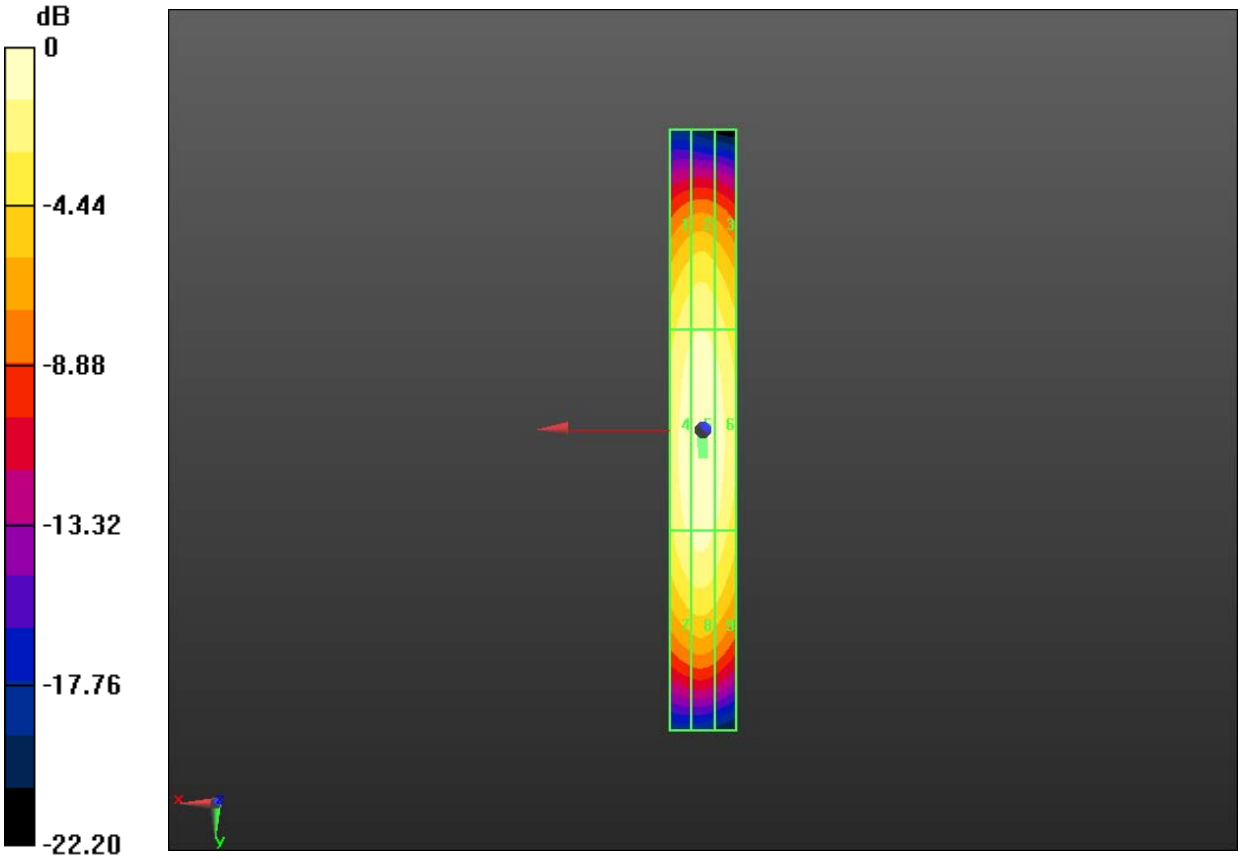
- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 3/7/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.479 A/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.509 A/m; Power Drift = -0.07 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.393 M4**	Grid 2 **0.406 M4**	Grid 3 **0.381 M4**
Grid 4 **0.459 M4**	Grid 5 **0.479 M4**	Grid 6 **0.450 M4**
Grid 7 **0.419 M4**	Grid 8 **0.435 M4**	Grid 9 **0.399 M4**

Cursor:
Total = 0.479 A/m
H Category: M4
Location: 0.5, 1.5, 4.7 mm



0 dB = 0.480A/m

Date/Time: 2/28/2011 2:57:08 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_PMF_UMTS_band II_1880 MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: WCDMA FDD II; ; Frequency: 1880 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

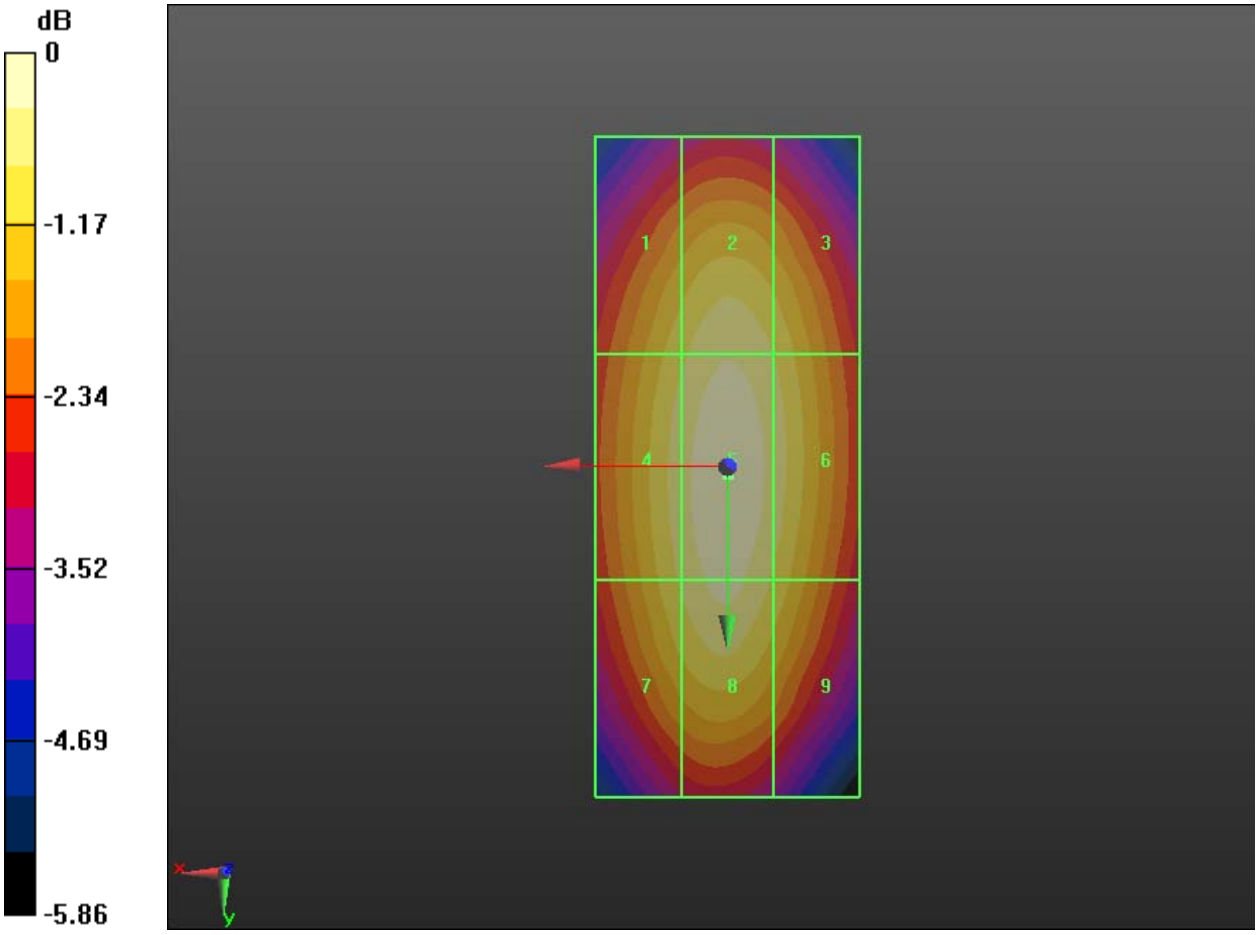
DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.138 A/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.147 A/m; Power Drift = 0.04 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.127 M4**	Grid 2 **0.134 M4**	Grid 3 **0.128 M4**
Grid 4 **0.132 M4**	Grid 5 **0.138 M4**	Grid 6 **0.132 M4**
Grid 7 **0.129 M4**	Grid 8 **0.136 M4**	Grid 9 **0.127 M4**



0 dB = 0.140A/m

Date/Time: 2/28/2011 2:40:44 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_PMF_CW1880 MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Communication System Band: D1900 (1900.0 MHz); Frequency: 1880 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: TCoil Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

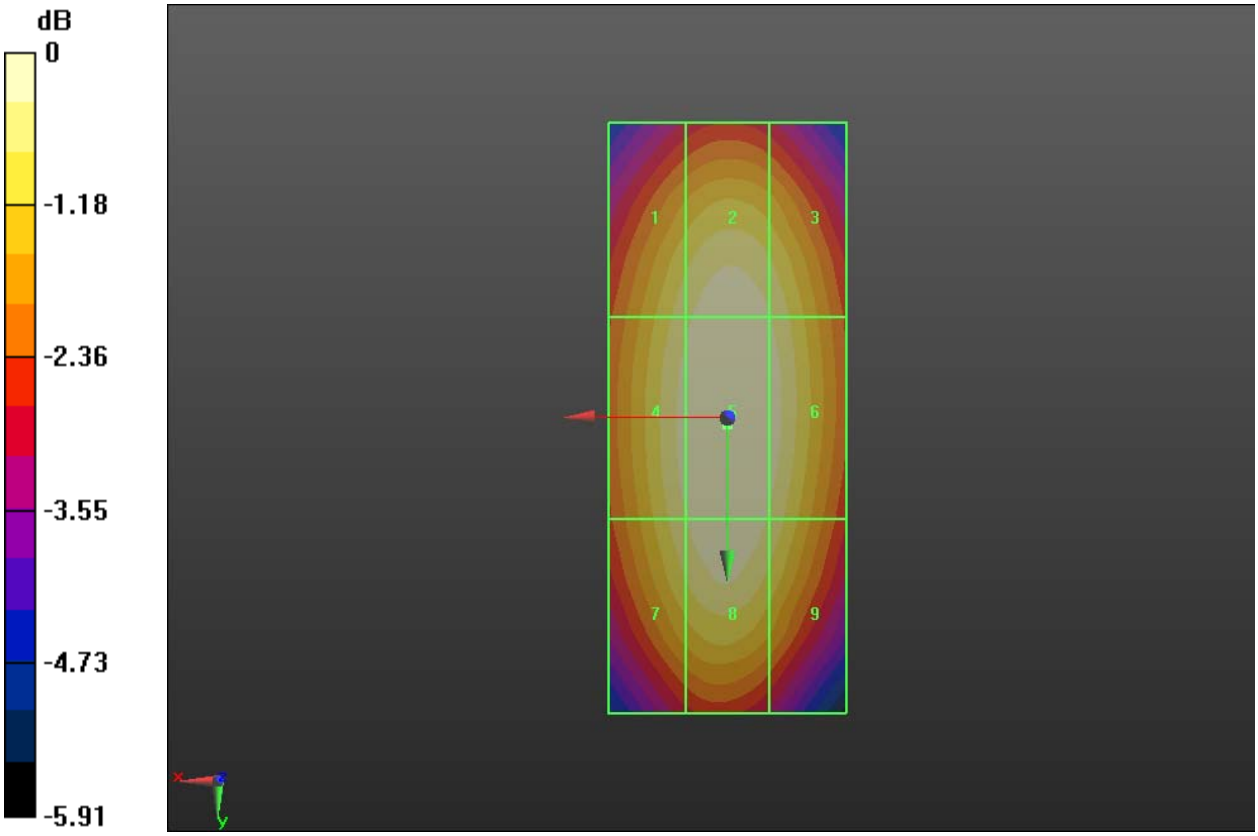
DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.155 A/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.163 A/m; Power Drift = 0.06 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.142 M4**	Grid 2 **0.149 M4**	Grid 3 **0.144 M4**
Grid 4 **0.147 M4**	Grid 5 **0.155 M4**	Grid 6 **0.148 M4**
Grid 7 **0.143 M4**	Grid 8 **0.151 M4**	Grid 9 **0.143 M4**



0 dB = 0.150A/m

Date/Time: 2/28/2011 2:44:44 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_PMF_AM80%1880 MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: AM 80%; Communication System Band: D1900 (1900.0 MHz);
Frequency: 1880 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: TCoil Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

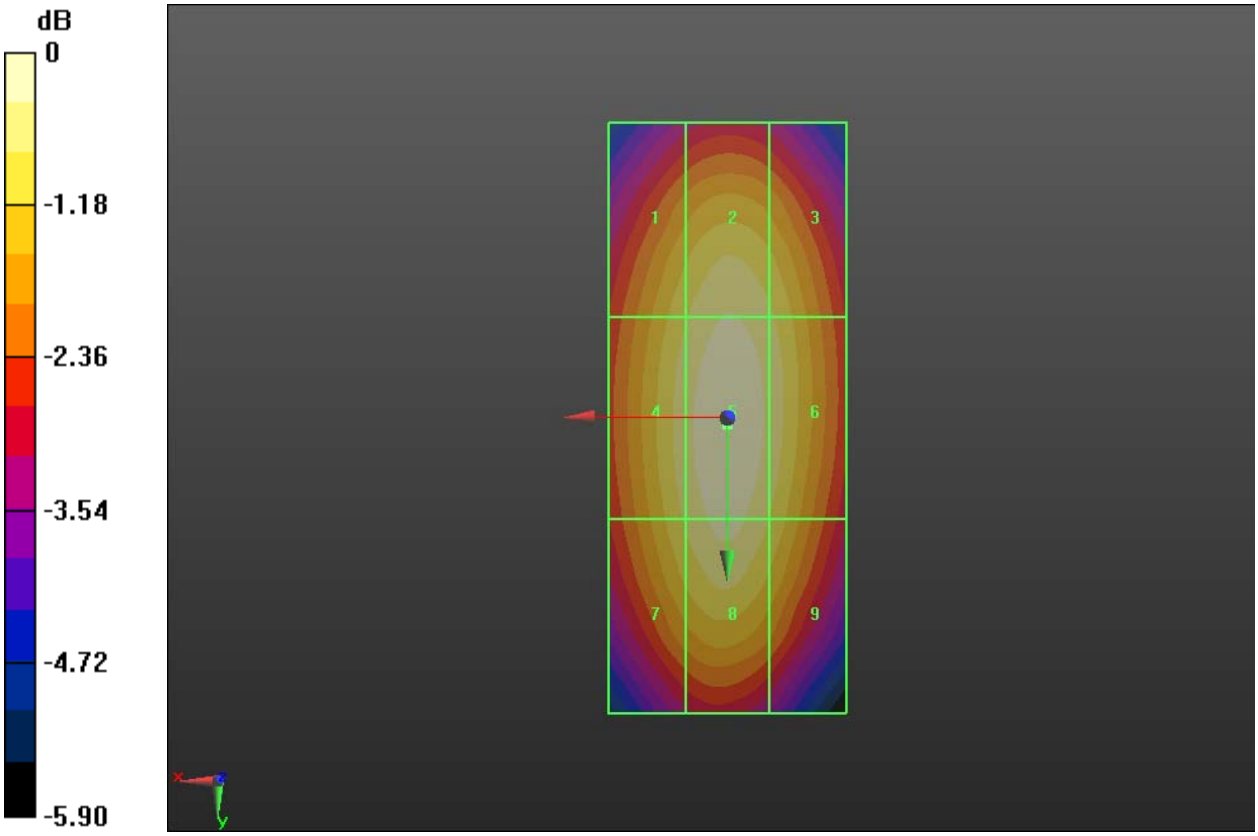
DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.099 A/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.106 A/m; Power Drift = 0.0091 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.091 M4**	Grid 2 **0.096 M4**	Grid 3 **0.092 M4**
Grid 4 **0.094 M4**	Grid 5 **0.099 M4**	Grid 6 **0.095 M4**
Grid 7 **0.092 M4**	Grid 8 **0.097 M4**	Grid 9 **0.091 M4**



0 dB = 0.100A/m

Date/Time: 6/21/2011 7:14:02 PM, Date/Time: 6/21/2011 7:19:36 PM, Date/Time: 6/21/2011 7:30:34 PM, Date/Time: 6/21/2011 7:37:59 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_validation_PMF_1880 MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Communication System Band: D1900 (1900.0 MHz); Frequency: 1880 MHz;Communication System PAR: 0, Communication System PAR: 9.19 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

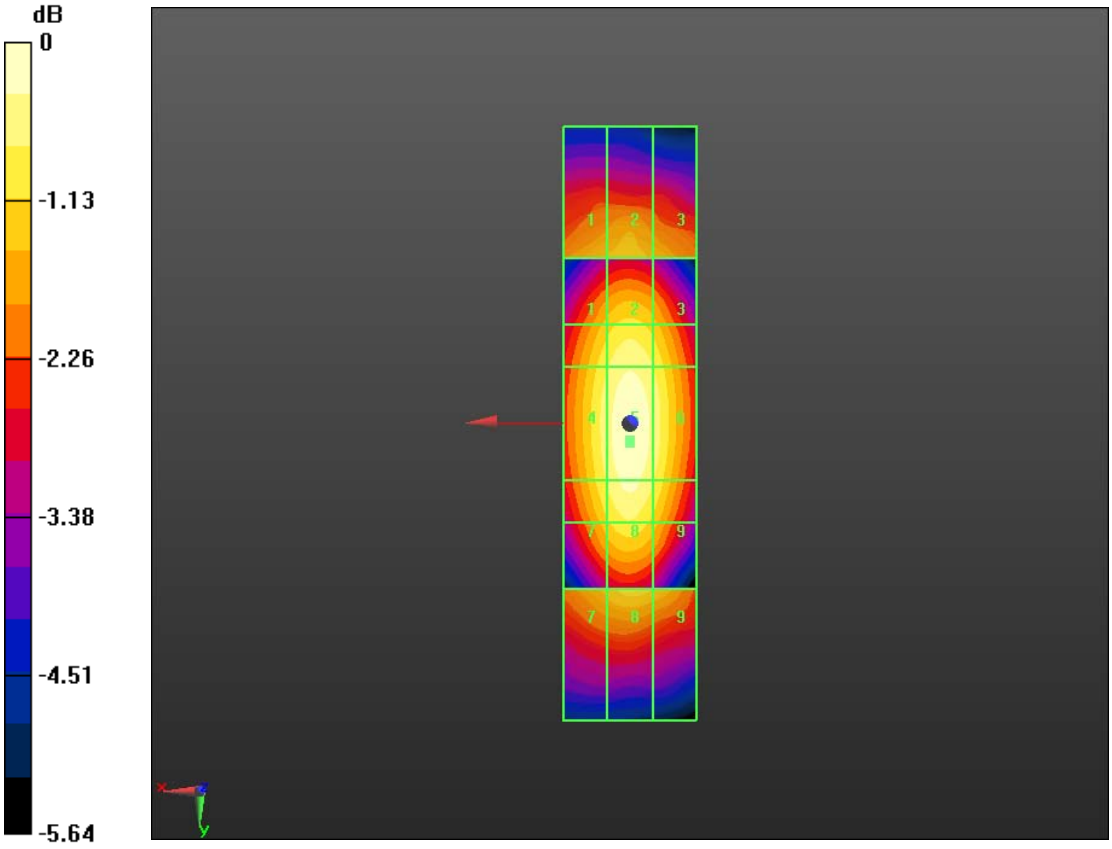
- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 3/7/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole H-Field measurement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.466 A/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.494 A/m; Power Drift = -0.06 dB
Hearing Aid Near-Field Category: M2 (AWF 0 dB)

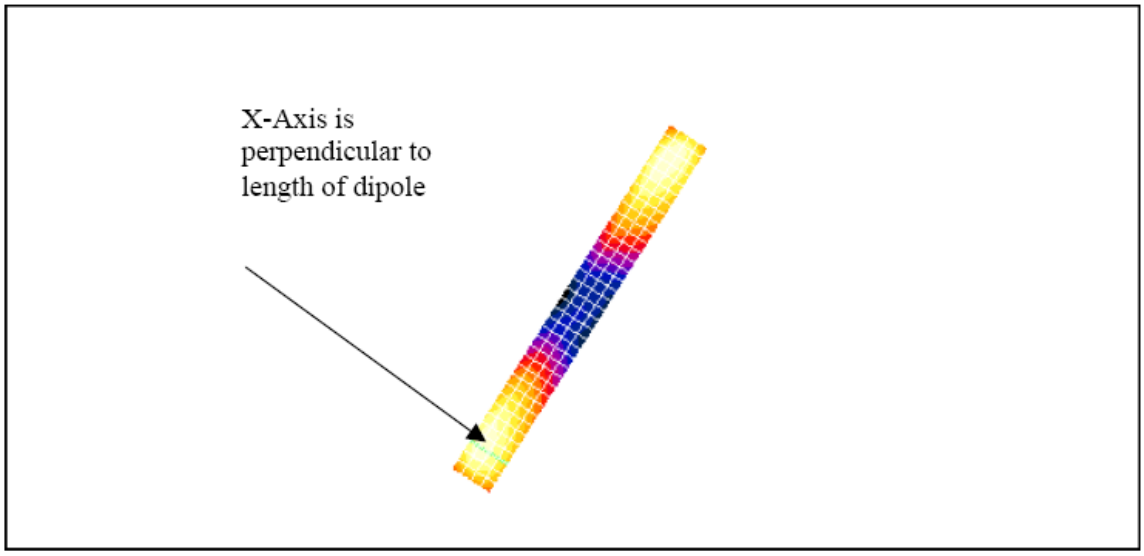
Peak H-field in A/m

Grid 1 **0.429 M2**	Grid 2 **0.449 M2**	Grid 3 **0.431 M2**
Grid 4 **0.443 M2**	Grid 5 **0.466 M2**	Grid 6 **0.445 M2**
Grid 7 **0.434 M2**	Grid 8 **0.457 M2**	Grid 9 **0.433 M2**

Cursor:
Total = 0.466 A/m
H Category: M2
Location: 0, 0.5, 4.7 mm



0 dB = 0.470A/m



The green line in this figure shows the axis along which the points lie.

Comparison of 5mm and 2mm step sizes

An additional set of measurements was taken: dipole validations were performed using 5mm and 2mm step sizes. The delta between the two readings is insignificant for both field types (< 0.4% for E and 0% for H), demonstrating that 5mm is sufficient. The plots follow.

Date/Time: 14/07/2005 11:35:24 AM

Lab: RIM Testing Services (RTS)

Dipole Validation 1880 MHz_E-Field 07_14_05

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz;Duty Cycle: 1:1
Medium: Air Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m^3
Phantom section: H Device Section

DASY4 Configuration:
- Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 10/12/2004
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 03/01/2005
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

E Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (5x19x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of Total (measured) = 134.8 V/m

E Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (41x181x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of Total field (slot averaged) = 131.0 V/m
Hearing Aid Near-Field Category: M2 (AWF 0 dB)

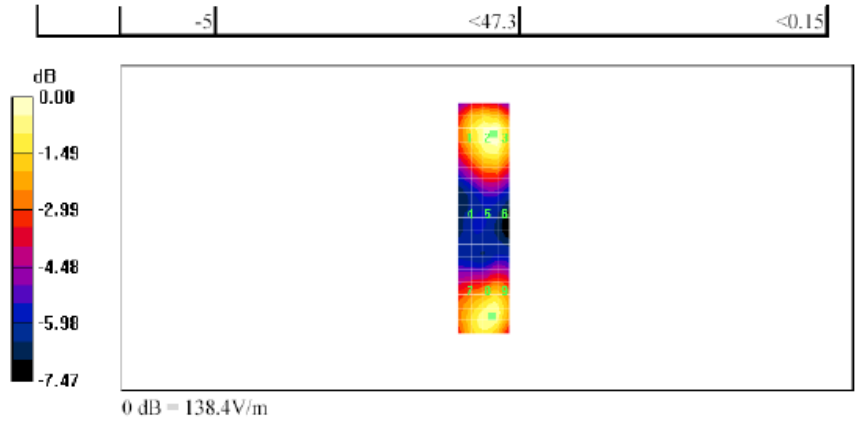
E in V/m (Time averaged)

Grid 1	Grid 2	Grid 3
123.2	**138.1**	**138.4**
Grid 4	Grid 5	Grid 6
80.9	**92.3**	**92.2**
Grid 7	Grid 8	Grid 9
119.8	**131.0**	**130.7**

E in V/m (Slot averaged)

Grid 1	Grid 2	Grid 3
123.2	**138.1**	**138.4**
Grid 4	Grid 5	Grid 6
80.9	**92.3**	**92.2**
Grid 7	Grid 8	Grid 9
119.8	**131.0**	**130.7**

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19



Date/Time: 14/07/2005 11:44:51 AM

Lab: RIM Testing Services (RTS)

Dipole Validation 1880 MHz_2mm step_E-Field 07_14_05

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz;Duty Cycle: 1:1
Medium: Air Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m^3
Phantom section: H Device Section

DASY4 Configuration:
- Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 10/12/2004
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 03/01/2005
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

E Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (11x46x1):
Measurement grid: dx=2mm, dy=2mm
Maximum value of Total (measured) = 138.0 V/m

E Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (101x451x1):
Measurement grid: dx=2mm, dy=2mm
Maximum value of Total field (slot averaged) = 131.2 V/m
Hearing Aid Near-Field Category: M2 (AWF 0 dB)

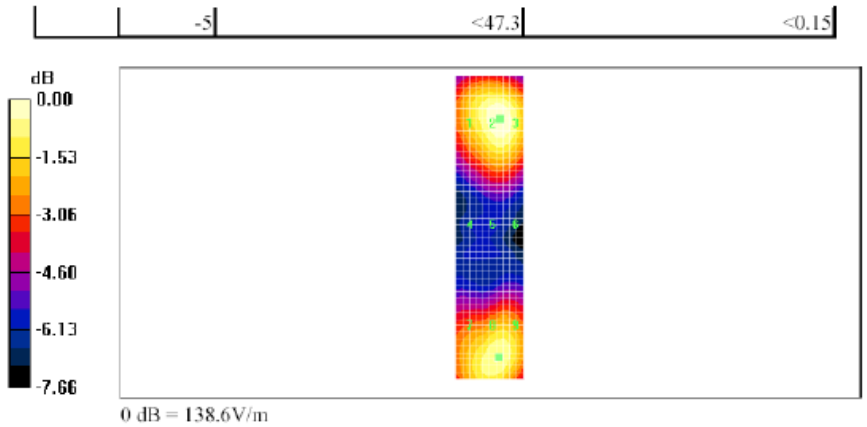
E in V/m (Time averaged)

Grid 1 **123.1**	Grid 2 **138.6**	Grid 3 **138.6**
Grid 4 **81.4**	Grid 5 **92.1**	Grid 6 **91.6**
Grid 7 **121.3**	Grid 8 **131.2**	Grid 9 **131.0**

E in V/m (Slot averaged)

Grid 1 **123.1**	Grid 2 **138.6**	Grid 3 **138.6**
Grid 4 **81.4**	Grid 5 **92.1**	Grid 6 **91.6**
Grid 7 **121.3**	Grid 8 **131.2**	Grid 9 **131.0**

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19



Date/Time: 14/07/2005 12:43:02 PM

Lab: RIM Testing Services (RTS)

HAC_H_Dipole_CW 1880_5 mm step_07_14_05

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz;Duty Cycle: 1:1
Medium: Air Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m^3
Phantom section: H Dipole Section

DASY4 Configuration:
- Probe: H3DV6 - SN6105; ; Calibrated: 10/12/2004
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 03/01/2005
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

H Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (5x19x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of Total (measured) = 0.406 A/m

H Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (41x181x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of Total field (slot averaged) = 0.406 A/m
Hearing Aid Near-Field Category: M2 (AWF 0 dB)

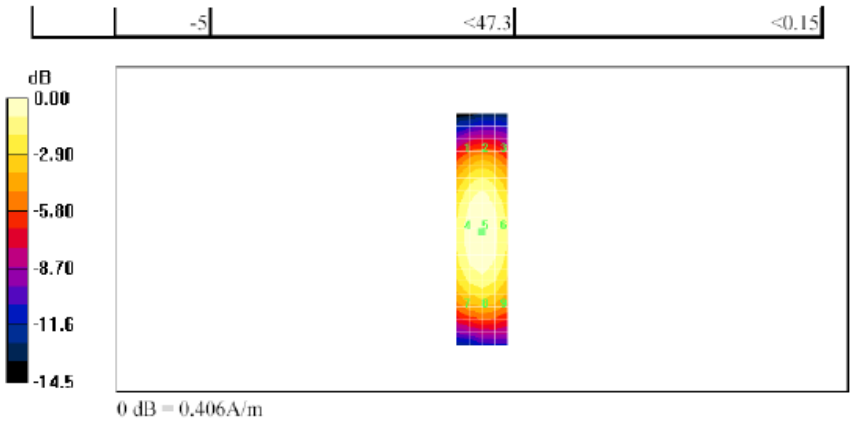
H in A/m (Time averaged)

Grid 1 **0.342**	Grid 2 **0.359**	Grid 3 **0.344**
Grid 4 **0.389**	Grid 5 **0.406**	Grid 6 **0.389**
Grid 7 **0.363**	Grid 8 **0.378**	Grid 9 **0.363**

H in A/m (Slot averaged)

Grid 1 **0.342**	Grid 2 **0.359**	Grid 3 **0.344**
Grid 4 **0.389**	Grid 5 **0.406**	Grid 6 **0.389**
Grid 7 **0.363**	Grid 8 **0.378**	Grid 9 **0.363**

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19



Date/Time: 14/07/2005 12:53:40 PM

Lab: RIM Testing Services (RTS)

HAC_H_Dipole_CW 1880_2 mm step_07_14_05

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz;Duty Cycle: 1:1
Medium: Air Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m^3
Phantom section: H Dipole Section

DASY4 Configuration:
- Probe: H3DV6 - SN6105; ; Calibrated: 10/12/2004
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 03/01/2005
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

H Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (11x46x1):
Measurement grid: dx=2mm, dy=2mm
Maximum value of Total (measured) = 0.406 A/m

H Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (101x451x1):
Measurement grid: dx=2mm, dy=2mm
Maximum value of Total field (slot averaged) = 0.406 A/m
Hearing Aid Near-Field Category: M2 (AWF 0 dB)

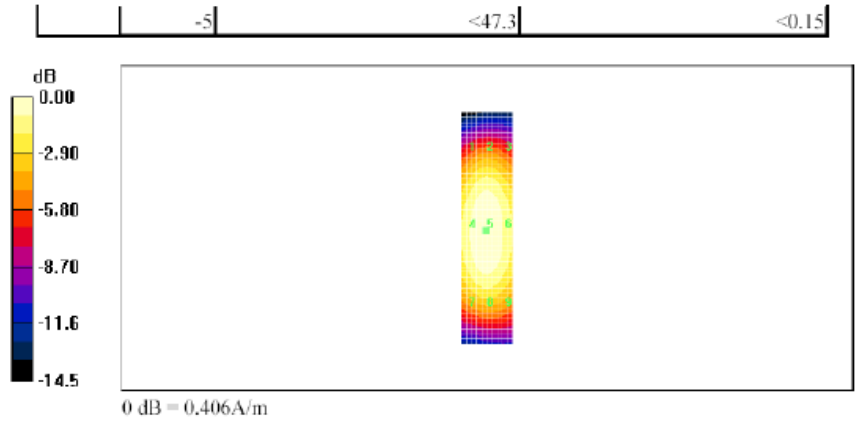
H in A/m (Time averaged)

Grid 1	Grid 2	Grid 3
0.347	**0.361**	**0.348**
Grid 4	Grid 5	Grid 6
0.394	**0.406**	**0.391**
Grid 7	Grid 8	Grid 9
0.367	**0.380**	**0.365**

H in A/m (Slot averaged)

Grid 1	Grid 2	Grid 3
0.347	**0.361**	**0.348**
Grid 4	Grid 5	Grid 6
0.394	**0.406**	**0.391**
Grid 7	Grid 8	Grid 9
0.367	**0.380**	**0.365**

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19



0 dB = 0.406A/m

A.3 RF emission field plots

Date/Time: 5/13/2011 11:25:05 AM, Date/Time: 5/13/2011 11:30:45 AM, Date/Time: 5/13/2011 11:34:35 AM

Test Laboratory: RIM Testing Services

HAC RF_E-Field_GSM850_

DUT: BlackBerry Smartphone; Type: Sample

Communication System: GSM 850; Frequency: 824.2 MHz, Frequency: 836.8 MHz, Frequency: 848.8 MHz;Communication System PAR: 9.191 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 200.4 V/m
Probe Modulation Factor = 2.940
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 84.085 V/m; Power Drift = 0.14 dB
Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **171.8 M3**	Grid 2 **193.9 M3**	Grid 3 **191.2 M3**
Grid 4 **178.1 M3**	Grid 5 **200.4 M3**	Grid 6 **198.1 M3**
Grid 7 **181.5 M3**	Grid 8 **200.2 M3**	Grid 9 **197.5 M3**

Cursor:

Total = 200.4 V/m
E Category: M3
Location: -4.5, 5, 8.7 mm

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 240.2 V/m
Probe Modulation Factor = 2.940
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 98.602 V/m; Power Drift = 0.13 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **192.1 M3**	Grid 2 **225.3 M3**	Grid 3 **224.7 M3**
Grid 4 **205.2 M3**	Grid 5 **240.2 M3**	Grid 6 **239.0 M3**
Grid 7 **214.5 M3**	Grid 8 **240.5 M3**	Grid 9 **239.0 M3**

Cursor:

Total = 240.5 V/m
E Category: M3
Location: -5.5, 12, 8.7 mm

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 264.7 V/m
Probe Modulation Factor = 2.940
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 108.7 V/m; Power Drift = 0.05 dB

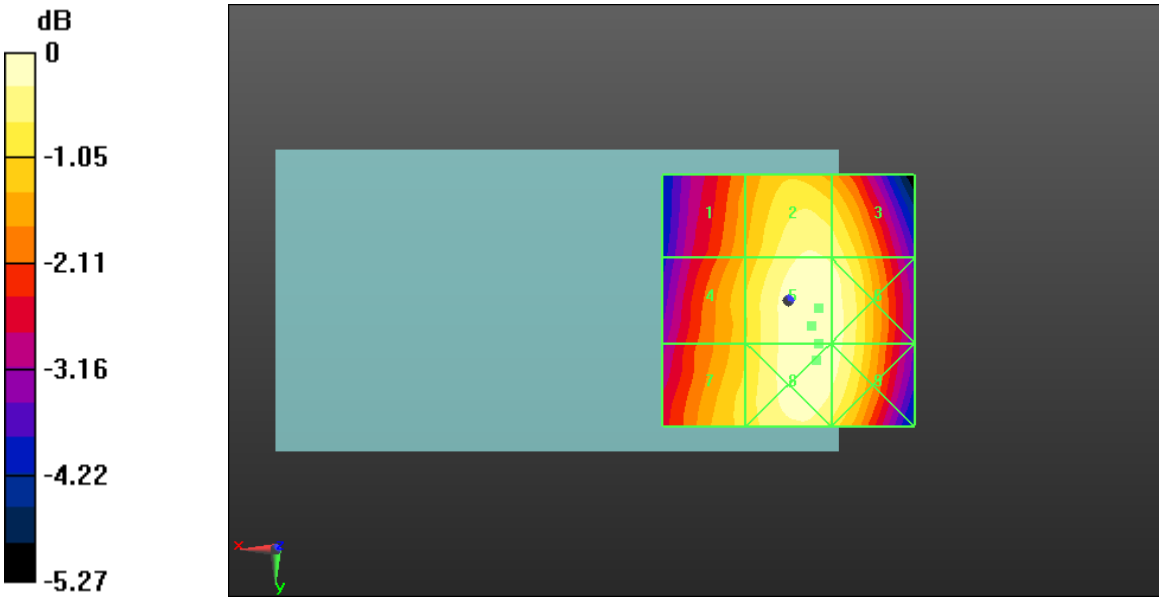
Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **214.6 M3**	Grid 2 **257.2 M3**	Grid 3 **256.8 M3**
Grid 4 **222.1 M3**	Grid 5 **264.7 M3**	Grid 6 **263.7 M3**
Grid 7 **225.9 M3**	Grid 8 **263.8 M3**	Grid 9 **261.3 M3**

Cursor:

Total = 264.7 V/m
E Category: M3
Location: -6, 1.5, 8.7 mm



0 dB = 200.4V/m

Date/Time: 5/16/2011 3:56:57 PM

Test Laboratory: RIM Testing Services

HAC RF_E-Field_GSM850_telecoil

DUT: BlackBerry Smartphone; Type: Sample

Communication System: GSM 850; Frequency: 848.8 MHz;Communication System PAR: 9.191 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device_telecoil/Hearing Aid Compatibility Test (101x101x1):

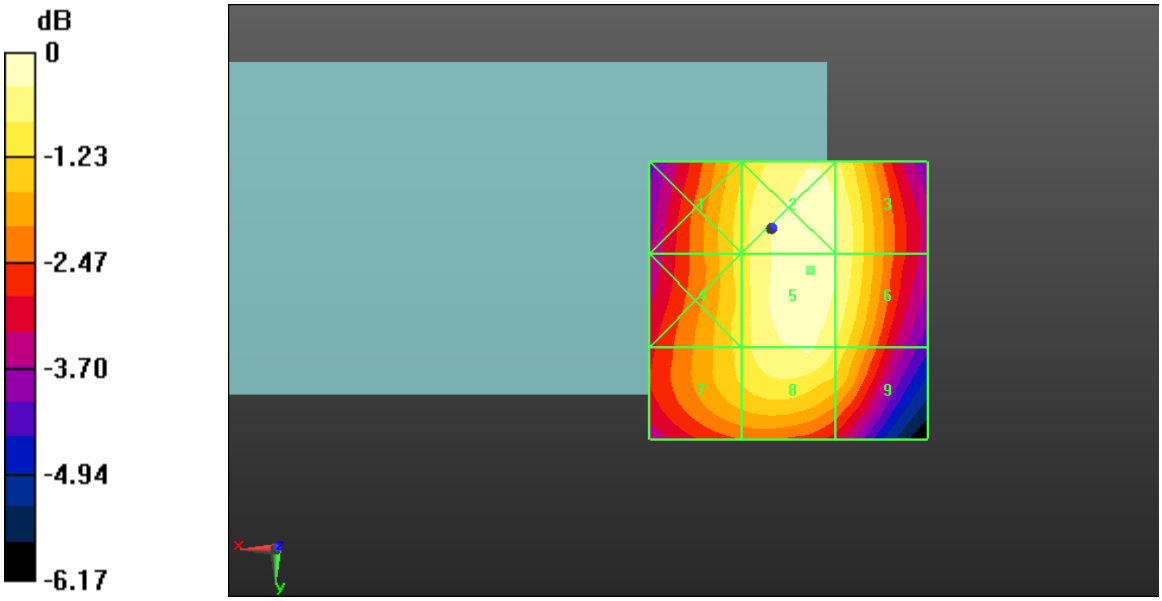
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 263.7 V/m
Probe Modulation Factor = 2.940
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 111.7 V/m; Power Drift = 0.06 dB
Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **234.8 M3**	Grid 2 **263.1 M3**	Grid 3 **254.2 M3**
Grid 4 **234.7 M3**	Grid 5 **263.7 M3**	Grid 6 **253.9 M3**
Grid 7 **233.7 M3**	Grid 8 **253.0 M3**	Grid 9 **238.3 M3**

Cursor:

Total = 263.7 V/m
E Category: M3
Location: -7, 7.5, 8.7 mm



0 dB = 263.7V/m

Date/Time: 5/13/2011 10:48:47 AM, Date/Time: 5/13/2011 11:09:01 AM, Date/Time: 5/13/2011 11:12:49 AM

Test Laboratory: RIM Testing Services

HAC RF_E-Field_GSM1900

DUT: BlackBerry Smartphone; Type: Sample

Communication System: GSM 1900; Frequency: 1850.2 MHz, Frequency: 1880 MHz, Frequency: 1909.8 MHz;Communication System PAR: 9.191 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 76.013 V/m
Probe Modulation Factor = 2.970
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 11.989 V/m; Power Drift = -0.0094 dB
Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **95.691 M2**	Grid 2 **102.1 M2**	Grid 3 **95.399 M2**
Grid 4 **44.352 M4**	Grid 5 **55.177 M3**	Grid 6 **55.472 M3**
Grid 7 **72.284 M3**	Grid 8 **76.013 M3**	Grid 9 **72.070 M3**

Cursor:

Total = 102.1 V/m
E Category: M2
Location: -2.5, -25, 8.7 mm

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 63.432 V/m
Probe Modulation Factor = 2.970
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 11.294 V/m; Power Drift = 0.15 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **77.124 M3**	Grid 2 **85.587 M2**	Grid 3 **82.924 M3**
Grid 4 **36.958 M4**	Grid 5 **53.580 M3**	Grid 6 **54.682 M3**
Grid 7 **58.237 M3**	Grid 8 **63.432 M3**	Grid 9 **62.234 M3**

Cursor:

Total = 85.587 V/m
E Category: M2
Location: -2.5, -25, 8.7 mm

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 52.785 V/m
Probe Modulation Factor = 2.970
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 10.720 V/m; Power Drift = -0.15 dB

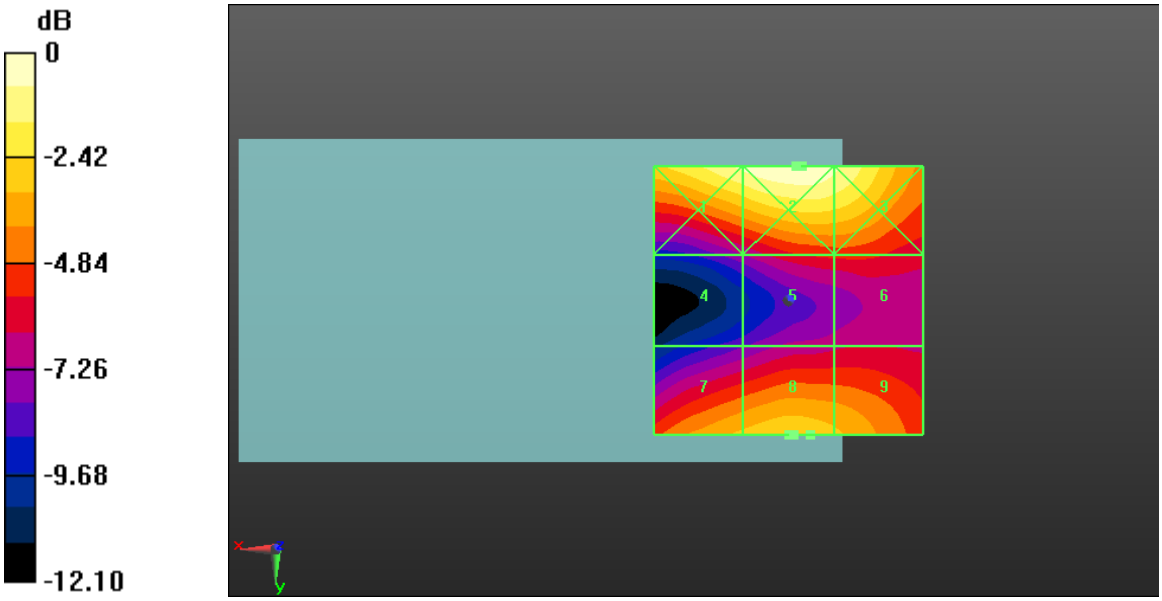
Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **73.517 M3**	Grid 2 **80.987 M3**	Grid 3 **77.626 M3**
Grid 4 **35.817 M4**	Grid 5 **50.087 M3**	Grid 6 **50.320 M3**
Grid 7 **50.905 M3**	Grid 8 **52.785 M3**	Grid 9 **50.778 M3**

Cursor:

Total = 80.987 V/m
E Category: M3
Location: -1.5, -25, 8.7 mm



0 dB = 102.1V/m

Date/Time: 5/16/2011 4:03:31 PM

Test Laboratory: RIM Testing Services

HAC RF_E-Field_GSM1900_telecoil

DUT: BlackBerry Smartphone; Type: Sample

Communication System: GSM 1900; Frequency: 1850.2 MHz;Communication System PAR: 9.191 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

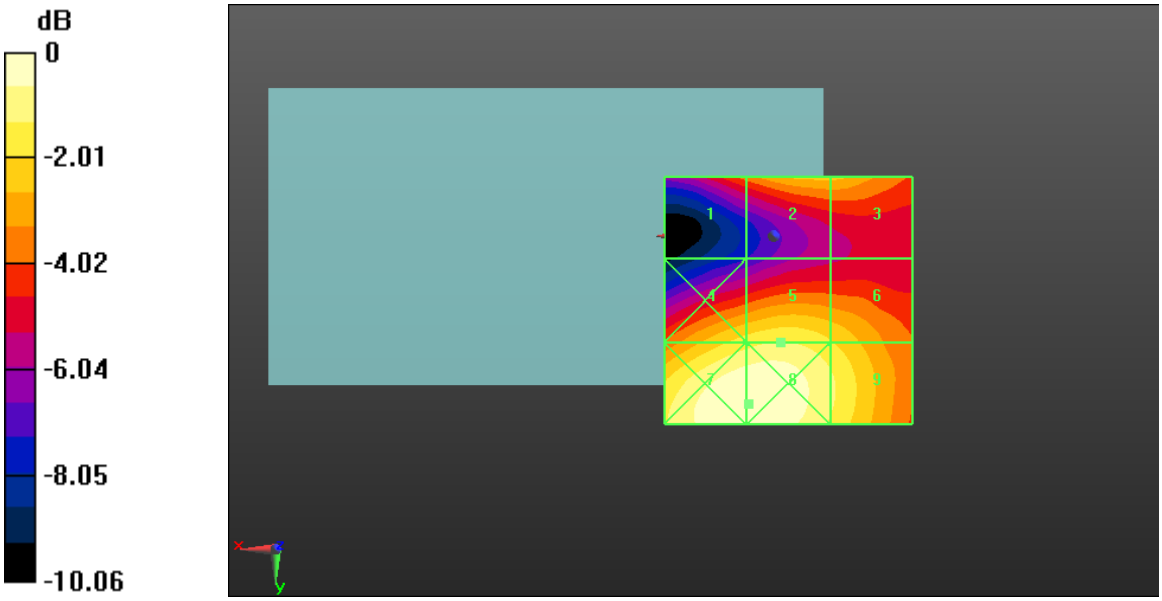
DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Telecoil/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 72.085 V/m
Probe Modulation Factor = 2.970
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 11.633 V/m; Power Drift = -0.19 dB
Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **54.928 M3**	Grid 2 **62.886 M3**	Grid 3 **62.830 M3**
Grid 4 **68.560 M3**	Grid 5 **71.121 M3**	Grid 6 **66.227 M3**
Grid 7 **82.764 M3**	Grid 8 **82.769 M3**	Grid 9 **72.085 M3**



0 dB = 82.770V/m

Date/Time: 5/13/2011 11:49:16 AM, Date/Time: 5/13/2011 11:54:23 AM, Date/Time: 5/13/2011 11:58:48 AM

Test Laboratory: RIM Testing Services

HAC RF_E-Field_UMTS_band_IV

DUT: BlackBerry Smartphone; Type: Sample

Communication System: WCDMA FDD IV; Frequency: 1712.4 MHz, Frequency: 1732.6 MHz, Frequency: 1752.6 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 31.404 V/m
Probe Modulation Factor = 0.970
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 20.396 V/m; Power Drift = 0.08 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **31.404 M4**	Grid 2 **31.002 M4**	Grid 3 **25.492 M4**
Grid 4 **20.346 M4**	Grid 5 **27.500 M4**	Grid 6 **27.494 M4**
Grid 7 **33.511 M4**	Grid 8 **38.136 M4**	Grid 9 **36.990 M4**

Cursor:

Total = 38.136 V/m
E Category: M4
Location: -3, 25, 8.7 mm

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 31.332 V/m
Probe Modulation Factor = 0.970
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 16.382 V/m; Power Drift = -0.13 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **31.233 M4**	Grid 2 **31.332 M4**	Grid 3 **26.491 M4**
Grid 4 **18.202 M4**	Grid 5 **23.887 M4**	Grid 6 **23.823 M4**
Grid 7 **32.161 M4**	Grid 8 **36.253 M4**	Grid 9 **35.041 M4**

Cursor:

Total = 36.253 V/m
E Category: M4
Location: -3.5, 25, 8.7 mm

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 28.977 V/m
Probe Modulation Factor = 0.970
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 12.012 V/m; Power Drift = 0.04 dB

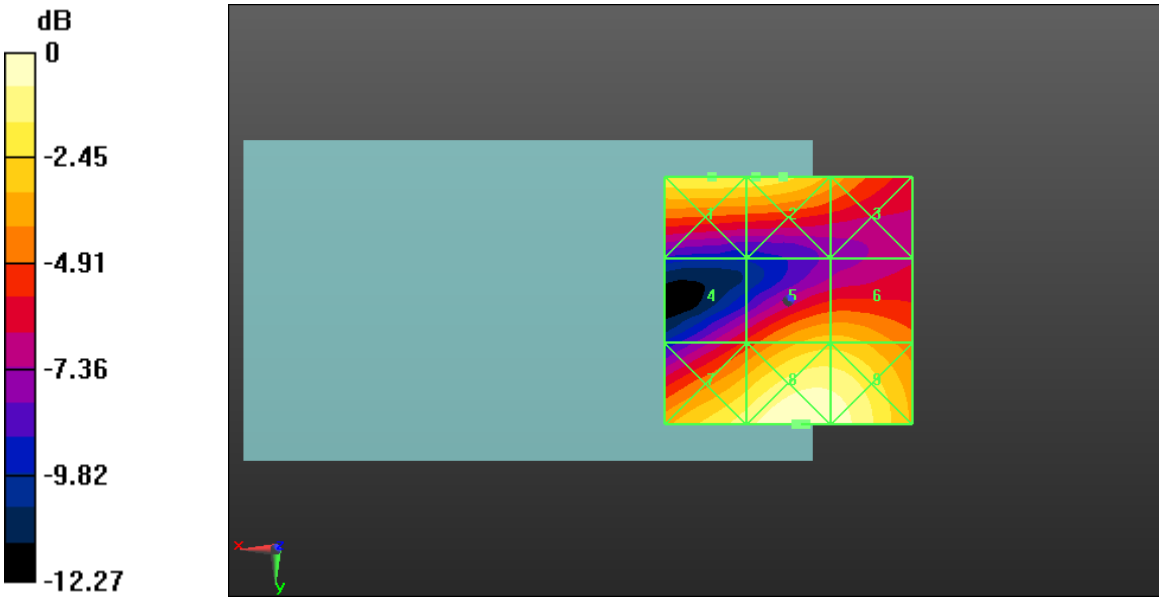
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **28.075 M4**	Grid 2 **29.012 M4**	Grid 3 **26.661 M4**
Grid 4 **14.167 M4**	Grid 5 **17.590 M4**	Grid 6 **17.487 M4**
Grid 7 **26.682 M4**	Grid 8 **28.977 M4**	Grid 9 **27.772 M4**

Cursor:

Total = 29.012 V/m
E Category: M4
Location: 1, -25, 8.7 mm



0 dB = 38.140V/m

Date/Time: 5/16/2011 3:47:10 PM

Test Laboratory: RIM Testing Services

HAC RF_E-Field_UMTS_band_IV_telecoil

DUT: BlackBerry Smartphone; Type: Sample

Communication System: WCDMA FDD IV; Frequency: 1712.4 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

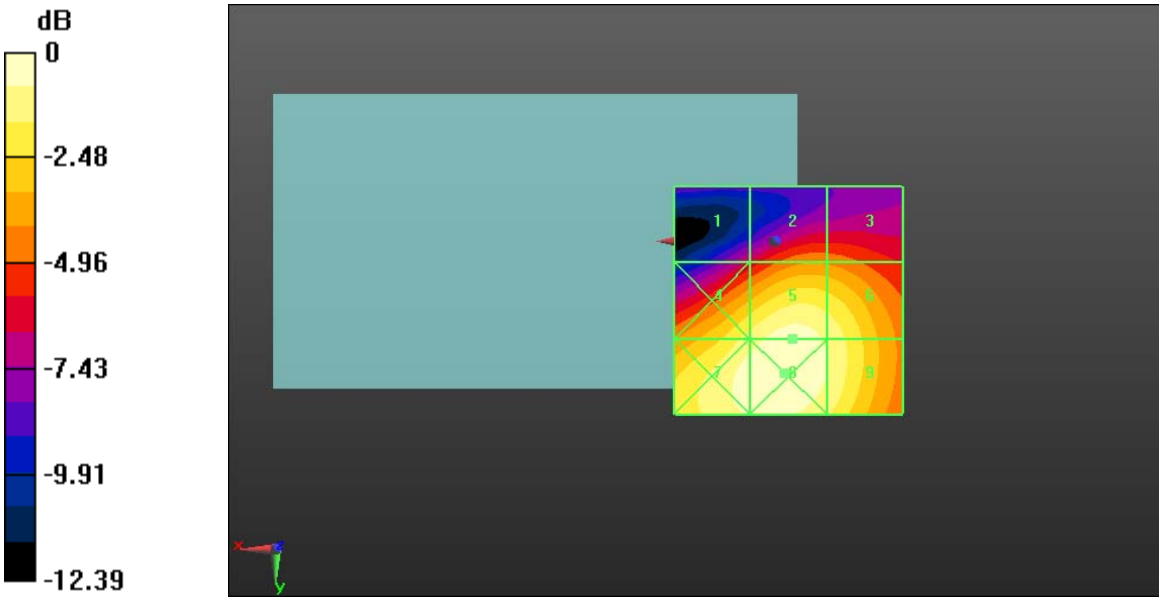
Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Telecoil cent/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 38.455 V/m
Probe Modulation Factor = 0.970
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 21.914 V/m; Power Drift = -0.11 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **19.146 M4**	Grid 2 **24.888 M4**	Grid 3 **24.554 M4**
Grid 4 **34.768 M4**	Grid 5 **38.455 M4**	Grid 6 **35.967 M4**
Grid 7 **38.624 M4**	Grid 8 **40.269 M4**	Grid 9 **36.679 M4**

Cursor:

Total = 40.269 V/m
E Category: M4
Location: -2, 29, 8.7 mm



0 dB = 40.270V/m

Date/Time: 5/13/2011 3:26:42 PM, Date/Time: 5/13/2011 3:30:46 PM, Date/Time: 5/13/2011 3:36:04 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_GSM850

DUT: BlackBerry Smartphone; Type: Sample

Communication System: GSM 850; Frequency: 824.2 MHz, Frequency: 836.8 MHz, Frequency: 848.8 MHz;Communication System PAR: 9.191 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.445 A/m
Probe Modulation Factor = 2.870
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.078 A/m; Power Drift = 0.0049 dB
Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m

Grid 1 **0.445 M4**	Grid 2 **0.313 M4**	Grid 3 **0.201 M4**
Grid 4 **0.399 M4**	Grid 5 **0.279 M4**	Grid 6 **0.176 M4**
Grid 7 **0.384 M4**	Grid 8 **0.261 M4**	Grid 9 **0.153 M4**

Cursor:

Total = 0.445 A/m
H Category: M4
Location: 25, -25, 8.7 mm

Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.544 A/m
Probe Modulation Factor = 2.870
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.102 A/m; Power Drift = 0.16 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

Grid 1 **0.544 M3**	Grid 2 **0.389 M4**	Grid 3 **0.259 M4**
Grid 4 **0.487 M3**	Grid 5 **0.354 M4**	Grid 6 **0.231 M4**
Grid 7 **0.486 M3**	Grid 8 **0.340 M4**	Grid 9 **0.199 M4**

Cursor:

Total = 0.544 A/m
H Category: M3
Location: 25, -25, 8.7 mm

Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.638 A/m
Probe Modulation Factor = 2.870
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.122 A/m; Power Drift = -0.11 dB

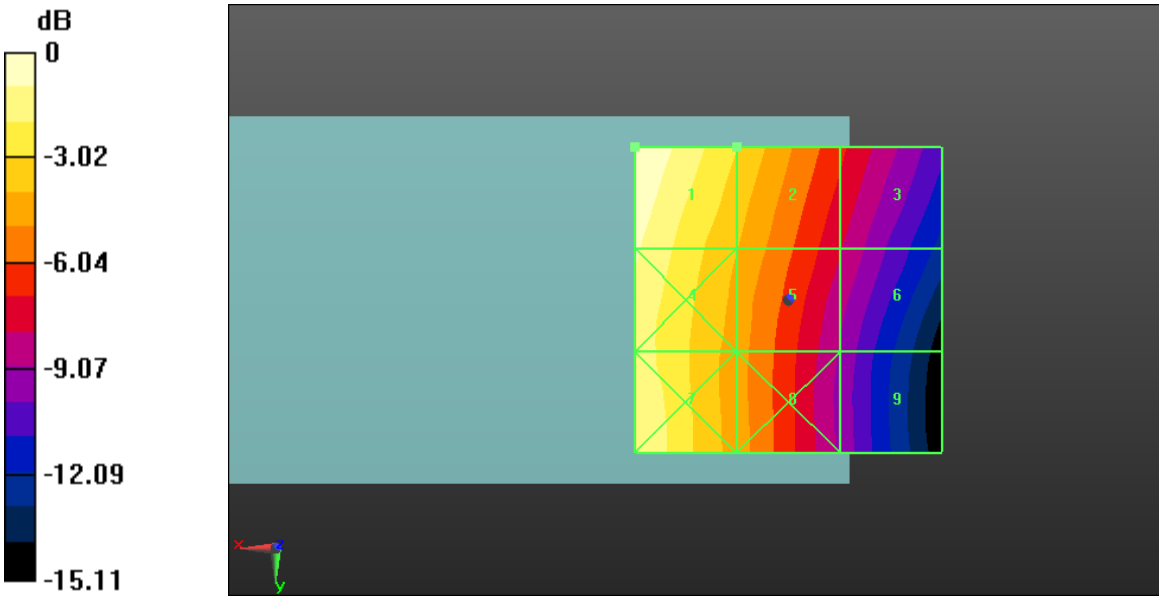
Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

Grid 1 **0.638 M3**	Grid 2 **0.463 M3**	Grid 3 **0.300 M4**
Grid 4 **0.586 M3**	Grid 5 **0.430 M4**	Grid 6 **0.277 M4**
Grid 7 **0.602 M3**	Grid 8 **0.437 M4**	Grid 9 **0.274 M4**

Cursor:

Total = 0.638 A/m
H Category: M3
Location: 25, -25, 8.7 mm



0 dB = 0.440A/m

Date/Time: 5/13/2011 3:48:16 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_GSM850_telecoil

DUT: BlackBerry Smartphone; Type: Sample

Communication System: GSM 850; Frequency: 848.8 MHz;Communication System PAR: 9.191 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

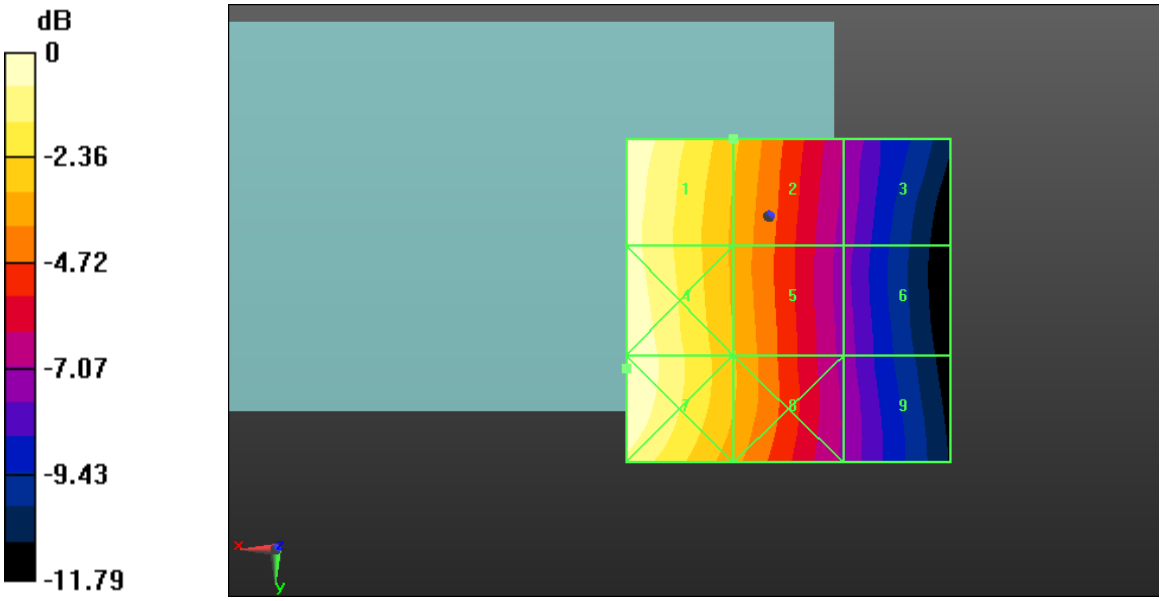
Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2 2/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.577 A/m
Probe Modulation Factor = 2.870
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.125 A/m; Power Drift = 0.00019 dB
Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

Grid 1 **0.577 M3**	Grid 2 **0.414 M4**	Grid 3 **0.260 M4**
Grid 4 **0.576 M3**	Grid 5 **0.408 M4**	Grid 6 **0.249 M4**
Grid 7 **0.577 M3**	Grid 8 **0.409 M4**	Grid 9 **0.255 M4**

Cursor:

Total = 0.577 A/m
H Category: M3
Location: 22, 23.5, 8.7 mm



0 dB = 0.580A/m

Date/Time: 5/16/2011 10:37:36 AM, Date/Time: 5/16/2011 10:42:27 AM, Date/Time: 5/16/2011 10:47:43 AM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_GSM1900

DUT: BlackBerry Smartphone; Type: Sample

Communication System: GSM 1900; Frequency: 1850.2 MHz, Frequency: 1880 MHz, Frequency: 1909.8 MHz;Communication System PAR: 9.191 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 3/7/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.227 A/m
Probe Modulation Factor = 2.870
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.084 A/m; Power Drift = -0.42 dB
Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

Grid 1 **0.339 M2**	Grid 2 **0.259 M2**	Grid 3 **0.223 M3**
Grid 4 **0.216 M3**	Grid 5 **0.227 M3**	Grid 6 **0.223 M3**
Grid 7 **0.176 M3**	Grid 8 **0.192 M3**	Grid 9 **0.192 M3**

Cursor:

Total = 0.339 A/m
H Category: M2
Location: 25, -25, 8.7 mm

Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.203 A/m
Probe Modulation Factor = 2.870
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.071 A/m; Power Drift = -0.07 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

Grid 1 **0.285 M2**	Grid 2 **0.235 M3**	Grid 3 **0.193 M3**
Grid 4 **0.194 M3**	Grid 5 **0.203 M3**	Grid 6 **0.192 M3**
Grid 7 **0.141 M3**	Grid 8 **0.163 M3**	Grid 9 **0.162 M3**

Cursor:

Total = 0.285 A/m
H Category: M2
Location: 25, -25, 8.7 mm

Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.185 A/m
Probe Modulation Factor = 2.870
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.067 A/m; Power Drift = -0.20 dB

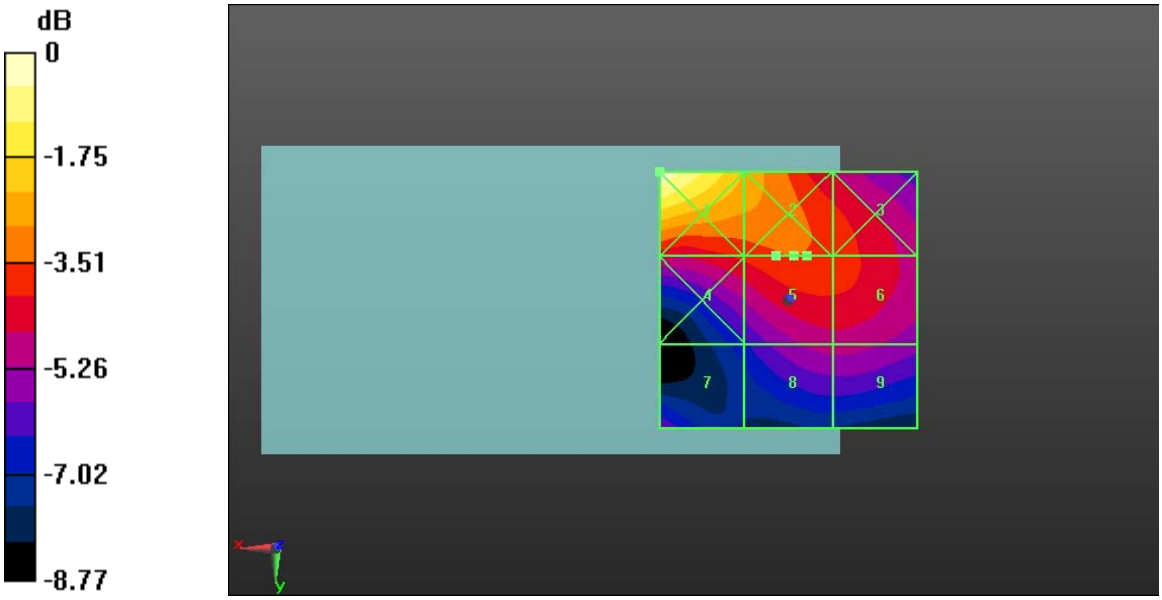
Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

Grid 1 **0.261 M2**	Grid 2 **0.211 M3**	Grid 3 **0.170 M3**
Grid 4 **0.183 M3**	Grid 5 **0.185 M3**	Grid 6 **0.169 M3**
Grid 7 **0.136 M4**	Grid 8 **0.147 M3**	Grid 9 **0.145 M3**

Cursor:

Total = 0.261 A/m
H Category: M2
Location: 25, -25, 8.7 mm



0 dB = 0.340A/m

Date/Time: 5/16/2011 10:54:01 AM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_GSM1900_telecoil

DUT: BlackBerry Smartphone; Type: Sample

Communication System: GSM 1900; Frequency: 1850.2 MHz;Communication System PAR: 9.191 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 3/7/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

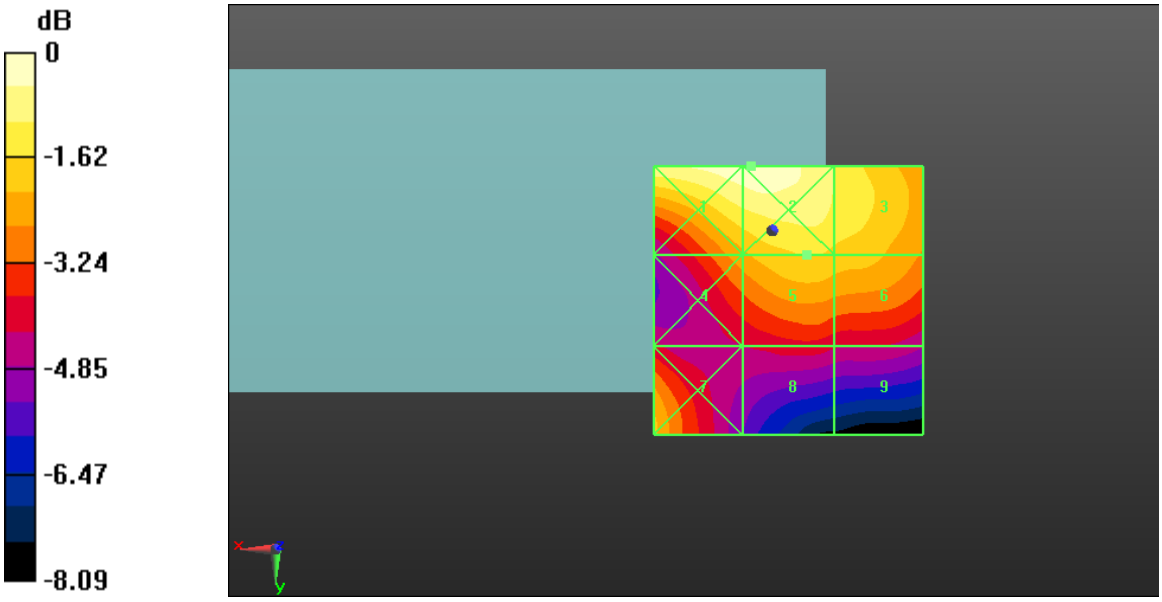
Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2 2/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.212 A/m
Probe Modulation Factor = 2.870
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.082 A/m; Power Drift = -0.23 dB
Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

Grid 1 **0.235 M3**	Grid 2 **0.235 M3**	Grid 3 **0.212 M3**
Grid 4 **0.184 M3**	Grid 5 **0.200 M3**	Grid 6 **0.196 M3**
Grid 7 **0.192 M3**	Grid 8 **0.152 M3**	Grid 9 **0.148 M3**

Cursor:

Total = 0.235 A/m
H Category: M3
Location: 4, -12, 8.7 mm



0 dB = 0.240A/m

Date/Time: 5/16/2011 1:51:15 PM, Date/Time: 5/16/2011 1:56:35 PM, Date/Time: 5/16/2011 2:00:41 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_UMTS_band IV

DUT: BlackBerry Smartphone; Type: Sample

Communication System: WCDMA FDD IV; Frequency: 1712.4 MHz, Frequency: 1732.6 MHz, Frequency: 1752.6 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 3/7/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.103 A/m
Probe Modulation Factor = 0.970
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.124 A/m; Power Drift = -0.16 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.097 M4**	Grid 2 **0.103 M4**	Grid 3 **0.098 M4**
Grid 4 **0.096 M4**	Grid 5 **0.103 M4**	Grid 6 **0.098 M4**
Grid 7 **0.107 M4**	Grid 8 **0.089 M4**	Grid 9 **0.084 M4**

Cursor:

Total = 0.107 A/m
H Category: M4
Location: 25, 25, 8.7 mm

Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.099 A/m
Probe Modulation Factor = 0.970
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.118 A/m; Power Drift = 0.04 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.093 M4**	Grid 2 **0.099 M4**	Grid 3 **0.096 M4**
Grid 4 **0.088 M4**	Grid 5 **0.099 M4**	Grid 6 **0.096 M4**
Grid 7 **0.099 M4**	Grid 8 **0.085 M4**	Grid 9 **0.082 M4**

Cursor:

Total = 0.099 A/m
H Category: M4
Location: -2.5, -7.5, 8.7 mm

Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.083 A/m
Probe Modulation Factor = 0.970
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.095 A/m; Power Drift = -0.06 dB

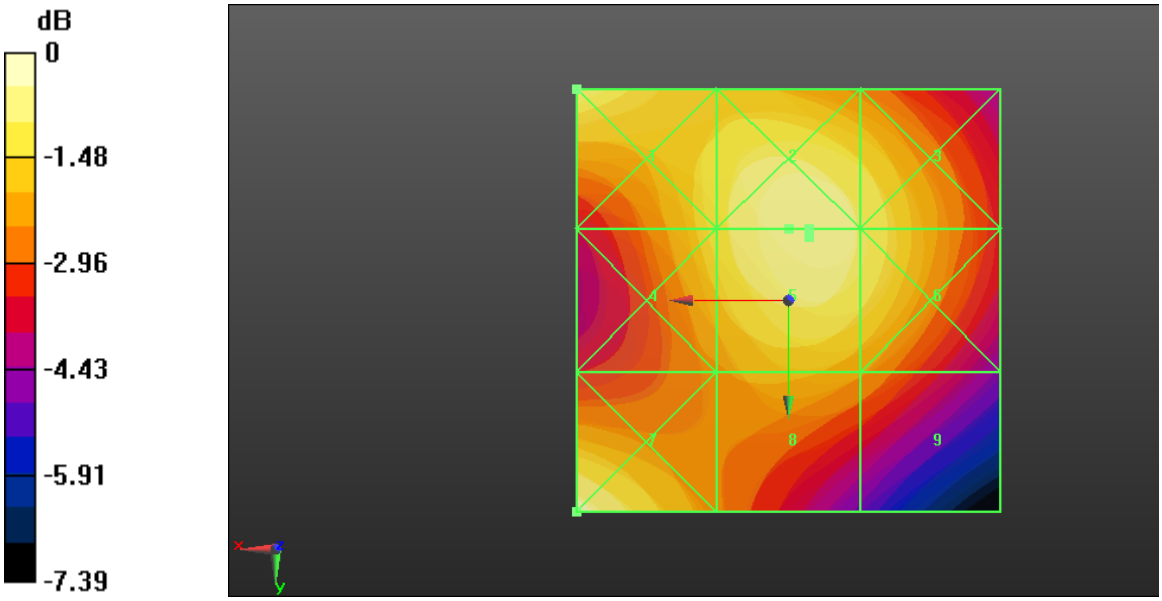
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.095 M4**	Grid 2 **0.083 M4**	Grid 3 **0.081 M4**
Grid 4 **0.075 M4**	Grid 5 **0.083 M4**	Grid 6 **0.081 M4**
Grid 7 **0.080 M4**	Grid 8 **0.071 M4**	Grid 9 **0.070 M4**

Cursor:

Total = 0.095 A/m
H Category: M4
Location: 25, -25, 8.7 mm



0 dB = 0.110A/m

Date/Time: 5/16/2011 2:05:45 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_UMTS_band IV_telecoil

DUT: BlackBerry Smartphone; Type: Sample

Communication System: WCDMA FDD IV; Frequency: 1712.4 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 3/7/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

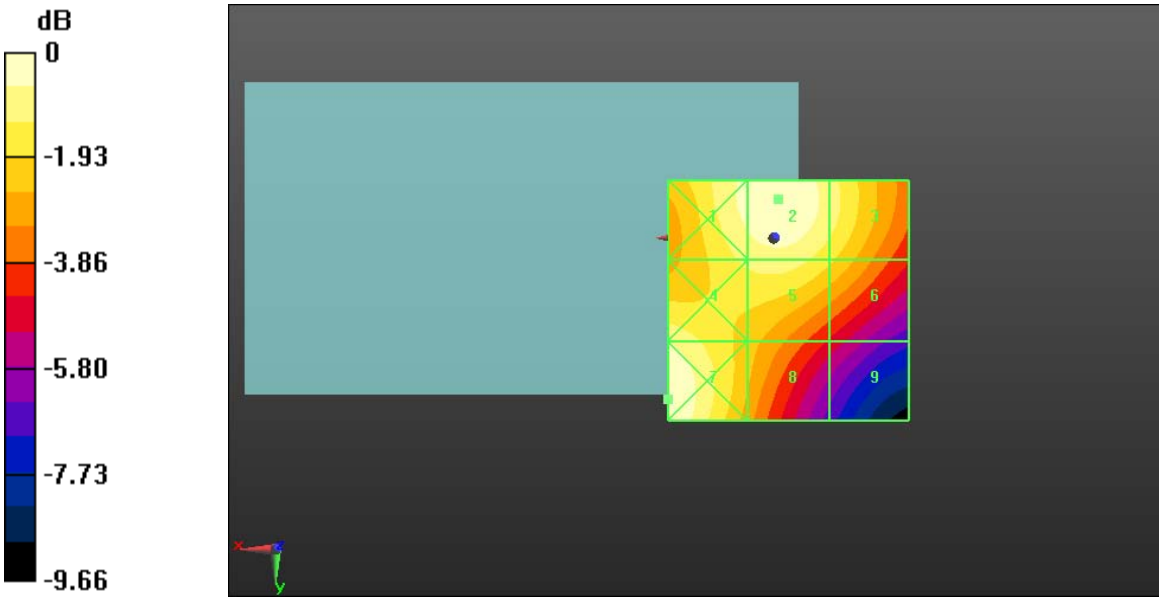
Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2 2/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.099 A/m
Probe Modulation Factor = 0.970
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.119 A/m; Power Drift = -0.06 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.096 M4**	Grid 2 **0.099 M4**	Grid 3 **0.090 M4**
Grid 4 **0.093 M4**	Grid 5 **0.090 M4**	Grid 6 **0.081 M4**
Grid 7 **0.103 M4**	Grid 8 **0.077 M4**	Grid 9 **0.059 M4**

Cursor:

Total = 0.103 A/m
H Category: M4
Location: 22, 33.5, 8.7 mm



0 dB = 0.100A/m

Date/Time: 7/11/2011 11:55:01 AM, Date/Time: 7/11/2011 11:58:50 AM, Date/Time: 7/11/2011 12:07:54 PM, Date/Time: 7/11/2011 12:11:13 PM

Test Laboratory: RIM Testing Services

HAC RF_E-Field_GSM850

DUT: BlackBerry Smartphone; Type: Sample

Communication System: GSM 850; ; Frequency: 824.2 MHz, Frequency: 836.8 MHz, Frequency: 848.8 MHz;Communication System PAR: 9.191 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 3/7/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 135.2 V/m
Probe Modulation Factor = 2.940
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 59.107 V/m; Power Drift = -0.07 dB
Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **122.1 M4**	Grid 2 **131.2 M4**	Grid 3 **127.3 M4**
Grid 4 **125.9 M4**	Grid 5 **135.2 M4**	Grid 6 **131.4 M4**
Grid 7 **127.1 M4**	Grid 8 **134.4 M4**	Grid 9 **130.2 M4**

Cursor:

Total = 135.2 V/m
E Category: M4
Location: -3.5, 0.5, 8.7 mm

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 172.5 V/m
Probe Modulation Factor = 2.940
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 73.222 V/m; Power Drift = -0.06 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **144.9 M4**	Grid 2 **164.2 M3**	Grid 3 **161.3 M3**
Grid 4 **153.0 M3**	Grid 5 **172.5 M3**	Grid 6 **170.0 M3**
Grid 7 **157.9 M3**	Grid 8 **171.5 M3**	Grid 9 **169.7 M3**

Cursor:

Total = 172.5 V/m
E Category: M3
Location: -4.5, 5.5, 8.7 mm

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 199.7 V/m
Probe Modulation Factor = 2.940
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 85.163 V/m; Power Drift = 0.09 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **169.0 M3**	Grid 2 **194.5 M3**	Grid 3 **193.9 M3**
Grid 4 **173.6 M3**	Grid 5 **199.7 M3**	Grid 6 **199.4 M3**
Grid 7 **174.6 M3**	Grid 8 **197.8 M3**	Grid 9 **197.3 M3**

Cursor:

Total = 199.7 V/m
E Category: M3
Location: -6.5, 1.5, 8.7 mm

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device_telecoil/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 200.4 V/m
Probe Modulation Factor = 2.940
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 86.196 V/m; Power Drift = -0.09 dB

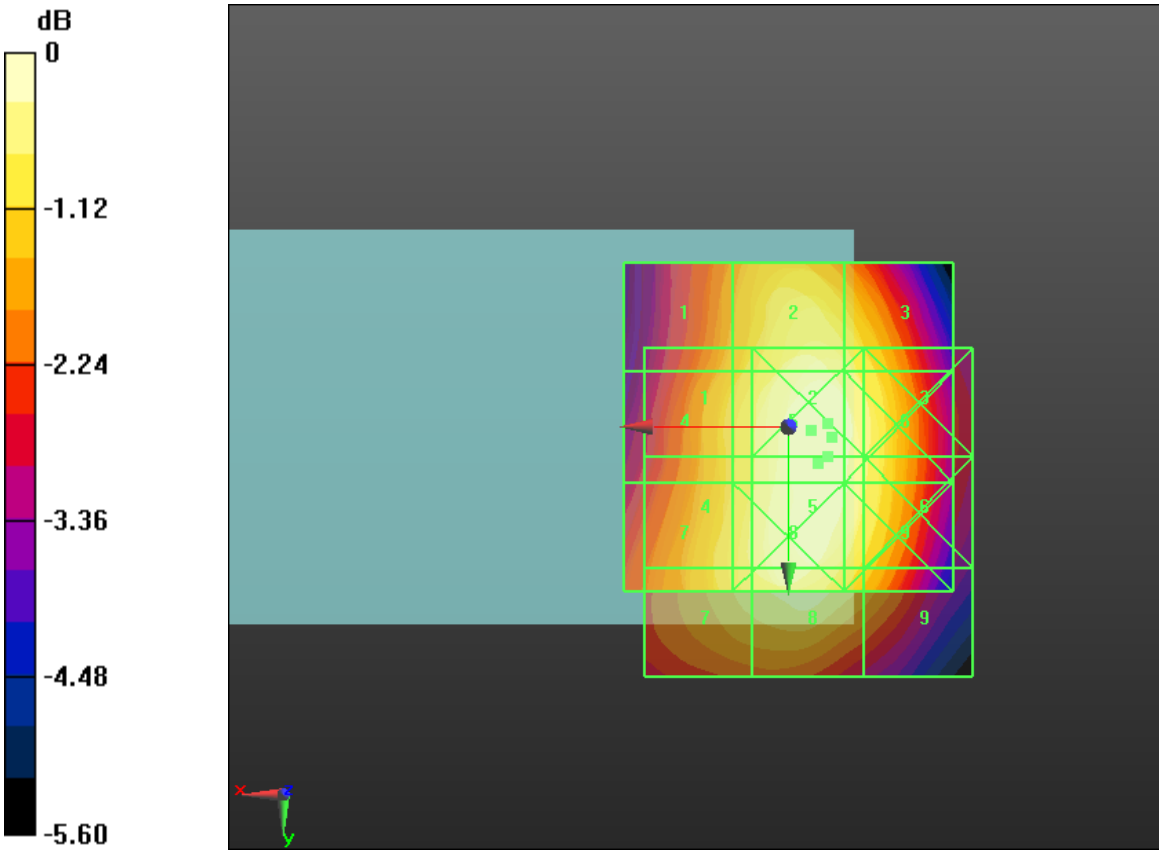
Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **184.1 M3**	Grid 2 **201.3 M3**	Grid 3 **194.9 M3**
Grid 4 **182.8 M3**	Grid 5 **200.4 M3**	Grid 6 **193.9 M3**
Grid 7 **182.5 M3**	Grid 8 **192.8 M3**	Grid 9 **180.0 M3**

Cursor:

Total = 201.3 V/m
E Category: M3
Location: -6, -0.5, 8.7 mm



0 dB = 135.2V/m

Date/Time: 7/11/2011 12:58:38 PM, Date/Time: 7/11/2011 1:03:07 PM, Date/Time: 7/11/2011 1:06:31 PM, Date/Time: 7/11/2011 1:09:55 PM

Test Laboratory: RIM Testing Services

HAC RF_E-Field_GSM1900_

DUT: BlackBerry Smartphone; Type: Sample

Communication System: GSM 1900; ; Frequency: 1850.2 MHz, Frequency: 1880 MHz, Frequency: 1909.8 MHz;Communication System PAR: 9.191 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 3/7/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 69.669 V/m
Probe Modulation Factor = 2.970
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 10.143 V/m; Power Drift = 0.18 dB
Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **91.000 M2**	Grid 2 **96.776 M2**	Grid 3 **89.302 M2**
Grid 4 **40.139 M4**	Grid 5 **53.956 M3**	Grid 6 **55.072 M3**
Grid 7 **68.641 M3**	Grid 8 **69.669 M3**	Grid 9 **64.234 M3**

Cursor:

Total = 96.776 V/m
E Category: M2
Location: 0.5, -25, 8.7 mm

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 57.088 V/m
Probe Modulation Factor = 2.970
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 10.386 V/m; Power Drift = -0.03 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **66.791 M3**	Grid 2 **72.046 M3**	Grid 3 **68.614 M3**
Grid 4 **33.862 M4**	Grid 5 **44.687 M4**	Grid 6 **46.422 M4**
Grid 7 **55.466 M3**	Grid 8 **57.088 M3**	Grid 9 **53.733 M3**

Cursor:

Total = 72.046 V/m
E Category: M3
Location: -1, -25, 8.7 mm

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 49.131 V/m
Probe Modulation Factor = 2.970
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 9.088 V/m; Power Drift = 0.16 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **61.165 M3**	Grid 2 **65.274 M3**	Grid 3 **62.084 M3**
Grid 4 **28.495 M4**	Grid 5 **41.502 M4**	Grid 6 **42.240 M4**
Grid 7 **48.242 M3**	Grid 8 **49.131 M3**	Grid 9 **45.146 M4**

Cursor:

Total = 65.274 V/m
E Category: M3
Location: 0, -25, 8.7 mm

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Telecoil/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 64.866 V/m
Probe Modulation Factor = 2.970
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 10.239 V/m; Power Drift = -0.43 dB

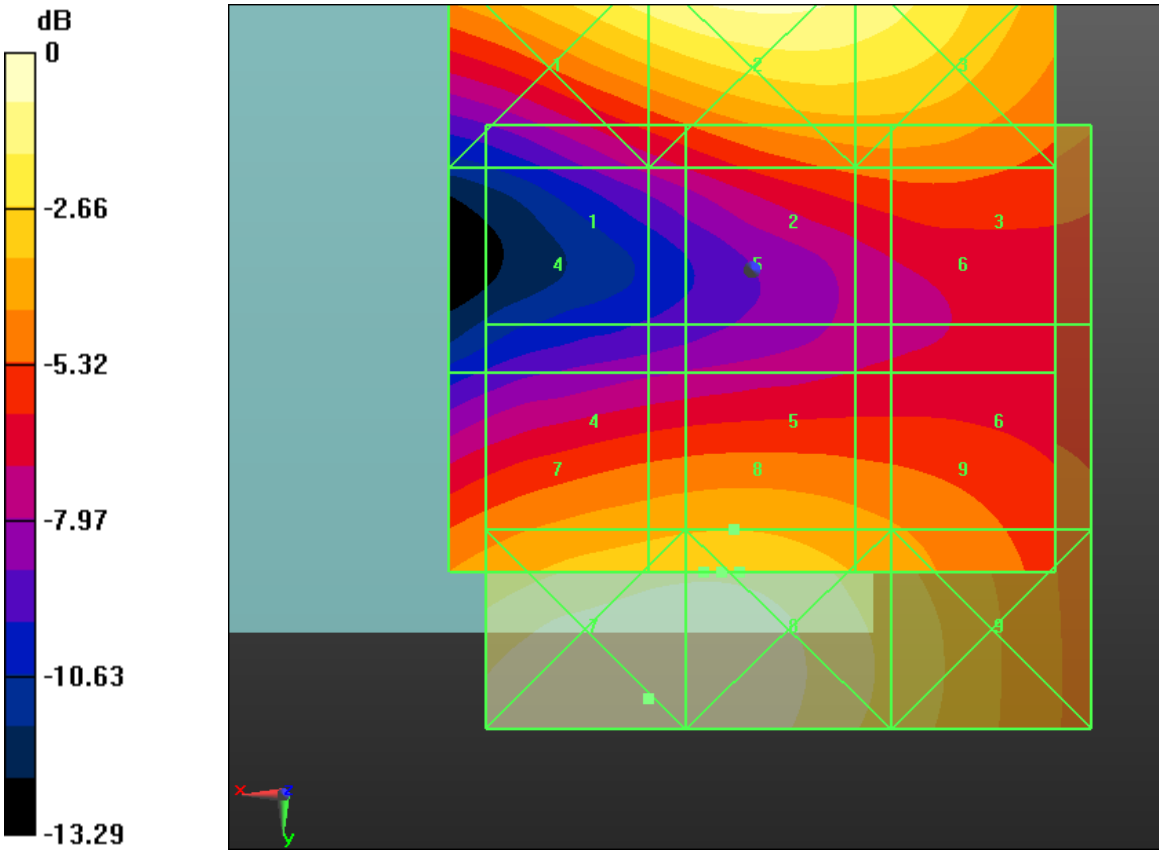
Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **51.427 M3**	Grid 2 **61.781 M3**	Grid 3 **61.072 M3**
Grid 4 **64.103 M3**	Grid 5 **64.866 M3**	Grid 6 **58.886 M3**
Grid 7 **77.243 M3**	Grid 8 **76.913 M3**	Grid 9 **64.118 M3**

Cursor:

Total = 77.243 V/m
E Category: M3
Location: 8.5, 35.5, 8.7 mm



0 dB = 96.780V/m

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Test Laboratory: RIM Testing Services

HAC RF_E-Field_UMTS_band_V

DUT: BlackBerry Smartphone; Type: Sample

Communication System: WCDMA FDD V; ; Frequency: 826.4 MHz, Frequency: 836.4 MHz, Frequency: 846.6 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 67.791 V/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 86.433 V/m; Power Drift = -0.16 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **58.081 M4**	Grid 2 **65.793 M4**	Grid 3 **65.308 M4**
Grid 4 **60.026 M4**	Grid 5 **67.791 M4**	Grid 6 **67.285 M4**
Grid 7 **60.624 M4**	Grid 8 **67.835 M4**	Grid 9 **67.037 M4**

Cursor:

Total = 67.835 V/m
E Category: M4
Location: -4.5, 9.5, 8.7 mm

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 78.696 V/m
Probe Modulation Factor = 1.010
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 96.746 V/m; Power Drift = -0.05 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **64.094 M4**	Grid 2 **75.396 M4**	Grid 3 **75.041 M4**
Grid 4 **67.129 M4**	Grid 5 **78.696 M4**	Grid 6 **78.406 M4**
Grid 7 **68.972 M4**	Grid 8 **78.646 M4**	Grid 9 **78.261 M4**

Cursor:

Total = 78.696 V/m
E Category: M4
Location: -6, 7, 8.7 mm

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 78.231 V/m
Probe Modulation Factor = 1.010
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 96.269 V/m; Power Drift = 0.04 dB

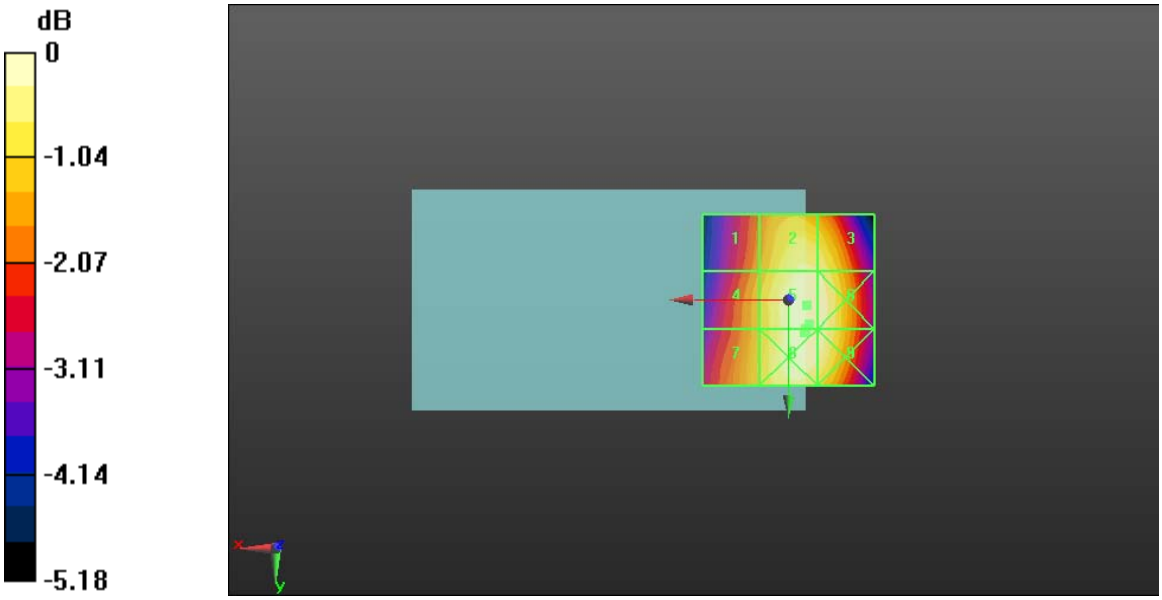
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **64.868 M4**	Grid 2 **75.989 M4**	Grid 3 **75.535 M4**
Grid 4 **67.032 M4**	Grid 5 **78.231 M4**	Grid 6 **77.625 M4**
Grid 7 **67.279 M4**	Grid 8 **77.869 M4**	Grid 9 **77.114 M4**

Cursor:

Total = 78.231 V/m
E Category: M4
Location: -5.5, 1.5, 8.7 mm



0 dB = 67.830V/m

Date/Time: 5/16/2011 3:33:02 PM

Test Laboratory: RIM Testing Services

HAC RF_E-Field_UMTS_band_V_telecoil

DUT: BlackBerry Smartphone; Type: Sample

Communication System: WCDMA FDD V; Frequency: 836.4 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

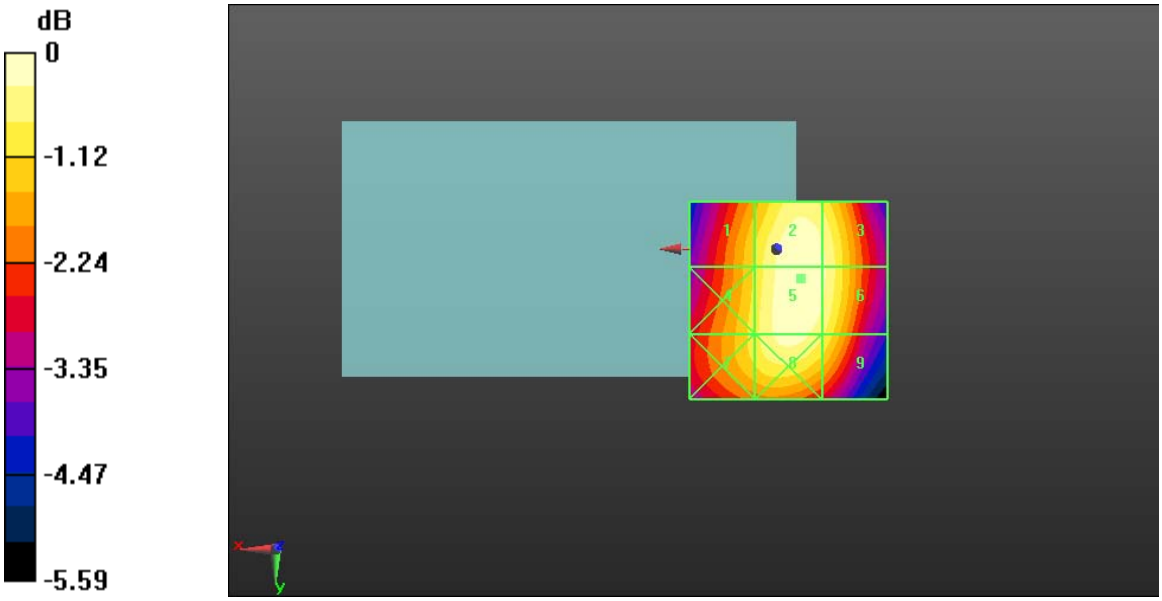
Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Telecoil cent/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 79.980 V/m
Probe Modulation Factor = 1.010
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 97.456 V/m; Power Drift = 0.08 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **70.995 M4**	Grid 2 **79.928 M4**	Grid 3 **77.504 M4**
Grid 4 **72.338 M4**	Grid 5 **79.980 M4**	Grid 6 **77.508 M4**
Grid 7 **72.327 M4**	Grid 8 **78.135 M4**	Grid 9 **74.168 M4**

Cursor:

Total = 79.980 V/m
E Category: M4
Location: -6, 7.5, 8.7 mm



0 dB = 79.980V/m

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Test Laboratory: RIM Testing Services

HAC RF_E-Field_UMTS_band_II

DUT: BlackBerry Smartphone; Type: Sample

Communication System: WCDMA FDD II; Frequency: 1852.4 MHz, Frequency: 1880 MHz, Frequency: 1907.6 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 24.247 V/m
Probe Modulation Factor = 1.120
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 9.507 V/m; Power Drift = -0.28 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **29.692 M4**	Grid 2 **31.468 M4**	Grid 3 **28.912 M4**
Grid 4 **13.140 M4**	Grid 5 **15.723 M4**	Grid 6 **15.648 M4**
Grid 7 **23.023 M4**	Grid 8 **24.247 M4**	Grid 9 **22.793 M4**

Cursor:

Total = 31.468 V/m
E Category: M4
Location: 0.5, -25, 8.7 mm

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 24.727 V/m
Probe Modulation Factor = 1.120
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 11.658 V/m; Power Drift = -0.33 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **29.955 M4**	Grid 2 **32.505 M4**	Grid 3 **30.996 M4**
Grid 4 **13.663 M4**	Grid 5 **19.129 M4**	Grid 6 **19.454 M4**
Grid 7 **22.777 M4**	Grid 8 **24.727 M4**	Grid 9 **23.833 M4**

Cursor:

Total = 32.505 V/m
E Category: M4
Location: -2, -25, 8.7 mm

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 24.045 V/m
Probe Modulation Factor = 1.120
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 11.387 V/m; Power Drift = -0.03 dB

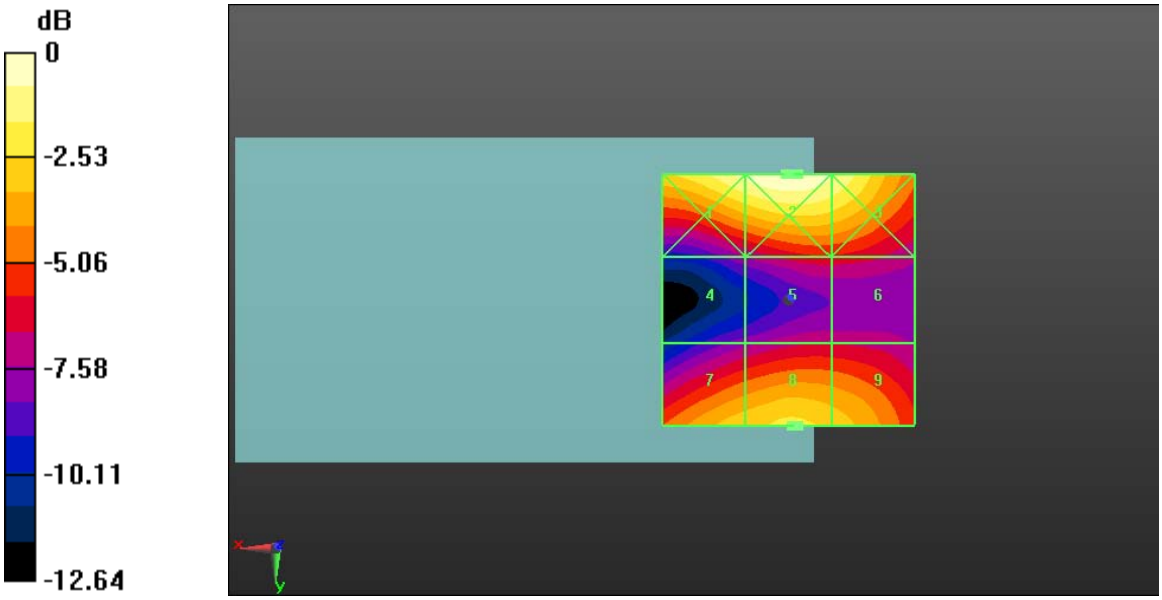
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **31.590 M4**	Grid 2 **33.594 M4**	Grid 3 **31.894 M4**
Grid 4 **14.852 M4**	Grid 5 **19.604 M4**	Grid 6 **19.812 M4**
Grid 7 **22.278 M4**	Grid 8 **24.045 M4**	Grid 9 **22.972 M4**

Cursor:

Total = 33.594 V/m
E Category: M4
Location: 0, -25, 8.7 mm



0 dB = 31.470V/m

Date/Time: 5/16/2011 3:25:18 PM

Test Laboratory: RIM Testing Services

HAC RF_E-Field_UMTS_band_II_telecoil

DUT: BlackBerry Smartphone; Type: Sample

Communication System: WCDMA FDD II; Frequency: 1852.4 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn473; Calibrated: 1/21/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

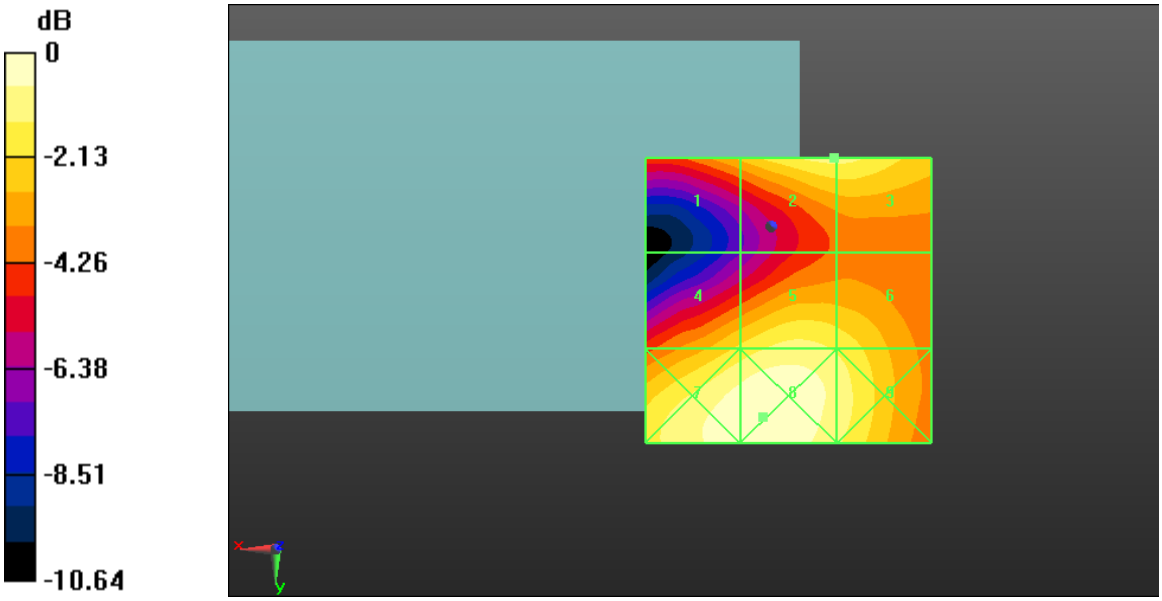
Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Telecoil cent/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 22.433 V/m
Probe Modulation Factor = 1.120
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 11.588 V/m; Power Drift = -0.19 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **18.837 M4**	Grid 2 **22.433 M4**	Grid 3 **22.420 M4**
Grid 4 **20.448 M4**	Grid 5 **22.408 M4**	Grid 6 **21.382 M4**
Grid 7 **24.923 M4**	Grid 8 **25.503 M4**	Grid 9 **22.787 M4**

Cursor:

Total = 25.503 V/m
E Category: M4
Location: 1.5, 33.5, 8.7 mm



0 dB = 25.500V/m

Date/Time: 7/11/2011 3:20:32 PM, Date/Time: 7/11/2011 3:27:15 PM, Date/Time: 7/11/2011 3:35:36 PM, Date/Time: 7/11/2011 3:41:16 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_GSM850

DUT: BlackBerry Smartphone; Type: Sample

Communication System: GSM 850; ; Frequency: 824.2 MHz, Frequency: 836.8 MHz, Frequency: 848.8 MHz;Communication System PAR: 9.191 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 3/7/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.395 A/m
Probe Modulation Factor = 2.870
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.067 A/m; Power Drift = 0.11 dB
Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m

Grid 1 **0.395 M4**	Grid 2 **0.264 M4**	Grid 3 **0.159 M4**
Grid 4 **0.357 M4**	Grid 5 **0.243 M4**	Grid 6 **0.143 M4**
Grid 7 **0.354 M4**	Grid 8 **0.242 M4**	Grid 9 **0.139 M4**

Cursor:

Total = 0.395 A/m
H Category: M4
Location: 25, -25, 8.7 mm

Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.478 A/m
Probe Modulation Factor = 2.870
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.091 A/m; Power Drift = -0.07 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

Grid 1 **0.478 M3**	Grid 2 **0.338 M4**	Grid 3 **0.213 M4**
Grid 4 **0.446 M4**	Grid 5 **0.318 M4**	Grid 6 **0.197 M4**
Grid 7 **0.457 M3**	Grid 8 **0.320 M4**	Grid 9 **0.192 M4**

Cursor:

Total = 0.478 A/m
H Category: M3
Location: 25, -25, 8.7 mm

Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.558 A/m
Probe Modulation Factor = 2.870
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.108 A/m; Power Drift = -0.12 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

Grid 1 **0.558 M3**	Grid 2 **0.387 M4**	Grid 3 **0.235 M4**
Grid 4 **0.527 M3**	Grid 5 **0.375 M4**	Grid 6 **0.234 M4**
Grid 7 **0.554 M3**	Grid 8 **0.399 M4**	Grid 9 **0.256 M4**

Cursor:

Total = 0.558 A/m
H Category: M3
Location: 25, -24.5, 8.7 mm

Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2 2/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.524 A/m
Probe Modulation Factor = 2.870
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.107 A/m; Power Drift = 0.04 dB

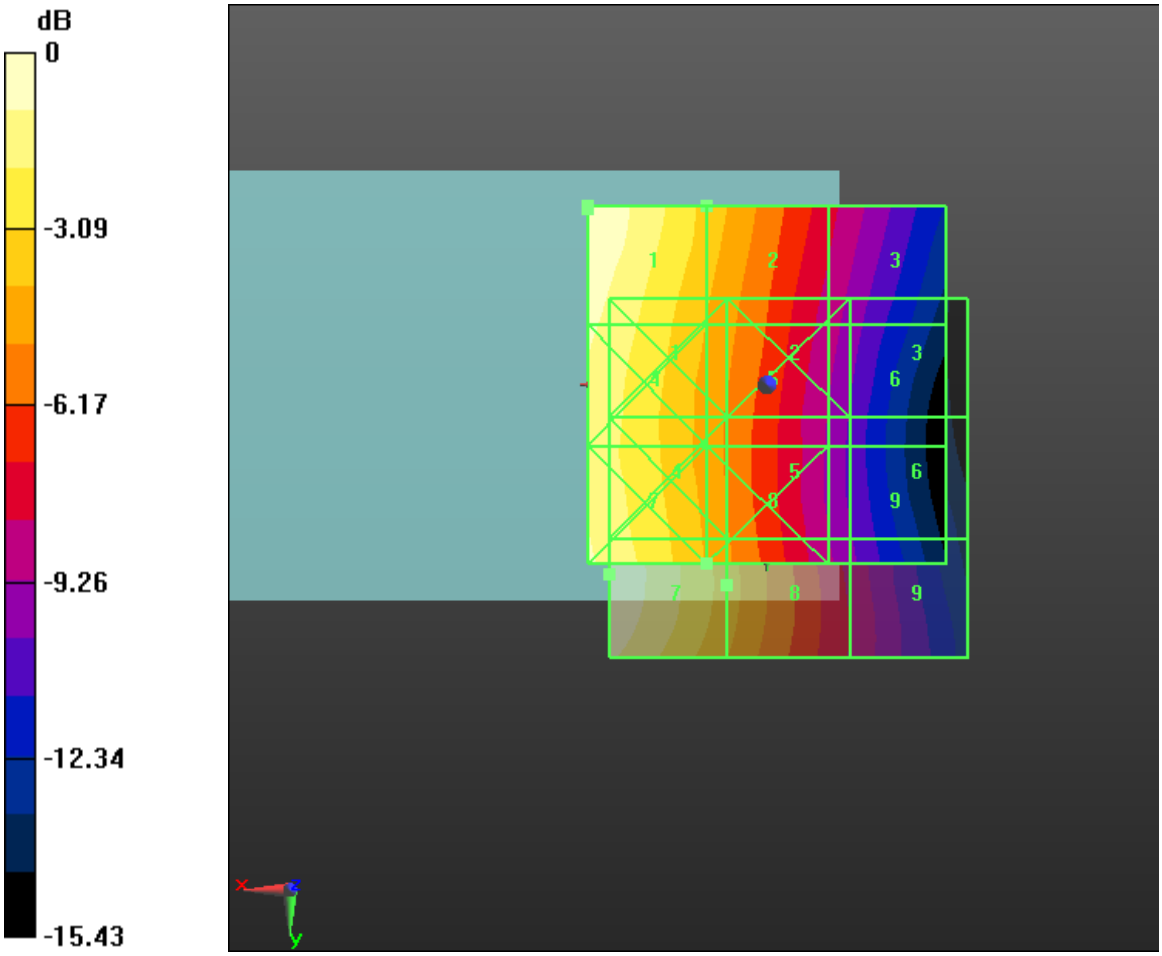
Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

Grid 1 **0.501 M3**	Grid 2 **0.347 M4**	Grid 3 **0.209 M4**
Grid 4 **0.515 M3**	Grid 5 **0.364 M4**	Grid 6 **0.229 M4**
Grid 7 **0.524 M3**	Grid 8 **0.371 M4**	Grid 9 **0.240 M4**

Cursor:

Total = 0.524 A/m
H Category: M3
Location: 22, 26.5, 8.7 mm



0 dB = 0.390A/m

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Test Laboratory: RIM Testing Services

HAC RF_H-Field_GSM1900

DUT: BlackBerry Smartphone; Type: Sample

Communication System: GSM 1900; , Communication System Band: GSM 1900; Frequency: 1850.2 MHz, Frequency: 1880 MHz, Frequency: 1909.8 MHz;Communication System PAR: 9.191 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 3/7/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.203 A/m
Probe Modulation Factor = 2.870
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.071 A/m; Power Drift = 0.03 dB
Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

Grid 1 **0.291 M2**	Grid 2 **0.222 M3**	Grid 3 **0.200 M3**
Grid 4 **0.192 M3**	Grid 5 **0.203 M3**	Grid 6 **0.200 M3**
Grid 7 **0.169 M3**	Grid 8 **0.174 M3**	Grid 9 **0.174 M3**

Cursor:

Total = 0.291 A/m
H Category: M2
Location: 25, -25, 8.7 mm

Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.170 A/m
Probe Modulation Factor = 2.870
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.060 A/m; Power Drift = -0.14 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

Grid 1 **0.233 M3**	Grid 2 **0.191 M3**	Grid 3 **0.165 M3**
Grid 4 **0.160 M3**	Grid 5 **0.170 M3**	Grid 6 **0.164 M3**
Grid 7 **0.143 M3**	Grid 8 **0.137 M4**	Grid 9 **0.137 M4**

Cursor:

Total = 0.233 A/m
H Category: M3
Location: 25, -25, 8.7 mm

Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.162 A/m
Probe Modulation Factor = 2.870
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.051 A/m; Power Drift = 0.05 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

Grid 1 **0.203 M3**	Grid 2 **0.162 M3**	Grid 3 **0.138 M4**
Grid 4 **0.138 M4**	Grid 5 **0.145 M3**	Grid 6 **0.138 M4**
Grid 7 **0.121 M4**	Grid 8 **0.119 M4**	Grid 9 **0.118 M4**

Cursor:

Total = 0.203 A/m
H Category: M3
Location: 25, -25, 8.7 mm

Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2 2/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.197 A/m
Probe Modulation Factor = 2.870
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.071 A/m; Power Drift = 0.06 dB

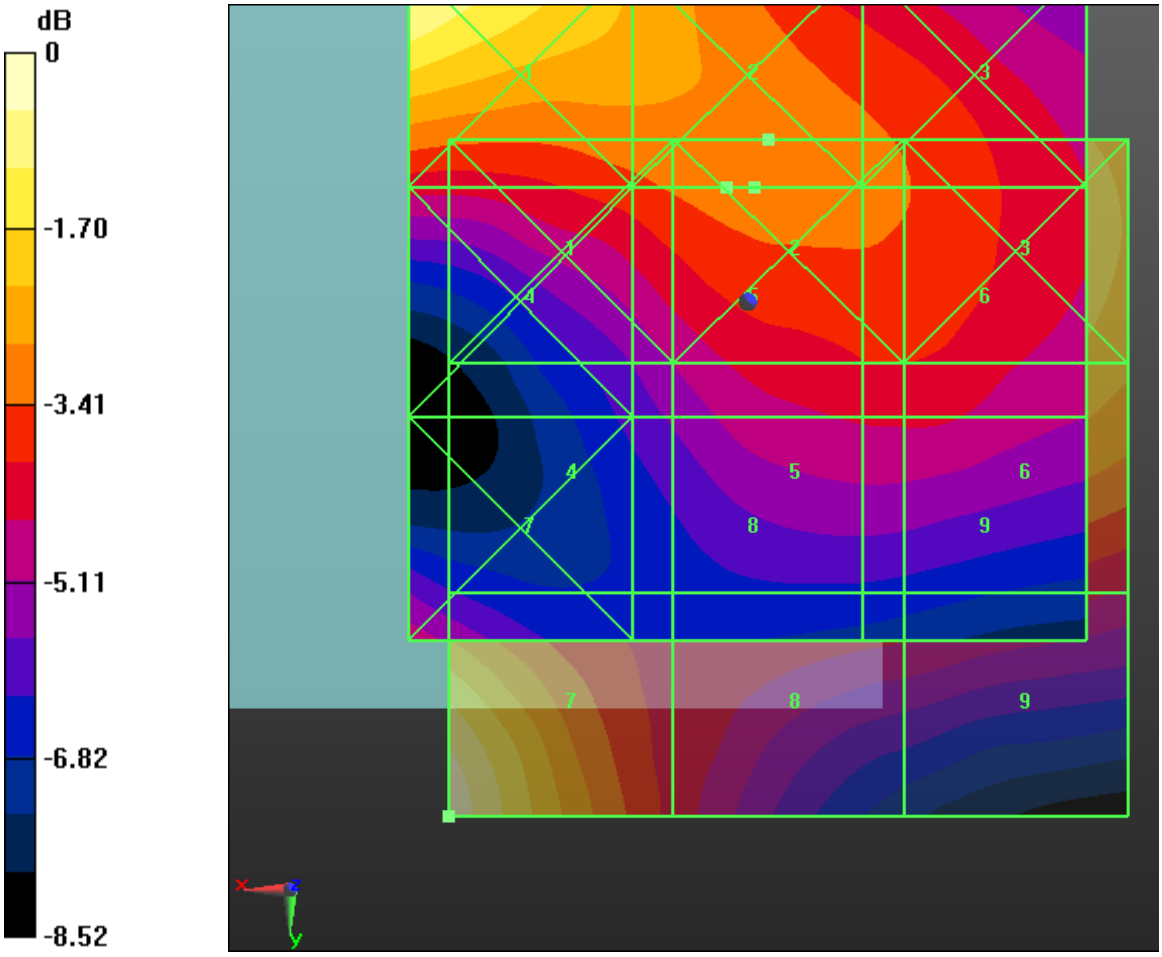
Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

Grid 1 **0.203 M3**	Grid 2 **0.204 M3**	Grid 3 **0.193 M3**
Grid 4 **0.161 M3**	Grid 5 **0.180 M3**	Grid 6 **0.180 M3**
Grid 7 **0.197 M3**	Grid 8 **0.139 M4**	Grid 9 **0.137 M4**

Cursor:

Total = 0.204 A/m
H Category: M3
Location: -1.5, -12, 8.7 mm



0 dB = 0.290A/m

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Test Laboratory: RIM Testing Services

HAC RF_H-Field_UMTS_band V

DUT: BlackBerry Smartphone; Type: Sample

Communication System: WCDMA FDD V; Frequency: 826.4 MHz, Frequency: 836.4 MHz, Frequency: 846.6 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 3/7/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.153 A/m
Probe Modulation Factor = 0.990
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.081 A/m; Power Drift = 0.11 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.153 M4**	Grid 2 **0.108 M4**	Grid 3 **0.067 M4**
Grid 4 **0.137 M4**	Grid 5 **0.099 M4**	Grid 6 **0.061 M4**
Grid 7 **0.139 M4**	Grid 8 **0.099 M4**	Grid 9 **0.060 M4**

Cursor:

Total = 0.153 A/m
H Category: M4
Location: 25, -25, 8.7 mm

Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.174 A/m
Probe Modulation Factor = 0.990
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.095 A/m; Power Drift = 0.06 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.174 M4**	Grid 2 **0.125 M4**	Grid 3 **0.081 M4**
Grid 4 **0.157 M4**	Grid 5 **0.115 M4**	Grid 6 **0.074 M4**
Grid 7 **0.160 M4**	Grid 8 **0.114 M4**	Grid 9 **0.069 M4**

Cursor:

Total = 0.174 A/m
H Category: M4
Location: 25, -25, 8.7 mm

Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.176 A/m
Probe Modulation Factor = 0.990
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.099 A/m; Power Drift = 0.09 dB

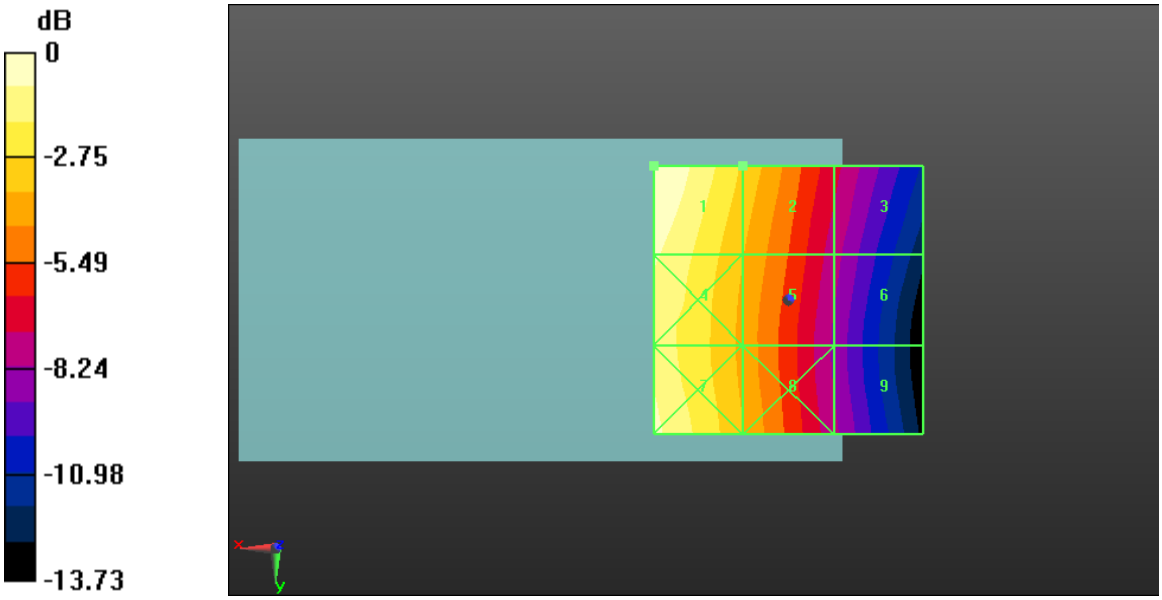
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.176 M4**	Grid 2 **0.126 M4**	Grid 3 **0.078 M4**
Grid 4 **0.162 M4**	Grid 5 **0.120 M4**	Grid 6 **0.074 M4**
Grid 7 **0.171 M4**	Grid 8 **0.126 M4**	Grid 9 **0.079 M4**

Cursor:

Total = 0.176 A/m
H Category: M4
Location: 25, -25, 8.7 mm



0 dB = 0.150A/m

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Test Laboratory: RIM Testing Services

HAC RF_H-Field_UMTS_band V_telecoil

DUT: BlackBerry Smartphone; Type: Sample

Communication System: WCDMA FDD V; Frequency: 846.6 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 3/7/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

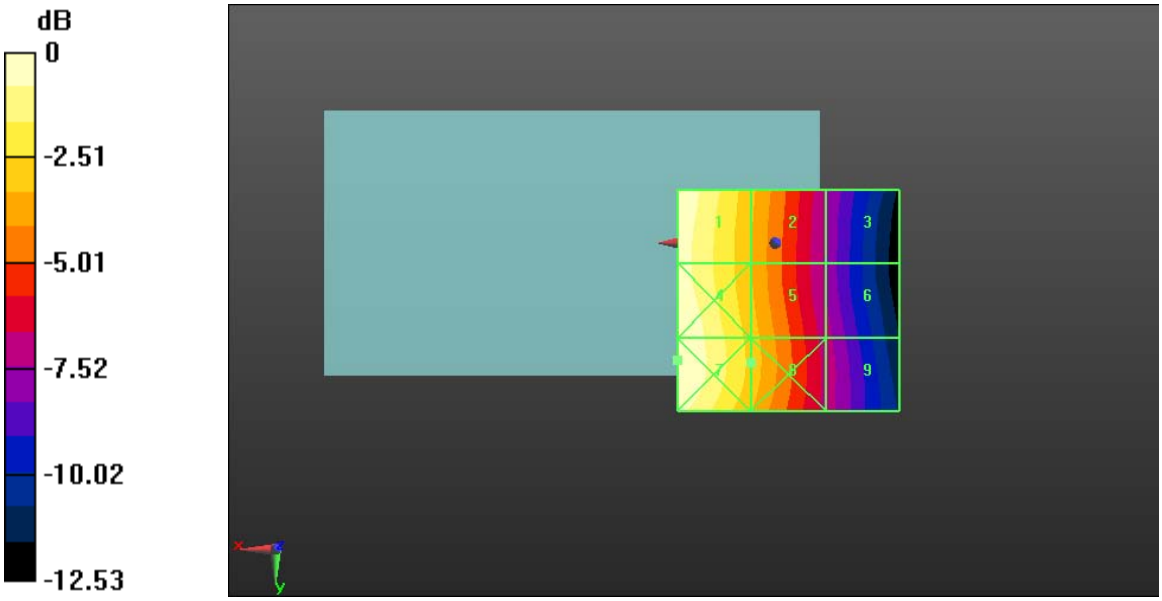
Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2 2/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.161 A/m
Probe Modulation Factor = 0.990
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.101 A/m; Power Drift = -0.03 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.161 M4**	Grid 2 **0.112 M4**	Grid 3 **0.068 M4**
Grid 4 **0.162 M4**	Grid 5 **0.115 M4**	Grid 6 **0.071 M4**
Grid 7 **0.164 M4**	Grid 8 **0.117 M4**	Grid 9 **0.072 M4**

Cursor:

Total = 0.164 A/m
H Category: M4
Location: 22, 26.5, 8.7 mm



0 dB = 0.160A/m

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Test Laboratory: RIM Testing Services

HAC RF_H-Field_UMTS_band II

DUT: BlackBerry Smartphone; Type: Sample

Communication System: WCDMA FDD II; Frequency: 1852.4 MHz, Frequency: 1880 MHz, Frequency: 1907.6 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 3/7/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.067 A/m
Probe Modulation Factor = 1.120
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.061 A/m; Power Drift = 0.0018 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.096 M4**	Grid 2 **0.075 M4**	Grid 3 **0.066 M4**
Grid 4 **0.064 M4**	Grid 5 **0.067 M4**	Grid 6 **0.066 M4**
Grid 7 **0.060 M4**	Grid 8 **0.057 M4**	Grid 9 **0.057 M4**

Cursor:

Total = 0.096 A/m
H Category: M4
Location: 25, -25, 8.7 mm

Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.074 A/m
Probe Modulation Factor = 1.120
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.067 A/m; Power Drift = -0.0088 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.105 M4**	Grid 2 **0.087 M4**	Grid 3 **0.072 M4**
Grid 4 **0.071 M4**	Grid 5 **0.074 M4**	Grid 6 **0.072 M4**
Grid 7 **0.064 M4**	Grid 8 **0.061 M4**	Grid 9 **0.061 M4**

Cursor:

Total = 0.105 A/m
H Category: M4
Location: 25, -25, 8.7 mm

Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.074 A/m
Probe Modulation Factor = 1.120
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.069 A/m; Power Drift = 0.06 dB

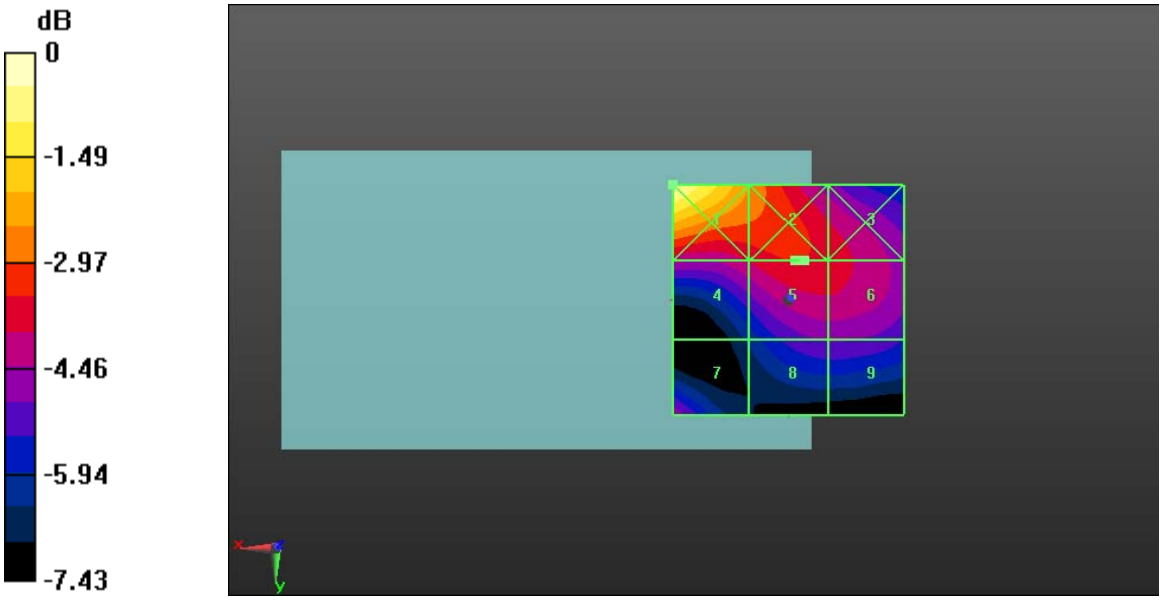
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.102 M4**	Grid 2 **0.083 M4**	Grid 3 **0.073 M4**
Grid 4 **0.070 M4**	Grid 5 **0.074 M4**	Grid 6 **0.073 M4**
Grid 7 **0.064 M4**	Grid 8 **0.063 M4**	Grid 9 **0.063 M4**

Cursor:

Total = 0.102 A/m
H Category: M4
Location: 25, -25, 8.7 mm



0 dB = 0.100A/m

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Test Laboratory: RIM Testing Services

HAC RF_H-Field_UMTS_band II_telecoil

DUT: BlackBerry Smartphone; Type: Sample

Communication System: WCDMA FDD II; Frequency: 1907.6 MHz;Communication System PAR: 0 dB
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 3/7/2011
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

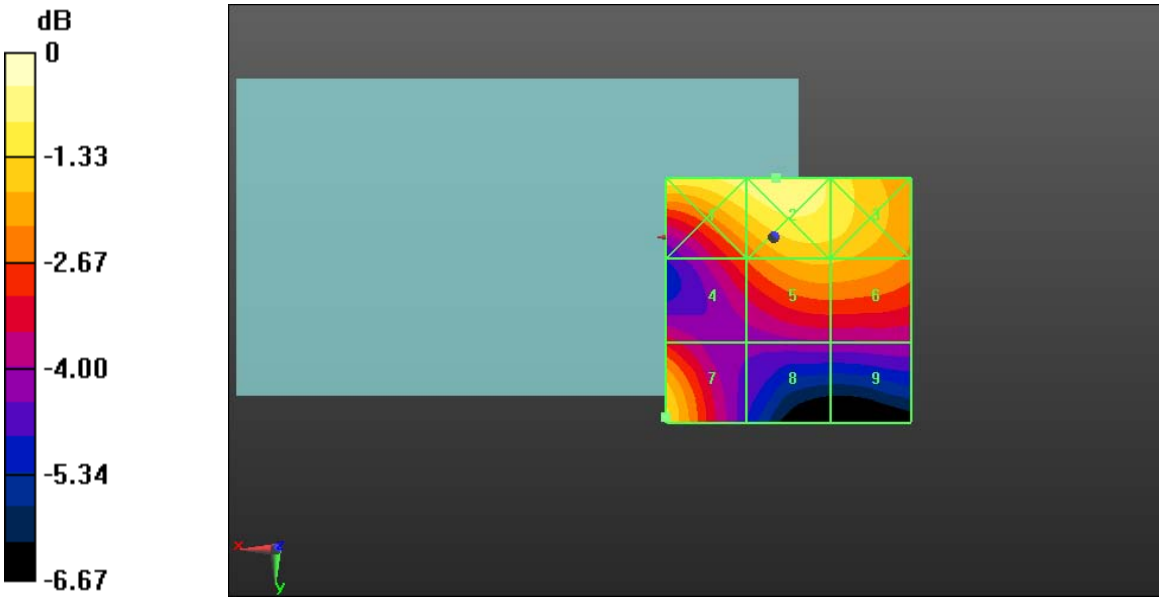
Device H-Field measurement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2 2/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.069 A/m
Probe Modulation Factor = 1.120
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.069 A/m; Power Drift = 0.06 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.074 M4**	Grid 2 **0.076 M4**	Grid 3 **0.072 M4**
Grid 4 **0.059 M4**	Grid 5 **0.066 M4**	Grid 6 **0.066 M4**
Grid 7 **0.069 M4**	Grid 8 **0.050 M4**	Grid 9 **0.051 M4**

Cursor:

Total = 0.076 A/m
H Category: M4
Location: -0.5, -12, 8.7 mm



0 dB = 0.080A/m